

18-pin Flash/EEPROM 8-Bit Microcontrollers

Devices Included in this Data Sheet:

- PIC16F83
- PIC16F84
- PIC16CR83
- PIC16CR84
- Extended voltage range devices available (PIC16LF8X, PIC16LCR8X)

High Performance RISC CPU Features:

- · Only 35 single word instructions to learn
- All instructions single cycle except for program branches which are two-cycle
- Operating speed: DC 10 MHz clock input DC - 400 ns instruction cycle

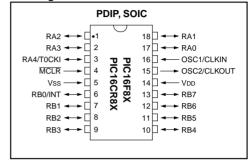
Device	Program Memory (words)	Data RAM (bytes)	Data EEPROM (bytes)	Max. Freq (MHz)
PIC16F83	512 Flash	36	64	10
PIC16F84	1 K Flash	68	64	10
PIC16CR83	512 ROM	36	64	10
PIC16CR84	1 K ROM	68	64	10

- 14-bit wide instructions
- 8-bit wide data path
- 15 special function hardware registers
- · Eight-level deep hardware stack
- · Direct, indirect and relative addressing modes
- · Four interrupt sources:
 - External RB0/INT pin
 - TMR0 timer overflow
 - PORTB<7:4> interrupt on change
 - Data EEPROM write complete
- 1000 erase/write cycles Flash program memory
- 10,000,000 erase/write cycles EEPROM data memory
- EEPROM Data Retention > 40 years

Peripheral Features:

- 13 I/O pins with individual direction control
- · High current sink/source for direct LED drive
 - 25 mA sink max. per pin
 - 20 mA source max. per pin
- TMR0: 8-bit timer/counter with 8-bit programmable prescaler

Pin Diagrams



Special Microcontroller Features:

- In-Circuit Serial Programming (ICSP™) via two pins (ROM devices support only Data EEPROM programming)
- · Power-on Reset (POR)
- Power-up Timer (PWRT)
- Oscillator Start-up Timer (OST)
- Watchdog Timer (WDT) with its own on-chip RC oscillator for reliable operation
- Code-protection
- · Power saving SLEEP mode
- · Selectable oscillator options

CMOS Flash/EEPROM Technology:

- · Low-power, high-speed technology
- · Fully static design
- Wide operating voltage range:
 - Commercial: 2.0V to 6.0V
 - Industrial: 2.0V to 6.0V
- · Low power consumption:
 - < 2 mA typical @ 5V. 4 MHz
 - 15 μA typical @ 2V, 32 kHz
 - < 1 μA typical standby current @ 2V

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1.0 GENERAL DESCRIPTION

The PIC16F8X is a group in the PIC16CXX family of low-cost, high-performance, CMOS, fully-static, 8-bit microcontrollers. This group contains the following devices:

- PIC16F83
- PIC16F84
- PIC16CR83
- PIC16CR84

All PICmicro™ microcontrollers employ an advanced RISC architecture. PIC16F8X devices have enhanced core features, eight-level deep stack, and multiple internal and external interrupt sources. The separate instruction and data buses of the Harvard architecture allow a 14-bit wide instruction word with a separate 8-bit wide data bus. The two stage instruction pipeline allows all instructions to execute in a single cycle, except for program branches (which require two cycles). A total of 35 instructions (reduced instruction set) are available. Additionally, a large register set is used to achieve a very high performance level.

PIC16F8X microcontrollers typically achieve a 2:1 code compression and up to a 4:1 speed improvement (at 20 MHz) over other 8-bit microcontrollers in their class.

The PIC16F8X has up to 68 bytes of RAM, 64 bytes of Data EEPROM memory, and 13 I/O pins. A timer/counter is also available.

The PIC16CXX family has special features to reduce external components, thus reducing cost, enhancing system reliability and reducing power consumption. There are four oscillator options, of which the single pin RC oscillator provides a low-cost solution, the LP oscillator minimizes power consumption, XT is a standard crystal, and the HS is for High Speed crystals. The SLEEP (power-down) mode offers power saving. The user can wake the chip from sleep through several external and internal interrupts and resets.

A highly reliable Watchdog Timer with its own on-chip RC oscillator provides protection against software lock-up.

The devices with Flash program memory allow the same device package to be used for prototyping and production. In-circuit reprogrammability allows the code to be updated without the device being removed from the end application. This is useful in the development of many applications where the device may not be easily accessible, but the prototypes may require code updates. This is also useful for remote applications where the code may need to be updated (such as rate information).

Table 1-1 lists the features of the PIC16F8X. A simplified block diagram of the PIC16F8X is shown in Figure 3-1.

The PIC16F8X fits perfectly in applications ranging from high speed automotive and appliance motor control to low-power remote sensors, electronic locks, security devices and smart cards. The Flash/EEPROM technology makes customization of application programs (transmitter codes, motor speeds, receiver frequencies, security codes, etc.) extremely fast and convenient. The small footprint packages make this microcontroller series perfect for all applications with space limitations. Low-cost, low-power, high performance, ease-of-use and I/O flexibility make the PIC16F8X very versatile even in areas where no microcontroller use has been considered before (e.g., timer functions: serial communication: capture. compare and PWM functions; and co-processor applications).

The serial in-system programming feature (via two pins) offers flexibility of customizing the product after complete assembly and testing. This feature can be used to serialize a product, store calibration data, or program the device with the current firmware before shipping.

1.1 Family and Upward Compatibility

Those users familiar with the PIC16C5X family of microcontrollers will realize that this is an enhanced version of the PIC16C5X architecture. Please refer to Appendix A for a detailed list of enhancements. Code written for PIC16C5X devices can be easily ported to PIC16F8X devices (Appendix B).

1.2 <u>Development Support</u>

The PIC16CXX family is supported by a full-featured macro assembler, a software simulator, an in-circuit emulator, a low-cost development programmer and a full-featured programmer. A "C" compiler and fuzzy logic support tools are also available.

TABLE 1-1 PIC16F8X FAMILY OF DEVICES

		PIC16F83	PIC16CR83	PIC16F84	PIC16CR84
Clock	Maximum Frequency of Operation (MHz)	10	10	10	10
	Flash Program Memory	512	_	1K	_
	EEPROM Program Memory	_	_	_	_
Memory	ROM Program Memory	_	512	_	1K
	Data Memory (bytes)	36	36	68	68
	Data EEPROM (bytes)	64	64	64	64
Peripherals	Timer Module(s)	TMR0	TMR0	TMR0	TMR0
	Interrupt Sources	4	4	4	4
	I/O Pins	13	13	13	13
Features	Voltage Range (Volts)	2.0-6.0	2.0-6.0	2.0-6.0	2.0-6.0
	Packages	18-pin DIP, SOIC	18-pin DIP, SOIC	18-pin DIP, SOIC	18-pin DIP, SOIC

All PICmicroTM Family devices have Power-on Reset, selectable Watchdog Timer, selectable code protect and high I/O current capability. All PIC16F8X Family devices use serial programming with clock pin RB6 and data pin RB7.

2.0 PIC16F8X DEVICE VARIETIES

A variety of frequency ranges and packaging options are available. Depending on application and production requirements the proper device option can be selected using the information in this section. When placing orders, please use the "PIC16F8X Product Identification System" at the back of this data sheet to specify the correct part number.

There are four device "types" as indicated in the device number

- F, as in PIC16F84. These devices have Flash program memory and operate over the standard voltage range.
- LF, as in PIC16LF84. These devices have Flash program memory and operate over an extended voltage range.
- CR, as in PIC16CR83. These devices have ROM program memory and operate over the standard voltage range.
- LCR, as in PIC16LCR84. These devices have ROM program memory and operate over an extended voltage range.

When discussing memory maps and other architectural features, the use of **F** and **CR** also implies the **LF** and **LCR** versions.

2.1 Flash Devices

These devices are offered in the lower cost plastic package, even though the device can be erased and reprogrammed. This allows the same device to be used for prototype development and pilot programs as well as production.

A further advantage of the electrically-erasable Flash version is that it can be erased and reprogrammed incircuit, or by device programmers, such as Microchip's PICSTART[®] Plus or PRO MATE[®] II programmers.

2.2 Quick-Turnaround-Production (QTP) Devices

Microchip offers a QTP Programming Service for factory production orders. This service is made available for users who choose not to program a medium to high quantity of units and whose code patterns have stabilized. The devices have all Flash locations and configuration options already programmed by the factory. Certain code and prototype verification procedures do apply before production shipments are available.

For information on submitting a QTP code, please contact your Microchip Regional Sales Office.

2.3 <u>Serialized Quick-Turnaround-</u> Production (SQTPSM) Devices

Microchip offers the unique programming service where a few user-defined locations in each device are programmed with different serial numbers. The serial numbers may be random, pseudo-random or sequential.

Serial programming allows each device to have a unique number which can serve as an entry-code, password or ID number.

For information on submitting a SQTP code, please contact your Microchip Regional Sales Office.

2.4 ROM Devices

Some of Microchip's devices have a corresponding device where the program memory is a ROM. These devices give a cost savings over Microchip's traditional user programmed devices (EPROM, EEPROM).

ROM devices (PIC16CR8X) do not allow serialization information in the program memory space. The user may program this information into the Data EEPROM.

For information on submitting a ROM code, please contact your Microchip Regional Sales Office.

NOTES:

3.0 ARCHITECTURAL OVERVIEW

The high performance of the PIC16CXX family can be attributed to a number of architectural features commonly found in RISC microprocessors. To begin with, the PIC16CXX uses a Harvard architecture. This architecture has the program and data accessed from separate memories. So the device has a program memory bus and a data memory bus. This improves bandwidth over traditional von Neumann architecture where program and data are fetched from the same memory (accesses over the same bus). Separating program and data memory further allows instructions to be sized differently than the 8-bit wide data word. PIC16CXX opcodes are 14-bits wide, enabling single word instructions. The full 14-bit wide program memory bus fetches a 14-bit instruction in a single cycle. A twostage pipeline overlaps fetch and execution of instructions (Example 3-1). Consequently, all instructions execute in a single cycle except for program branches.

The PIC16F83 and PIC16CR83 address 512 x 14 of program memory, and the PIC16F84 and PIC16CR84 address 1K x 14 program memory. All program memory is internal.

The PIC16CXX can directly or indirectly address its register files or data memory. All special function registers including the program counter are mapped in the data memory. An orthogonal (symmetrical) instruction set makes it possible to carry out any operation on any register using any addressing mode. This symmetrical nature and lack of 'special optimal situations' make programming with the PIC16CXX simple yet efficient. In addition, the learning curve is reduced significantly.

PIC16CXX devices contain an 8-bit ALU and working register. The ALU is a general purpose arithmetic unit. It performs arithmetic and Boolean functions between data in the working register and any register file.

The ALU is 8-bits wide and capable of addition, subtraction, shift and logical operations. Unless otherwise mentioned, arithmetic operations are two's complement in nature. In two-operand instructions, typically one operand is the working register (W register), and the other operand is a file register or an immediate constant. In single operand instructions, the operand is either the W register or a file register.

The W register is an 8-bit working register used for ALU operations. It is not an addressable register.

Depending on the instruction executed, the ALU may affect the values of the Carry (C), Digit Carry (DC), and Zero (Z) bits in the STATUS register. The C and DC bits operate as a borrow and digit borrow out bit, respectively, in subtraction. See the SUBLW and SUBWF instructions for examples.

A simplified block diagram for the PIC16F8X is shown in Figure 3-1, its corresponding pin description is shown in Table 3-1.

FIGURE 3-1: PIC16F8X BLOCK DIAGRAM

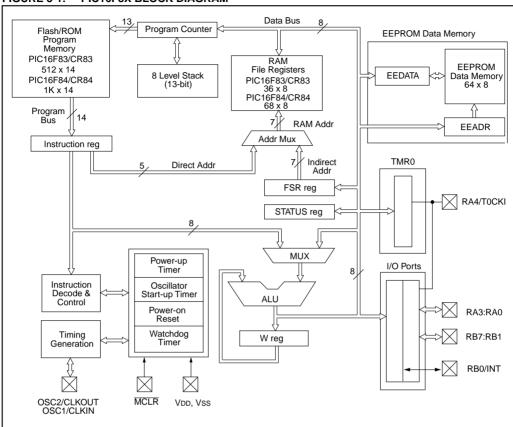


TABLE 3-1 PIC16F8X PINOUT DESCRIPTION

Pin Name	DIP No.	SOIC No.	I/O/P Type	Buffer Type	Description
OSC1/CLKIN	16	16	ı	ST/CMOS (3)	Oscillator crystal input/external clock source input.
OSC2/CLKOUT	15	15	0	_	Oscillator crystal output. Connects to crystal or resonator in crystal oscillator mode. In RC mode, OSC2 pin outputs CLKOUT which has 1/4 the frequency of OSC1, and denotes the instruction cycle rate.
MCLR	4	4	I/P	ST	Master clear (reset) input/programming voltage input. This pin is an active low reset to the device.
					PORTA is a bi-directional I/O port.
RA0	17	17	I/O	TTL	
RA1	18	18	I/O	TTL	
RA2	1	1	I/O	TTL	
RA3	2	2	I/O	TTL	
RA4/T0CKI	3	3	I/O	ST	Can also be selected to be the clock input to the TMR0 timer/counter. Output is open drain type.
					PORTB is a bi-directional I/O port. PORTB can be software programmed for internal weak pull-up on all inputs.
RB0/INT	6	6	I/O	TTL/ST (1)	RB0/INT can also be selected as an external interrupt pin.
RB1	7	7	1/0	TTL	
RB2	8	8	I/O	TTL	
RB3	9	9	I/O	TTL	
RB4	10	10	I/O	TTL	Interrupt on change pin.
RB5	11	11	I/O	TTL	Interrupt on change pin.
RB6	12	12	I/O	TTL/ST (2)	Interrupt on change pin. Serial programming clock.
RB7	13	13	1/0	TTL/ST (2)	Interrupt on change pin. Serial programming data.
Vss	5	5	Р	_	Ground reference for logic and I/O pins.
VDD	14	14	Р	_	Positive supply for logic and I/O pins.

Legend: I= input

O = output

I/O = Input/Output

P = power

— = Not used TTL = TTL input

ST = Schmitt Trigger input

- Note 1: This buffer is a Schmitt Trigger input when configured as the external interrupt.
 - 2: This buffer is a Schmitt Trigger input when used in serial programming mode.
 - 3: This buffer is a Schmitt Trigger input when configured in RC oscillator mode and a CMOS input otherwise.

3.1 Clocking Scheme/Instruction Cycle

The clock input (from OSC1) is internally divided by four to generate four non-overlapping quadrature clocks namely Q1, Q2, Q3 and Q4. Internally, the program counter (PC) is incremented every Q1, the instruction is fetched from the program memory and latched into the instruction register in Q4. The instruction is decoded and executed during the following Q1 through Q4. The clocks and instruction execution flow is shown in Figure 3-2.

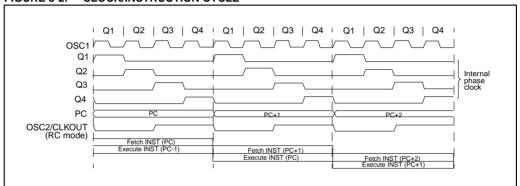
3.2 Instruction Flow/Pipelining

An "Instruction Cycle" consists of four Q cycles (Q1, Q2, Q3 and Q4). The instruction fetch and execute are pipelined such that fetch takes one instruction cycle while decode and execute takes another instruction cycle. However, due to the pipelining, each instruction effectively executes in one cycle. If an instruction causes the program counter to change (e.g., GOTO) then two cycles are required to complete the instruction (Example 3-1).

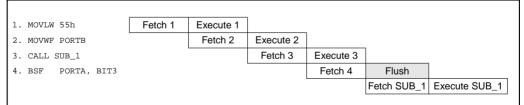
A fetch cycle begins with the Program Counter (PC) incrementing in Q1.

In the execution cycle, the fetched instruction is latched into the "Instruction Register" in cycle Q1. This instruction is then decoded and executed during the Q2, Q3, and Q4 cycles. Data memory is read during Q2 (operand read) and written during Q4 (destination write).

FIGURE 3-2: CLOCK/INSTRUCTION CYCLE



EXAMPLE 3-1: INSTRUCTION PIPELINE FLOW



All instructions are single cycle, except for any program branches. These take two cycles since the fetch instruction is "flushed" from the pipeline while the new instruction is being fetched and then executed.

4.0 MEMORY ORGANIZATION

There are two memory blocks in the PIC16F8X. These are the program memory and the data memory. Each block has its own bus, so that access to each block can occur during the same oscillator cycle.

The data memory can further be broken down into the general purpose RAM and the Special Function Registers (SFRs). The operation of the SFRs that control the "core" are described here. The SFRs used to control the peripheral modules are described in the section discussing each individual peripheral module.

The data memory area also contains the data EEPROM memory. This memory is not directly mapped into the data memory, but is indirectly mapped. That is, an indirect address pointer specifies the address of the data EEPROM memory to read/write. The 64 bytes of data EEPROM memory have the address range 0h-3Fh. More details on the EEPROM memory can be found in Section 7.0.

4.1 Program Memory Organization

The PIC16FXX has a 13-bit program counter capable of addressing an 8K x 14 program memory space. For the PIC16F83 and PIC16CR83, the first 512 x 14 (0000h-01FFh) are physically implemented (Figure 4-1). For the PIC16F84 and PIC16CR84, the first 1K x 14 (0000h-03FFh) are physically implemented (Figure 4-2). Accessing a location above the physically implemented address will cause a wraparound. For example, for the PIC16F84 locations 20h, 420h, 820h, C20h, 1020h, 1420h, 1820h, and 1C20h will be the same instruction.

The reset vector is at 0000h and the interrupt vector is at 0004h.

FIGURE 4-1: PROGRAM MEMORY MAP AND STACK -PIC16F83/CR83

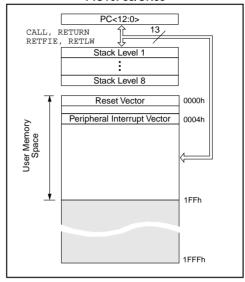
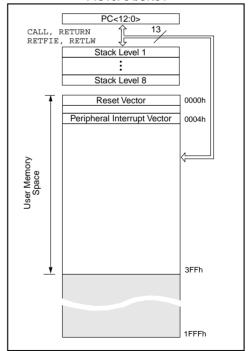


FIGURE 4-2: PROGRAM MEMORY MAP AND STACK -PIC16F84/CR84



4.2 Data Memory Organization

The data memory is partitioned into two areas. The first is the Special Function Registers (SFR) area, while the second is the General Purpose Registers (GPR) area. The SFRs control the operation of the device.

Portions of data memory are banked. This is for both the SFR area and the GPR area. The GPR area is banked to allow greater than 116 bytes of general purpose RAM. The banked areas of the SFR are for the registers that control the peripheral functions. Banking requires the use of control bits for bank selection. These control bits are located in the STATUS Register. Figure 4-1 and Figure 4-2 show the data memory map organization.

Instructions MOVWF and MOVF can move values from the W register to any location in the register file ("F"), and vice-versa.

The entire data memory can be accessed either directly using the absolute address of each register file or indirectly through the File Select Register (FSR) (Section 4.5). Indirect addressing uses the present value of the RP1:RP0 bits for access into the banked areas of data memory.

Data memory is partitioned into two banks which contain the general purpose registers and the special function registers. Bank 0 is selected by clearing the RP0 bit (STATUS<5>). Setting the RP0 bit selects Bank 1. Each Bank extends up to 7Fh (128 bytes). The first twelve locations of each Bank are reserved for the Special Function Registers. The remainder are General Purpose Registers implemented as static RAM.

4.2.1 GENERAL PURPOSE REGISTER FILE

All devices have some amount of General Purpose Register (GPR) area. Each GPR is 8 bits wide and is accessed either directly or indirectly through the FSR (Section 4.5).

The GPR addresses in bank 1 are mapped to addresses in bank 0. As an example, addressing location 0Ch or 8Ch will access the same GPR.

4.2.2 SPECIAL FUNCTION REGISTERS

The Special Function Registers (Figure 4-1, Figure 4-2 and Table 4-1) are used by the CPU and Peripheral functions to control the device operation. These registers are static RAM.

The special function registers can be classified into two sets, core and peripheral. Those associated with the core functions are described in this section. Those related to the operation of the peripheral features are described in the section for that specific feature.

FIGURE 4-1: REGISTER FILE MAP - PIC16F83/CR83

File Addre			ile Address
00h	Indirect addr.(1)	Indirect addr.(1)	80h
01h	TMR0	OPTION	81h
02h	PCL	PCL	82h
03h	STATUS	STATUS	83h
04h	FSR	FSR	84h
05h	PORTA	TRISA	85h
06h	PORTB	TRISB	86h
07h			87h
08h	EEDATA	EECON1	88h
09h	EEADR	EECON2 ⁽¹⁾	89h
0Ah	PCLATH	PCLATH	8Ah
0Bh	INTCON	INTCON	8Bh
0Ch 2Fh 30h	36 General Purpose registers (SRAM)	Mapped (accesses) in Bank 0	AFh B0h
	Bank 0 emented data mei Not a physical reg		FFh d as '0'.

FIGURE 4-2: REGISTER FILE MAP - PIC16F84/CR84

File Addre		F	ile Address						
00h	Indirect addr.(1)	Indirect addr. (1)	80h						
01h	TMR0	OPTION	81h						
02h	PCL	PCL	82h						
03h	STATUS	STATUS	83h						
04h	FSR	FSR	84h						
05h	PORTA	TRISA	85h						
06h	PORTB	TRISB	86h						
07h			87h						
08h	EEDATA	EECON1	88h						
09h	EEADR	EECON2 ⁽¹⁾	89h						
0Ah	PCLATH	PCLATH	8Ah						
0Bh	INTCON	INTCON	8Bh						
0Ch			8Ch						
	68 General Purpose registers (SRAM)	Mapped (accesses) in Bank 0							
4Fh 50h			CFh D0h						
)						
7Fh			FFh						
	Bank 0	Bank 1							
Unimpl	Unimplemented data memory location; read as '0'.								
Note 1:	Not a physical reg	ister.							

TABLE 4-1 REGISTER FILE SUMMARY

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on Power-on Reset	Value on all other resets (Note3)
Bank 0											
00h	INDF	Uses co	ntents of F								
01h	TMR0	8-bit rea	l-time clock	/counter						xxxx xxxx	uuuu uuuu
02h	PCL	Low ord	er 8 bits of	the Program	m Counter (PC)					0000 0000	0000 0000
03h	STATUS (2)	IRP	RP1	RP0	TO	PD	Z	DC	С	0001 1xxx	000q quuu
04h	FSR	Indirect	data memo	ry address	pointer 0			!		xxxx xxxx	uuuu uuuu
05h	PORTA	_	_	_	RA4/T0CKI	RA3	RA2	RA1	RA0	x xxxx	u uuuu
06h	PORTB	RB7	RB6	RB5	RB4	RB3	RB2	RB1	RB0/INT	xxxx xxxx	uuuu uuuu
07h		Unimple	mented loc								
08h	EEDATA	EEPROI	M data regi	ster						xxxx xxxx	uuuu uuuu
09h	EEADR	EEPROM address register								xxxx xxxx	uuuu uuuu
0Ah	PCLATH	_	1	_	Write buffer for	upper 5 bit	s of the PC	(1)		0 0000	0 0000
0Bh	INTCON	GIE	EEIE	TOIE	INTE	RBIE	TOIF	INTF	RBIF	0000 000x	0000 000u
Bank 1											
80h	INDF	Uses co	ntents of F	SR to addre	ess data memor	y (not a phy	sical registe	r)			
81h	OPTION_ REG	RBPU	INTEDG	T0CS	TOSE	PSA	PS2	PS1	PS0	1111 1111	1111 1111
82h	PCL	Low ord	er 8 bits of	Program C	ounter (PC)					0000 0000	0000 0000
83h	STATUS (2)	IRP	RP1	RP0	TO	PD	Z	DC	С	0001 1xxx	000q quuu
84h	FSR	Indirect	data memo	ry address	pointer 0					xxxx xxxx	uuuu uuuu
85h	TRISA	_	_	_	PORTA data d	irection regi	ster			1 1111	1 1111
86h	TRISB	PORTB	data directi	on register	•					1111 1111	1111 1111
87h		Unimplemented location, read as '0'									
88h	EECON1	_	_	_	EEIF	WRERR	WREN	WR	RD	0 x000	0 q000
89h	EECON2	EEPROI	M control re	gister 2 (n	ot a physical reg	ister)					
0Ah	PCLATH	_	_	_	Write buffer for	upper 5 bit	s of the PC	(1)		0 0000	0 0000
0Bh	INTCON	GIE	EEIE	TOIE	INTE	RBIE	T0IF	INTF	RBIF	0000 000x	0000 000u

Legend: x = unknown, u = unchanged. - = unimplemented read as '0', q = value depends on condition.

Note 1: The upper byte of the program counter is not directly accessible. PCLATH is a slave register for PC<12:8>. The contents of PCLATH can be transferred to the upper byte of the program counter, but the contents of PC<12:8> is never transferred to PCLATH.

- 2: The $\overline{\text{TO}}$ and $\overline{\text{PD}}$ status bits in the STATUS register are not affected by a $\overline{\text{MCLR}}$ reset.
- 3: Other (non power-up) resets include: external reset through MCLR and the Watchdog Timer Reset.

STATUS REGISTER 4.2.2.1

The STATUS register contains the arithmetic status of the ALU, the RESET status and the bank select bit for data memory.

As with any register, the STATUS register can be the destination for any instruction. If the STATUS register is the destination for an instruction that affects the Z. DC or C bits, then the write to these three bits is disabled. These bits are set or cleared according to device logic. Furthermore, the TO and PD bits are not writable. Therefore, the result of an instruction with the STATUS register as destination may be different than intended.

For example, CLRF STATUS will clear the upper-three bits and set the Z bit. This leaves the STATUS register as 000u uluu (where u = unchanged).

Only the BCF, BSF, SWAPF and MOVWF instructions should be used to alter the STATUS register (Table 9-2) because these instructions do not affect any status bit.

- Note 1: The IRP and RP1 bits (STATUS<7:6>) are not used by the PIC16F8X and should be programmed as cleared. Use of these bits as general purpose R/W bits is NOT recommended, since this may affect upward compatibility with future products.
- Note 2: The C and DC bits operate as a borrow and digit borrow out bit, respectively, in subtraction. See the SUBLW and SUBWF instructions for examples.
- Note 3: When the STATUS register is the destination for an instruction that affects the Z, DC or C bits, then the write to these three bits is disabled. The specified bit(s) will be updated according to device logic

FIGURE 4-1: STATUS REGISTER (ADDRESS 03h, 83h)

R/W-0	R/W-0	R/W-0	R-1	R-1	R/W-x	R/W-x	R/W-x	
IRP	RP1	RP0	TO	PD	Z	DC	С	R = Readable bit
bit7							bit0	W = Writable bit U = Unimplemented bit, read as '0' - n = Value at POR reset
bit 7:	IRP: Regi	ster Bank	Select bit	(used for	indirect add	ressing)		

- - 0 = Bank 0.1 (00h FFh)
 - 1 = Bank 2. 3 (100h 1FFh)

The IRP bit is not used by the PIC16F8X, IRP should be maintained clear.

- bit 6-5: RP1:RP0: Register Bank Select bits (used for direct addressing)
 - 00 = Bank 0 (00h 7Fh)
 - 01 = Bank 1 (80h FFh)
 - 10 = Bank 2 (100h 17Fh)
 - 11 = Bank 3 (180h 1FFh)

Each bank is 128 bytes. Only bit RP0 is used by the PIC16F8X. RP1 should be maintained clear.

- bit 4: TO: Time-out bit
 - 1 = After power-up, CLRWDT instruction, or SLEEP instruction
 - 0 = A WDT time-out occurred
- bit 3: PD: Power-down bit
 - 1 = After power-up or by the CLRWDT instruction
 - 0 = By execution of the SLEEP instruction
- bit 2: Z: Zero bit
 - 1 = The result of an arithmetic or logic operation is zero
 - 0 = The result of an arithmetic or logic operation is not zero
- bit 1: DC: Digit carry/borrow bit (for ADDLW instructions) (For borrow the polarity is reversed)
 - 1 = A carry-out from the 4th low order bit of the result occurred
 - 0 = No carry-out from the 4th low order bit of the result
- C: Carry/borrow bit (for ADDWF and ADDLW instructions) bit 0:
 - 1 = A carry-out from the most significant bit of the result occurred
 - 0 = No carry-out from the most significant bit of the result occurred

Note: For borrow the polarity is reversed. A subtraction is executed by adding the two's complement of the second operand. For rotate (RRF, RLF) instructions, this bit is loaded with either the high or low order bit of the source register.

4.2.2.2 OPTION_REG REGISTER

The OPTION_REG register is a readable and writable register which contains various control bits to configure the TMR0/WDT prescaler, the external INT interrupt, TMR0, and the weak pull-ups on PORTB.

Note: When the prescaler is assigned to the WDT (PSA = '1'), TMR0 has a 1:1 prescaler assignment.

FIGURE 4-1: OPTION_REG REGISTER (ADDRESS 81h)

R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1							
RBPU	INTEDG	T0CS	T0SE	PSA	PS2	PS1	PS0	R = Readable bit						
bit7							bit0	W = Writable bit						
								U = Unimplemented bit, read as '0'						
								- n = Value at POR reset						
bit 7:	RBPU: PO	RTB Pull-	up Enabl	e bit										
	1 = PORTE													
	0 = PORTB pull-ups are enabled (by individual port latch values)													
bit 6:	INTEDG: Interrupt Edge Select bit													
	1 = Interrupt on rising edge of RB0/INT pin													
		0 = Interrupt on falling edge of RB0/INT pin												
bit 5:		TOCS: TMR0 Clock Source Select bit												
	1 = Transition on RA4/T0CKI pin 0 = Internal instruction cycle clock (CLKOUT)													
F-20 - 4			•	•	(001)									
bit 4:	TOSE: TMF		0		on RA4/T00	`KI nin								
					on RA4/T00									
bit 3:	PSA: Pres		ŭ											
Dit O.	1 = Presca		0											
	0 = Presca													
bit 2-0:	PS2:PS0:	Prescaler	Rate Sel	ect bits										
	Bit Value	TMR0 Ra	ate WD	T Rate										
	000	1:2	1:	: 1										
	001	1:4	l l	: 2										
	010 011	1:8		: 4 : 8										
	100	1:32	1:	: 16										
	101	1:64		32										
	110 111	1:128	· .	: 64 : 128										
		1 1.230												

4.2.2.3 INTCON REGISTER

The INTCON register is a readable and writable register which contains the various enable bits for all interrupt sources.

Interrupt flag bits get set when an interrupt condition occurs regardless of the state of its corresponding enable bit or the global enable bit, GIE (INTCON<7>).

FIGURE 4-1: INTCON REGISTER (ADDRESS 0Bh, 8Bh)

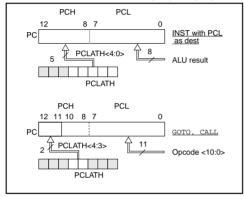
Dav.	D.44.0	D.144.0	D.44.0	D.44.0	D.444.0	D.44.0	D 444							
R/W-0 GIE	R/W-0 EEIE	R/W-0 T0IE	R/W-0 INTE	R/W-0 RBIE	R/W-0 T0IF	R/W-0 INTF	R/W-x RBIF	R = Readable bit						
bit7	CEIC	TOIL		NOIL	1011		bit0	W = Writable bit U = Unimplemented bit, read as '0' - n = Value at POR reset						
bit 7:	GIE: Glob 1 = Enabl 0 = Disab	es all un-r	nasked in											
	Note: For the operation of the interrupt structure, please refer to Section 8.5.													
bit 6:														
bit 5:	1 = Enabl	TolE: TMR0 Overflow Interrupt Enable bit 1 = Enables the TMR0 interrupt 0 = Disables the TMR0 interrupt												
bit 4:	INTE: RB 1 = Enabl 0 = Disab	es the RB	0/INT inte	rrupt										
bit 3:	RBIE: RB 1 = Enabl 0 = Disab	es the RB	port char	ige interru	pt									
bit 2:	TOIF : TMF 1 = TMR0 0 = TMR0	has overf	flowed (m		ared in soft	ware)								
bit 1:	INTF : RB6 1 = The R 0 = The R	B0/INT in	terrupt oc	curred										
bit 0:		at least o	ne of the	RB7:RB4 p			nust be clea	ared in software)						

Note:

4.3 Program Counter: PCL and PCLATH

The Program Counter (PC) is 13-bits wide. The low byte is the PCL register, which is a readable and writable register. The high byte of the PC (PC<12:8>) is not directly readable nor writable and comes from the PCLATH register. The PCLATH (PC latch high) register is a holding register for PC<12:8>. The contents of PCLATH are transferred to the upper byte of the program counter when the PC is loaded with a new value. This occurs during a CALL, GOTO or a write to PCL. The high bits of PC are loaded from PCLATH as shown in Figure 4-1.

FIGURE 4-1: LOADING OF PC IN DIFFERENT SITUATIONS



4.3.1 COMPUTED GOTO

A computed GOTO is accomplished by adding an offset to the program counter (ADDWF PCL). When doing a table read using a computed GOTO method, care should be exercised if the table location crosses a PCL memory boundary (each 256 word block). Refer to the application note "Implementing a Table Read" (AN556).

4.3.2 PROGRAM MEMORY PAGING

The PIC16F83 and PIC16CR83 have 512 words of program memory. The PIC16F84 and PIC16CR84 have 1K of program memory. The CALL and GOTO instructions have an 11-bit address range. This 11-bit address range allows a branch within a 2K program memory page size. For future PIC16F8X program memory expansion, there must be another two bits to specify the program memory page. These paging bits come from the PCLATH<4:3> bits (Figure 4-1). When doing a CALL or a GOTO instruction, the user must ensure that these page bits (PCLATH<4:3>) are programmed to the desired program memory page. If a CALL instruction (or interrupt) is executed, the entire 13-bit PC is "pushed" onto the stack (see next section). Therefore,

manipulation of the PCLATH<4:3> is not required for the return instructions (which "pops" the PC from the stack).

Note:

The PIC16F8X ignores the PCLATH<4:3> bits, which are used for program memory pages 1, 2 and 3 (0800h - 1FFFh). The use of PCLATH<4:3> as general purpose R/W bits is not recommended since this may affect upward compatibility with future products.

4.4 Stack

The PIC16FXX has an 8 deep x 13-bit wide hardware stack (Figure 4-1). The stack space is not part of either program or data space and the stack pointer is not readable or writable.

The entire 13-bit PC is "pushed" onto the stack when a CALL instruction is executed or an interrupt is acknowledged. The stack is "popped" in the event of a RETURN, RETLW or a RETFIE instruction execution. PCLATH is not affected by a push or a pop operation.

Note:

There are no instruction mnemonics called push or pop. These are actions that occur from the execution of the CALL, RETURN, RETLW, and RETFIE instructions, or the vectoring to an interrupt address.

The stack operates as a circular buffer. That is, after the stack has been pushed eight times, the ninth push overwrites the value that was stored from the first push. The tenth push overwrites the second push (and so on).

If the stack is effectively popped nine times, the PC value is the same as the value from the first pop.

Note:

There are no status bits to indicate stack overflow or stack underflow conditions.

4.5 Indirect Addressing; INDF and FSR Registers

The INDF register is not a physical register. Addressing INDF actually addresses the register whose address is contained in the FSR register (FSR is a *pointer*). This is indirect addressing.

EXAMPLE 4-1: INDIRECT ADDRESSING

- · Register file 05 contains the value 10h
- · Register file 06 contains the value 0Ah
- Load the value 05 into the FSR register
- A read of the INDF register will return the value of 10h
- Increment the value of the FSR register by one (FSR = 06)
- A read of the INDF register now will return the value of 0Ah.

Reading INDF itself indirectly (FSR = 0) will produce 00h. Writing to the INDF register indirectly results in a no-operation (although STATUS bits may be affected).

A simple program to clear RAM locations 20h-2Fh using indirect addressing is shown in Example 4-2.

EXAMPLE 4-2: HOW TO CLEAR RAM USING INDIRECT ADDRESSING

```
movlw 0x20 ;initialize pointer
movwf FSR ; to RAM

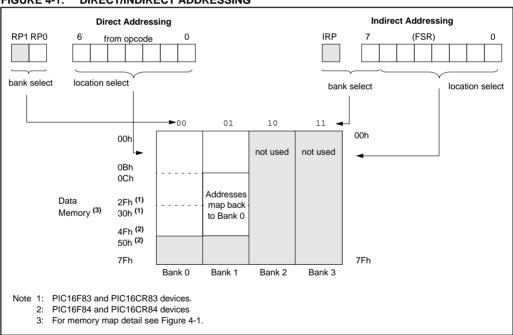
NEXT clrf INDF ;clear INDF register
incf FSR ;inc pointer
btfss FSR,4 ;all done?
goto NEXT ;NO, clear next

CONTINUE

: ;YES, continue
```

An effective 9-bit address is obtained by concatenating the 8-bit FSR register and the IRP bit (STATUS<7>), as shown in Figure 4-1. However, IRP is not used in the PIC16F8X.

FIGURE 4-1: DIRECT/INDIRECT ADDRESSING



NOTES:

5.0 I/O PORTS

The PIC16F8X has two ports, PORTA and PORTB. Some port pins are multiplexed with an alternate function for other features on the device.

5.1 PORTA and TRISA Registers

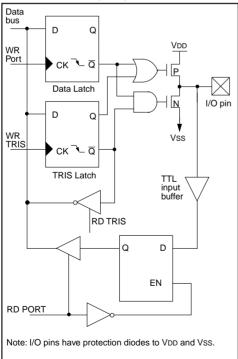
PORTA is a 5-bit wide latch. RA4 is a Schmitt Trigger input and an open drain output. All other RA port pins have TTL input levels and full CMOS output drivers. All pins have data direction bits (TRIS registers) which can configure these pins as output or input.

Setting a TRISA bit (=1) will make the corresponding PORTA pin an input, i.e., put the corresponding output driver in a hi-impedance mode. Clearing a TRISA bit (=0) will make the corresponding PORTA pin an output, i.e., put the contents of the output latch on the selected pin.

Reading the PORTA register reads the status of the pins whereas writing to it will write to the port latch. All write operations are read-modify-write operations. So a write to a port implies that the port pins are first read, then this value is modified and written to the port data latch.

The RA4 pin is multiplexed with the TMR0 clock input.

FIGURE 5-1: BLOCK DIAGRAM OF PINS RA3:RA0



EXAMPLE 5-1: INITIALIZING PORTA

CLRF PORTA ; Initialize PORTA by ; setting output ; data latches RSE STATUS, RPO ; Select Bank 1 MOVLW 0x0F ; Value used to ; initialize data ; direction MOVWE TRISA ; Set RA<3:0> as inputs ; RA4 as outputs ; TRISA<7:5> are always ; read as '0'.

FIGURE 5-2: BLOCK DIAGRAM OF PIN RA4

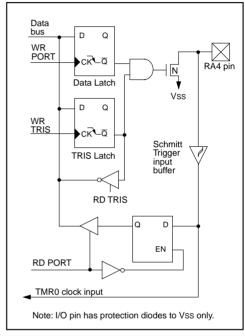


TABLE 5-1 PORTA FUNCTIONS

Name	Bit0	Buffer Type	Function
RA0	bit0	TTL	Input/output
RA1	bit1	TTL	Input/output
RA2	bit2	TTL	Input/output
RA3	bit3	TTL	Input/output
RA4/T0CKI	bit4	ST	Input/output or external clock input for TMR0. Output is open drain type.

Legend: TTL = TTL input, ST = Schmitt Trigger input

TABLE 5-2 SUMMARY OF REGISTERS ASSOCIATED WITH PORTA

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on Power-on Reset	Value on all other resets
05h	PORTA	_	_	_	RA4/T0CKI	RA3	RA2	RA1	RA0	x xxxx	u uuuu
85h	TRISA	_	_	_	TRISA4	TRISA3	TRISA2	TRISA1	TRISA0	1 1111	1 1111

Legend: x = unknown, u = unchanged, - = unimplemented read as '0'. Shaded cells are unimplemented, read as '0'

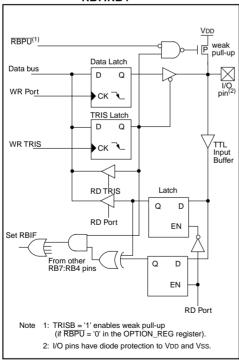
5.2 PORTB and TRISB Registers

PORTB is an 8-bit wide bi-directional port. The corresponding data direction register is TRISB. A '1' on any bit in the TRISB register puts the corresponding output driver in a hi-impedance mode. A '0' on any bit in the TRISB register puts the contents of the output latch on the selected pin(s).

Each of the PORTB pins have a weak internal pull-up. A single control bit can turn on all the pull-ups. This is done by clearing the RBPU (OPTION_REG<7>) bit. The weak pull-up is automatically turned off when the port pin is configured as an output. The pull-ups are disabled on a Power-on Reset.

Four of PORTB's pins, RB7:RB4, have an interrupt on change feature. Only pins configured as inputs can cause this interrupt to occur (i.e., any RB7:RB4 pin configured as an output is excluded from the interrupt on change comparison). The pins value in input mode are compared with the old value latched on the last read of PORTB. The "mismatch" outputs of the pins are OR'ed together to generate the RB port change interrupt.

FIGURE 5-3: BLOCK DIAGRAM OF PINS RB7:RB4



This interrupt can wake the device from SLEEP. The user, in the interrupt service routine, can clear the interrupt in the following manner:

- Read (or write) PORTB. This will end the mismatch condition.
- b) Clear flag bit RBIF.

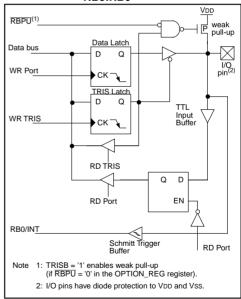
A mismatch condition will continue to set the RBIF bit. Reading PORTB will end the mismatch condition, and allow the RBIF bit to be cleared.

This interrupt on mismatch feature, together with software configurable pull-ups on these four pins allow easy interface to a key pad and make it possible for wake-up on key-depression (see AN552 in the Embedded Control Handbook).

Note 1: For a change on the I/O pin to be recognized, the pulse width must be at least Tcy (4/fosc) wide.

The interrupt on change feature is recommended for wake-up on key depression operation and operations where PORTB is only used for the interrupt on change feature. Polling of PORTB is not recommended while using the interrupt on change feature.

FIGURE 5-4: BLOCK DIAGRAM OF PINS RB3:RB0



EXAMPLE 5-1: INITIALIZING PORTB

CLRF PORTB ; Initialize PORTB by

; setting output
; data latches

BSF STATUS, RPO ; Select Bank 1
MOVLW 0xCF ; Value used to

; Value used to ; initialize data

; direction

MOVWF TRISB ; Set RB<3:0> as inputs

; RB<5:4> as outputs
; RB<7:6> as inputs

TABLE 5-3 PORTB FUNCTIONS

Name	Bit	Buffer Type	I/O Consistency Function
RB0/INT	bit0	TTL/ST ⁽¹⁾	Input/output pin or external interrupt input. Internal software programmable weak pull-up.
RB1	bit1	TTL	Input/output pin. Internal software programmable weak pull-up.
RB2	bit2	TTL	Input/output pin. Internal software programmable weak pull-up.
RB3	bit3	TTL	Input/output pin. Internal software programmable weak pull-up.
RB4	bit4	TTL	Input/output pin (with interrupt on change). Internal software programmable weak pull-up.
RB5	bit5	TTL	Input/output pin (with interrupt on change). Internal software programmable weak pull-up.
RB6	bit6	TTL/ST ⁽²⁾	Input/output pin (with interrupt on change). Internal software programmable weak pull-up. Serial programming clock.
RB7	bit7	TTL/ST ⁽²⁾	Input/output pin (with interrupt on change). Internal software programmable weak pull-up. Serial programming data.

Legend: TTL = TTL input, ST = Schmitt Trigger.

Note 1: This buffer is a Schmitt Trigger input when configured as the external interrupt.

2: This buffer is a Schmitt Trigger input when used in serial programming mode.

TABLE 5-4 SUMMARY OF REGISTERS ASSOCIATED WITH PORTB

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on Power-on Reset	Value on all other resets
06h	PORTB	RB7	RB6	RB5	RB4	RB3	RB2	RB1	RB0/INT	xxxx xxxx	uuuu uuuu
86h	TRISB	TRISB7	TRISB6	TRISB5	TRISB4	TRISB3	TRISB2	TRISB1	TRISB0	1111 1111	1111 1111
81h	OPTION_ REG	RBPU	INTEDG	T0CS	T0SE	PSA	PS2	PS1	PS0	1111 1111	1111 1111

Legend: x = unknown, u = unchanged. Shaded cells are not used by PORTB.

5.3 **I/O Programming Considerations**

5.3.1 BI-DIRECTIONAL I/O PORTS

Any instruction which writes, operates internally as a read followed by a write operation. The BCF and BSF instructions, for example, read the register into the CPU, execute the bit operation and write the result back to the register. Caution must be used when these instructions are applied to a port with both inputs and outputs defined. For example, a BSF operation on bit5 of PORTB will cause all eight bits of PORTB to be read into the CPU. Then the BSF operation takes place on bit5 and PORTB is written to the output latches. If another bit of PORTB is used as a bi-directional I/O pin (i.e., bit0) and it is defined as an input at this time, the input signal present on the pin itself would be read into the CPU and rewritten to the data latch of this particular pin, overwriting the previous content. As long as the pin stavs in the input mode, no problem occurs. However, if bit0 is switched into output mode later on, the content of the data latch is unknown.

Reading the port register, reads the values of the port pins. Writing to the port register writes the value to the port latch. When using read-modify-write instructions (i.e., BCF, BSF, etc.) on a port, the value of the port pins is read, the desired operation is done to this value, and this value is then written to the port latch.

A pin actively outputting a Low or High should not be driven from external devices at the same time in order to change the level on this pin ("wired-or", "wired-and"). The resulting high output current may damage the chip.

5.3.2 SUCCESSIVE OPERATIONS ON I/O PORTS

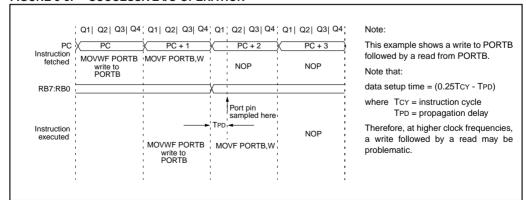
The actual write to an I/O port happens at the end of an instruction cycle, whereas for reading, the data must be valid at the beginning of the instruction cycle (Figure 5-5). Therefore, care must be exercised if a write followed by a read operation is carried out on the same I/O port. The sequence of instructions should be such that the pin voltage stabilizes (load dependent) before the next instruction which causes that file to be read into the CPU is executed. Otherwise, the previous state of that pin may be read into the CPU rather than the new state. When in doubt, it is better to separate these instructions with a NOP or another instruction not accessing this I/O port.

Example 5-1 shows the effect of two sequential read-modify-write instructions (e.g., BCF, BSF, etc.) on an I/O port.

EXAMPLE 5-1: READ-MODIFY-WRITE INSTRUCTIONS ON AN I/O PORT

```
;Initial PORT settings: PORTB<7:4> Inputs
                        PORTB<3:0> Outputs
;PORTB<7:6> have external pull-ups and are
;not connected to other circuitry
                     PORT latch PORT pins
 BCF PORTB, 7
                  ; 01pp ppp
                                 11pp ppp
 BCF PORTB, 6
                  ; 10pp ppp
                                 11pp ppp
 BSF STATUS, RPO ;
 BCF TRISB, 7
                  ; 10pp ppp
                                 מממ ממ11
 BCF TRISB, 6
                  ; 10pp ppp
                                 10pp ppp
; Note that the user may have expected the
;pin values to be 00pp ppp. The 2nd BCF
; caused RB7 to be latched as the pin value
```

FIGURE 5-5: SUCCESSIVE I/O OPERATION



; (high).

NOTES:

6.0 TIMERO MODULE AND TMRO REGISTER

The Timer0 module timer/counter has the following features:

- · 8-bit timer/counter
- · Readable and writable
- · 8-bit software programmable prescaler
- · Internal or external clock select
- Interrupt on overflow from FFh to 00h
- · Edge select for external clock

Timer mode is selected by clearing the TOCS bit (OPTION_REG<5>). In timer mode, the Timer0 module (Figure 6-1) will increment every instruction cycle (without prescaler). If the TMR0 register is written, the increment is inhibited for the following two cycles (Figure 6-2 and Figure 6-3). The user can work around this by writing an adjusted value to the TMR0 register.

Counter mode is selected by setting the T0CS bit (OPTION_REG<5>). In this mode TMR0 will increment either on every rising or falling edge of pin RA4/T0CKI. The incrementing edge is determined by the T0 source

edge select bit, TOSE (OPTION_REG<4>). Clearing bit TOSE selects the rising edge. Restrictions on the external clock input are discussed in detail in Section 6.2.

The prescaler is shared between the Timer0 Module and the Watchdog Timer. The prescaler assignment is controlled, in software, by control bit PSA (OPTION_REG<3>). Clearing bit PSA will assign the prescaler to the Timer0 Module. The prescaler is not readable or writable. When the prescaler (Section 6.3) is assigned to the Timer0 Module, the prescale value (1:2, 1:4, ..., 1:256) is software selectable.

6.1 TMR0 Interrupt

The TMR0 interrupt is generated when the TMR0 register overflows from FFh to 00h. This overflow sets the T0IF bit (INTCON<2>). The interrupt can be masked by clearing enable bit T0IE (INTCON<5>). The T0IF bit must be cleared in software by the Timer0 Module interrupt service routine before re-enabling this interrupt. The TMR0 interrupt (Figure 6-4) cannot wake the processor from SLEEP since the timer is shut off during SLEEP.

FIGURE 6-1: TMR0 BLOCK DIAGRAM

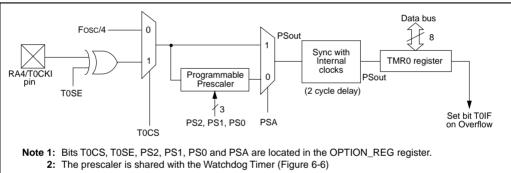


FIGURE 6-2: TMR0 TIMING: INTERNAL CLOCK/NO PRESCALER

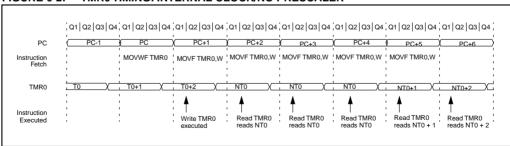


FIGURE 6-3: TMR0 TIMING: INTERNAL CLOCK/PRESCALE 1:2

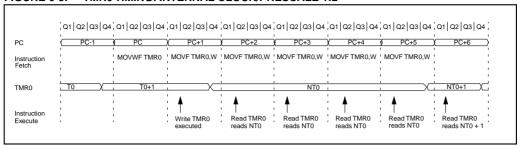
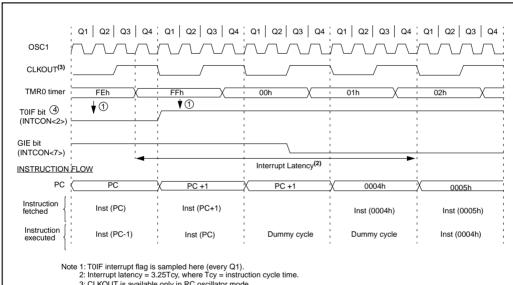


FIGURE 6-4: TMR0 INTERRUPT TIMING



- 3: CLKOUT is available only in RC oscillator mode.
- 4: The timer clock (after the synchronizer circuit) which increments the timer from FFh to 00h immediately sets the T0IF bit. The TMR0 register will roll over 3 Tosc cycles later.

6.2 Using TMR0 with External Clock

When an external clock input is used for TMR0, it must meet certain requirements. The external clock requirement is due to internal phase clock (Tosc) synchronization. Also, there is a delay in the actual incrementing of the TMR0 register after synchronization.

6.2.1 EXTERNAL CLOCK SYNCHRONIZATION

When no prescaler is used, the external clock input is the same as the prescaler output. The synchronization of pin RA4/T0CKI with the internal phase clocks is accomplished by sampling the prescaler output on the Q2 and Q4 cycles of the internal phase clocks (Figure 6-5). Therefore, it is necessary for T0CKI to be high for at least 2Tosc (plus a small RC delay) and low for at least 2Tosc (plus a small RC delay). Refer to the electrical specification of the desired device.

When a prescaler is used, the external clock input is divided by an asynchronous ripple counter type prescaler so that the prescaler output is symmetrical. For the external clock to meet the sampling requirement, the ripple counter must be taken into account. Therefore, it is necessary for TOCKI to have a period of at least 4Tosc (plus a small RC delay) divided by the prescaler value. The only requirement on TOCKI high and low time is that they do not violate the minimum pulse width requirement of 10 ns. Refer to parameters 40, 41 and 42 in the AC Electrical Specifications of the desired device.

6.2.2 TMR0 INCREMENT DELAY

Since the prescaler output is synchronized with the internal clocks, there is a small delay from the time the external clock edge occurs to the time the Timer0 Module is actually incremented. Figure 6-5 shows the delay from the external clock edge to the timer incrementing.

6.3 Prescaler

An 8-bit counter is available as a prescaler for the Timer0 Module, or as a postscaler for the Watchdog Timer (Figure 6-6). For simplicity, this counter is being referred to as "prescaler" throughout this data sheet. Note that there is only one prescaler available which is mutually exclusive between the Timer0 Module and the Watchdog Timer. Thus, a prescaler assignment for the Timer0 Module means that there is no prescaler for the Watchdog Timer, and vice-versa.

The PSA and PS2:PS0 bits (OPTION_REG<3:0>) determine the prescaler assignment and prescale ratio.

When assigned to the Timer0 Module, all instructions writing to the Timer0 Module (e.g., CLRF 1, MOVWF 1, BSF 1, xetc.) will clear the prescaler. When assigned to WDT, a CLRWDT instruction will clear the prescaler along with the Watchdog Timer. The prescaler is not readable or writable.

FIGURE 6-5: TIMERO TIMING WITH EXTERNAL CLOCK

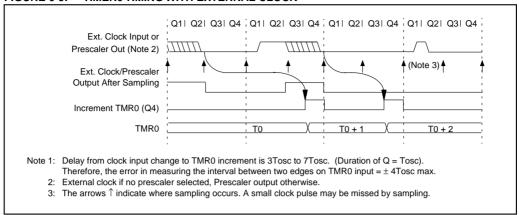
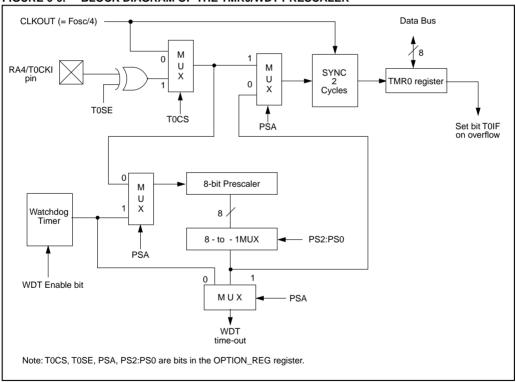


FIGURE 6-6: BLOCK DIAGRAM OF THE TMR0/WDT PRESCALER



6.3.1 SWITCHING PRESCALER ASSIGNMENT

The prescaler assignment is fully under software control (i.e., it can be changed "on the fly" during program execution).

Note: To avoid an unintended device RESET, the following instruction sequence (Example 6-1) must be executed when changing the prescaler assignment from Timer0 to the WDT. This sequence must be taken even if the WDT is disabled. To change prescaler from the WDT to the Timer0 module use the sequence shown in Example 6-2.

EXAMPLE 6-1: CHANGING PRESCALER (TIMER0→WDT)

BCF STATUS, RP0 ;Bank 0

CLRF TMR0 ;Clear TMR0 ; and Prescaler

BSF STATUS, RP0 ;Bank 1

CLRWDT ;Clears WDT

MOVLW b'xxxxlxxx' ;Select new

MOVWF OPTION_REG ; prescale value

EXAMPLE 6-2: CHANGING PRESCALER (WDT→TIMER0)

STATUS, RPO ; Bank 0

CLRWDT ;Clear WDT and ; prescaler

BSF STATUS, RP0 ;Bank 1

MOVLW b'xxxx0xxx' ;Select TMR0, new ; prescale value 'and clock source

MOVWF OPTION_REG ;

BCF STATUS, RP0 ;Bank 0

TABLE 6-1 REGISTERS ASSOCIATED WITH TIMERO

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on Power-on Reset	Value on all other resets
01h	TMR0			xxxx xxxx	uuuu uuuu						
0Bh	INTCON	GIE EEIE TOIE INTE RBIE TOIF INTF RBIF C							0000 000x	0000 0000	
81h	OPTION_ REG	RBPU	INTEDG	T0CS	T0SE	PSA	PS2	PS1	PS0	1111 1111	1111 1111
85h	TRISA	_	_	_	TRISA4	TRISA3	TRISA2	TRISA1	TRISA0	1 1111	1 1111

BCF

Legend: x = unknown, u = unchanged. - = unimplemented read as '0'. Shaded cells are not associated with Timer0.

NOTES:

7.0 DATA FEPROM MEMORY

The EEPROM data memory is readable and writable during normal operation (full VDD range). This memory is not directly mapped in the register file space. Instead it is indirectly addressed through the Special Function Registers. There are four SFRs used to read and write this memory. These registers are:

- EECON1
- EECON2
- EEDATA
- EEADR

EEDATA holds the 8-bit data for read/write, and EEADR holds the address of the EEPROM location being accessed. PIC16F8X devices have 64 bytes of data EEPROM with an address range from 0h to 3Fh.

The EEPROM data memory allows byte read and write.

A byte write automatically erases the location and writes the new data (erase before write). The EEPROM

data memory is rated for high erase/write cycles. The write time is controlled by an on-chip timer. The write-time will vary with voltage and temperature as well as from chip to chip. Please refer to AC specifications for exact limits

When the device is code protected, the CPU may continue to read and write the data EEPROM memory. The device programmer can no longer access this memory.

7.1 EEADR

The EEADR register can address up to a maximum of 256 bytes of data EEPROM. Only the first 64 bytes of data EEPROM are implemented.

The upper two bits are address decoded. This means that these two bits must always be '0' to ensure that the address is in the 64 byte memory space.

FIGURE 7-1: EECON1 REGISTER (ADDRESS 88h)

U	U	U	R/W-0	R/W-x	R/W-0	R/S-0	R/S-x				
_	_	_	EEIF	WRERR	WREN	WR	RD	R = Readable bit			
bit7							bit0	W = Writable bit S = Settable bit U = Unimplemented bit, read as '0' - n = Value at POR reset			
bit 7:5	Unimplem	nented: F	Read as 'C) ¹							
bit 4	EEIF: EEPROM Write Operation Interrupt Flag bit 1 = The write operation completed (must be cleared in software) 0 = The write operation is not complete or has not been started										
bit 3	WRERR: EEPROM Error Flag bit 1 = A write operation is prematurely terminated (any MCLR reset or any WDT reset during normal operation) 0 = The write operation completed										
bit 2	WREN: EEPROM Write Enable bit 1 = Allows write cycles 0 = Inhibits write to the data EEPROM										
bit 1		s a write (not clea	cycle. (The red) in so	ftware.	•	ardware on	ice write is	complete. The WR bit can only			
bit 0		es an EE (not clea	PROM rea	ftware).	ikes one cy	/cle. RD is	cleared in	hardware. The RD bit can only			

7.2 EECON1 and EECON2 Registers

EECON1 is the control register with five low order bits physically implemented. The upper-three bits are non-existent and read as '0's.

Control bits RD and WR initiate read and write, respectively. These bits cannot be cleared, only set, in software. They are cleared in hardware at completion of the read or write operation. The inability to clear the WR bit in software prevents the accidental, premature termination of a write operation.

The WREN bit, when set, will allow a write operation. On power-up, the WREN bit is clear. The WRERR bit is set when a write operation is interrupted by a $\overline{\text{MCLR}}$ reset or a WDT time-out reset during normal operation. In these situations, following reset, the user can check the WRERR bit and rewrite the location. The data and address will be unchanged in the EEDATA and EEADR registers.

Interrupt flag bit EEIF is set when write is complete. It must be cleared in software.

EECON2 is not a physical register. Reading EECON2 will read all '0's. The EECON2 register is used exclusively in the Data EEPROM write sequence.

7.3 Reading the EEPROM Data Memory

To read a data memory location, the user must write the address to the EEADR register and then set control bit RD (EECON1<0>). The data is available, in the very next cycle, in the EEDATA register; therefore it can be read in the next instruction. EEDATA will hold this value until another read or until it is written to by the user (during a write operation).

EXAMPLE 7-1: DATA EEPROM READ

```
BCF
       STATUS, RPO ; Bank 0
MOVLW
       CONFIG ADDR ;
MOVWF
       EEADR
                    ; Address to read
       STATUS, RPO ; Bank 1
BSF
BSF
       EECON1, RD ; EE Read
       STATUS, RPO ; Bank 0
BCF
MOVF
       EEDATA, W
                  ; W = EEDATA
```

7.4 Writing to the EEPROM Data Memory

To write an EEPROM data location, the user must first write the address to the EEADR register and the data to the EEDATA register. Then the user must follow a specific sequence to initiate the write for each byte.

EXAMPLE 7-1: DATA EEPROM WRITE

	BSF	STATUS, RP0	;	Bank 1
	BCF	INTCON, GIE	;	Disable INTs.
	BSF	EECON1, WREN	;	Enable Write
	MOVLW	55h	;	
	MOVWF	EECON2	;	Write 55h
<u> </u>	MOVLW	AAh	;	
Required Sequence	MOVWF	EECON2	;	Write AAh
1 g	BSF	EECON1,WR	;	Set WR bit
Se			;	begin write
	BSF	INTCON, GIE	;	Enable INTs.

The write will not initiate if the above sequence is not exactly followed (write 55h to EECON2, write AAh to EECON2, then set WR bit) for each byte. We strongly recommend that interrupts be disabled during this code segment.

Additionally, the WREN bit in EECON1 must be set to enable write. This mechanism prevents accidental writes to data EEPROM due to errant (unexpected) code execution (i.e., lost programs). The user should keep the WREN bit clear at all times, except when updating EEPROM. The WREN bit is not cleared by hardware

After a write sequence has been initiated, clearing the WREN bit will not affect this write cycle. The WR bit will be inhibited from being set unless the WREN bit is set.

At the completion of the write cycle, the WR bit is cleared in hardware and the EE Write Complete Interrupt Flag bit (EEIF) is set. The user can either enable this interrupt or poll this bit. EEIF must be cleared by software.

7.5 Write Verify

Depending on the application, good programming practice may dictate that the value written to the Data EEPROM should be verified (Example 7-1) to the desired value to be written. This should be used in applications where an EEPROM bit will be stressed near the specification limit. The Total Endurance disk will help determine your comfort level.

Generally the EEPROM write failure will be a bit which was written as a '1', but reads back as a '0' (due to leakage off the bit).

EXAMPLE 7-1: WRITE VERIFY

```
BCE
         STATUS, RPO; Bank 0
   .
                    ; Any code can go here
   .
   MOVF EEDATA, W ; Must be in Bank 0
   BSF
         STATUS, RPO; Bank 1
READ
   BSF
         EECON1, RD ; YES, Read the
                    ; value written
         STATUS, RPO ; Bank 0
;
; Is the value written (in W reg) and
   read (in EEDATA) the same?
;
   SUBWF EEDATA, W
   BTFSS STATUS, Z
                    ; Is difference 0?
```

```
GOTO WRITE_ERR ; NO, Write error
: ; YES, Good write
: ; Continue program
```

7.6 Protection Against Spurious Writes

There are conditions when the device may not want to write to the data EEPROM memory. To protect against spurious EEPROM writes, various mechanisms have been built in. On power-up, WREN is cleared. Also, the Power-up Timer (72 ms duration) prevents EEPROM write.

The write initiate sequence and the WREN bit together help prevent an accidental write during brown-out, power glitch, or software malfunction.

7.7 <u>Data EEPROM Operation during Code</u> Protect

When the device is code protected, the CPU is able to read and write unscrambled data to the Data EEPROM.

For ROM devices, there are two code protection bits (Section 8.1). One for the ROM program memory and one for the Data EEPROM memory.

TABLE 7-1 REGISTERS/BITS ASSOCIATED WITH DATA EEPROM

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on Power-on Reset	Value on all other resets
08h	EEDATA	EEPROM (data regis		xxxx xxxx	uuuu uuuu					
09h	EEADR	EEPROM :	address re		xxxx xxxx	uuuu uuuu					
88h	EECON1	EEIF WRERR WREN WR RD							0 x000	0 q000	
89h	EECON2	EEPROM (control reg								

Legend: x = unknown, u = unchanged, - = unimplemented read as '0', q = value depends upon condition. Shaded cells are not used by Data EEPROM.

NOTES:

8.0 SPECIAL FEATURES OF THE

What sets a microcontroller apart from other processors are special circuits to deal with the needs of real time applications. The PIC16F8X has a host of such features intended to maximize system reliability, minimize cost through elimination of external components, provide power saving operating modes and offer code protection. These features are:

- OSC Selection
- Reset
 - Power-on Reset (POR)
 - Power-up Timer (PWRT)
 - Oscillator Start-up Timer (OST)
- Interrupts
- · Watchdog Timer (WDT)
- SLEEP
- · Code protection
- · ID locations
- · In-circuit serial programming

The PIC16F8X has a Watchdog Timer which can be shut off only through configuration bits. It runs off its own RC oscillator for added reliability. There are two timers that offer necessary delays on power-up. One is the Oscillator Start-up Timer (OST), intended to keep the chip in reset until the crystal oscillator is stable. The other is the Power-up Timer (PWRT), which provides a fixed delay of 72 ms (nominal) on power-up only. This design keeps the device in reset while the power supply stabilizes. With these two timers on-chip, most applications need no external reset circuitry.

SLEEP mode offers a very low current power-down mode. The user can wake-up from SLEEP through external reset, Watchdog Timer time-out or through an interrupt. Several oscillator options are provided to allow the part to fit the application. The RC oscillator option saves system cost while the LP crystal option saves power. A set of configuration bits are used to select the various options.

8.1 Configuration Bits

The configuration bits can be programmed (read as '0') or left unprogrammed (read as '1') to select various device configurations. These bits are mapped in program memory location 2007h.

Address 2007h is beyond the user program memory space and it belongs to the special test/configuration memory space (2000h - 3FFFh). This space can only be accessed during programming.

To find out how to program the PIC16C84, refer to *PIC16C84 EEPROM Memory Programming Specification* (DS30189).

FIGURE 8-1: CONFIGURATION WORD - PIC16CR83 AND PIC16CR84

R-u R-u R-u R-u R-u R-u R/P-u R-u R-u R-u R-u R-u R-u R-u СР CP CP СР СР СР DP СР СР CP PWRTE WDTE FOSC1 FOSC0 bit13 R = Readable bit P = Programmable bit - n = Value at POR reset u = unchanged bit 13:8 CP: Program Memory Code Protection bit 1 = Code protection off 0 = Program memory is code protected DP: Data Memory Code Protection bit bit 7 1 = Code protection off 0 = Data memory is code protected CP: Program Memory Code Protection bit bit 6:4 1 = Code protection off 0 = Program memory is code protected bit 3 **PWRTE**: Power-up Timer Enable bit 1 = Power-up timer is disabled 0 = Power-up timer is enabled WDTE: Watchdog Timer Enable bit bit 2 1 = WDT enabled 0 = WDT disabled bit 1:0 FOSC1:FOSC0: Oscillator Selection bits 11 = RC oscillator 10 = HS oscillator 01 = XT oscillator 00 = LP oscillator

FIGURE 8-2: CONFIGURATION WORD - PIC16F83 AND PIC16F84

R/P-u	R/P-u	R/P-u	R/P-u	R/P-u	R/P-u	R/P-u	R/P-u	R/P-u	R/P-u	R/P-u	R/P-u	R/P-u	R/P-u
CP	CP	СР	CP	СР	CP	СР	CP	CP	CP	PWRTE	WDTE	FOSC1	FOSC0
bit13								•		•			bit0
												1	adable bit
													ogrammable bit
												1	ue at POR reset unchanged
bit 13:4	CP:	Code F	Protecti	on bit									
			rotectio										
	0 = R	0 = All memory is code protected											
bit 3	PWF	RTE: Po	ower-up	Time	r Enabl	e bit							
	1 = F	ower-	up time	r is dis	abled								
	0 = I	0 = Power-up timer is enabled											
bit 2	WD	Γ E : Wa	tchdog	Timer	Enable	bit							
		NDT e											
	0 = \	NDT di	isabled										
bit 1:0			SC0 : 0		or Sele	ction b	its						
			scillator										
			scillator scillator										
			cillator										
	- 00	: 03	omator										

8.2 Oscillator Configurations

8.2.1 OSCILLATOR TYPES

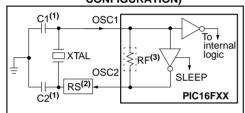
The PIC16F8X can be operated in four different oscillator modes. The user can program two configuration bits (FOSC1 and FOSC0) to select one of these four modes:

- LP Low Power Crystal
- XT Crystal/Resonator
- HS High Speed Crystal/Resonator
- RC Resistor/Capacitor

8.2.2 CRYSTAL OSCILLATOR / CERAMIC RESONATORS

In XT, LP or HS modes a crystal or ceramic resonator is connected to the OSC1/CLKIN and OSC2/CLKOUT pins to establish oscillation (Figure 8-3).

FIGURE 8-3: CRYSTAL/CERAMIC
RESONATOR OPERATION
(HS, XT OR LP OSC
CONFIGURATION)



Note1: See Table 8-1 for recommended values of C1 and C2.

- 2: A series resistor (RS) may be required for AT strip cut crystals.
- 3: RF varies with the crystal chosen.

The PIC16F8X oscillator design requires the use of a parallel cut crystal. Use of a series cut crystal may give a frequency out of the crystal manufacturers specifications. When in XT, LP or HS modes, the device can have an external clock source to drive the OSC1/CLKIN pin (Figure 8-4).

FIGURE 8-4: EXTERNAL CLOCK INPUT OPERATION (HS, XT OR LP OSC CONFIGURATION)

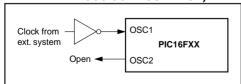


TABLE 8-1 CAPACITOR SELECTION FOR CERAMIC RESONATORS

Ranges Tested:							
Mode	Freq	OSC1/C1	OSC2/C2				
XT	455 kHz	47 - 100 pF	47 - 100 pF				
	2.0 MHz	15 - 33 pF	15 - 33 pF				
	4.0 MHz	15 - 33 pF	15 - 33 pF				
HS	8.0 MHz	15 - 33 pF	15 - 33 pF				
	10.0 MHz	15 - 33 pF	15 - 33 pF				

Note: Recommended values of C1 and C2 are identical to the ranges tested table.

Higher capacitance increases the stability of the oscillator but also increases the start-up time. These values are for design guidance only. Since each resonator has its own characteristics, the user should consult the resonator manufacturer for the appropriate values of external components.

Resonators	Tested:	
455 kHz	Panasonic EFO-A455K04B	± 0.3%
2.0 MHz	Murata Erie CSA2.00MG	± 0.5%
4.0 MHz	Murata Erie CSA4.00MG	± 0.5%
8.0 MHz	Murata Erie CSA8.00MT	± 0.5%
10.0 MHz	Murata Erie CSA10.00MTZ	± 0.5%

None of the resonators had built-in capacitors.

TABLE 8-2 CAPACITOR SELECTION
FOR CRYSTAL OSCILLATOR

Mode	Freq	OSC1/C1	OSC2/C2
LP	32 kHz	68 - 100 pF	68 - 100 pF
	200 kHz	15 - 33 pF	15 - 33 pF
XT	100 kHz	100 - 150 pF	100 - 150 pF
	2 MHz	15 - 33 pF	15 - 33 pF
	4 MHz	15 - 33 pF	15 - 33 pF
HS	4 MHz	15 - 33 pF	15 - 33 pF
	10 MHz	15 - 33 pF	15 - 33 pF

Note: Higher capacitance increases the stability of oscillator but also increases the start-up time. These values are for design guidance only. Rs may be required in HS mode as well as XT mode to avoid overdriving crystals with low drive level specification. Since each crystal has its own characteristics, the user should consult the crystal manufacturer for appropriate values of external components.

For VDD > 4.5V, C1 = C2 \approx 30 pF is recommended.

Crystals Tested:

32.768 kHz	Epson C-001R32.768K-A	± 20 PPM
100 kHz	Epson C-2 100.00 KC-P	± 20 PPM
200 kHz	STD XTL 200.000 KHz	± 20 PPM
1.0 MHz	ECS ECS-10-13-2	± 50 PPM
2.0 MHz	ECS ECS-20-S-2	± 50 PPM
4.0 MHz	ECS ECS-40-S-4	± 50 PPM
10.0 MHz	ECS ECS-100-S-4	± 50 PPM

8.2.3 EXTERNAL CRYSTAL OSCILLATOR CIRCUIT

Either a prepackaged oscillator can be used or a simple oscillator circuit with TTL gates can be built. Prepackaged oscillators provide a wide operating range and better stability. A well-designed crystal oscillator will provide good performance with TTL gates. Two types of crystal oscillator circuits are available; one with series resonance, and one with parallel resonance.

Figure 8-5 shows a parallel resonant oscillator circuit. The circuit is designed to use the fundamental frequency of the crystal. The 74AS04 inverter performs the 180-degree phase shift that a parallel oscillator requires. The 4.7 k Ω resistor provides negative feedback for stability. The 10 k Ω potentiometer biases the 74AS04 in the linear region. This could be used for external oscillator designs.

FIGURE 8-5: EXTERNAL PARALLEL RESONANT CRYSTAL OSCILLATOR CIRCUIT

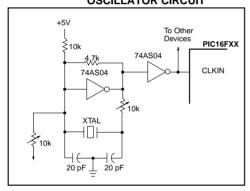
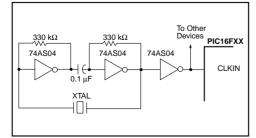


Figure 8-6 shows a series resonant oscillator circuit. This circuit is also designed to use the fundamental frequency of the crystal. The inverter performs a 180-degree phase shift. The 330 $k\Omega$ resistors provide the negative feedback to bias the inverters in their linear region.

FIGURE 8-6: EXTERNAL SERIES
RESONANT CRYSTAL
OSCILLATOR CIRCUIT



8.2.4 RC OSCILLATOR

For timing insensitive applications the RC device option offers additional cost savings. The RC oscillator frequency is a function of the supply voltage, the resistor (Rext) values, capacitor (Cext) values, and the operating temperature. In addition to this, the oscillator frequency will vary from unit to unit due to normal process parameter variation Furthermore the difference in lead frame capacitance between package types also affects the oscillation frequency, especially for low Cext values. The user needs to take into account variation due to tolerance of the external R and C components. Figure 8-7 shows how an R/C combination is connected to the PIC16F8X. For Rext values below $4 k\Omega$, the oscillator operation may become unstable, or stop completely. For very high Rext values (e.g., $1 \text{ M}\Omega$), the oscillator becomes sensitive to noise, humidity and leakage. Thus, we recommend keeping Rext between 5 k Ω and 100 k Ω .

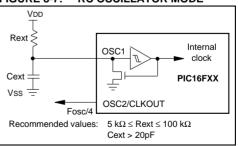
Although the oscillator will operate with no external capacitor (Cext = 0 pF), we recommend using values above 20 pF for noise and stability reasons. With little or no external capacitance, the oscillation frequency can vary dramatically due to changes in external capacitances, such as PCB trace capacitance or package lead frame capacitance.

See the electrical specification section for RC frequency variation from part to part due to normal process variation. The variation is larger for larger R (since leakage current variation will affect RC frequency more for large R) and for smaller C (since variation of input capacitance has a greater affect on RC frequency).

See the electrical specification section for variation of oscillator frequency due to VDD for given Rext/Cext values as well as frequency variation due to operating temperature.

The oscillator frequency, divided by 4, is available on the OSC2/CLKOUT pin, and can be used for test purposes or to synchronize other logic (see Figure 3-2 for waveform).

FIGURE 8-7: RC OSCILLATOR MODE



Note: When the device oscillator is in RC mode, do not drive the OSC1 pin with an external clock or you may damage the device.

8.3 Reset

The PIC16F8X differentiates between various kinds of reset:

- · Power-on Reset (POR)
- MCLR reset during normal operation
- MCLR reset during SLEEP
- WDT Reset (during normal operation)
- WDT Wake-up (during SLEEP)

Figure 8-8 shows a simplified block diagram of the on-chip reset circuit. The $\overline{\text{MCLR}}$ reset path has a noise filter to ignore small pulses. The electrical specifications state the pulse width requirements for the $\overline{\text{MCLR}}$ pin.

Some registers are not affected in any reset condition; their status is unknown on a POR reset and unchanged in any other reset. Most other registers are reset to a "reset state" on POR, MCLR or WDT reset during normal operation and on MCLR reset during SLEEP. They are not affected by a WDT reset during SLEEP, since this reset is viewed as the resumption of normal operation.

Table 8-3 gives a description of reset conditions for the program counter (PC) and the STATUS register. Table 8-4 gives a full description of reset states for all registers.

The TO and PD bits are set or cleared differently in different reset situations (Section 8.7). These bits are used in software to determine the nature of the reset.

FIGURE 8-8: SIMPLIFIED BLOCK DIAGRAM OF ON-CHIP RESET CIRCUIT

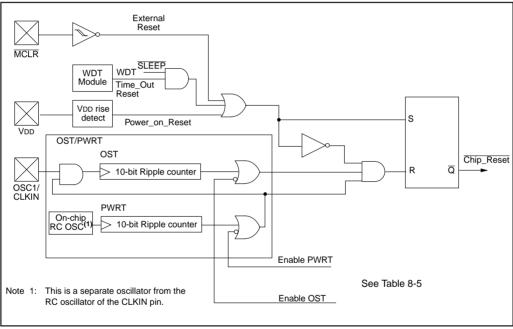


TABLE 8-3 RESET CONDITION FOR PROGRAM COUNTER AND THE STATUS REGISTER

Condition	Program Counter	STATUS Register
Power-on Reset	000h	0001 1xxx
MCLR Reset during normal operation	000h	000u uuuu
MCLR Reset during SLEEP	000h	0001 0uuu
WDT Reset (during normal operation)	000h	0000 1uuu
WDT Wake-up	PC + 1	uuu0 0uuu
Interrupt wake-up from SLEEP	PC + 1 ⁽¹⁾	uuu1 0uuu

Legend: u = unchanged, x = unknown.

Note 1: When the wake-up is due to an interrupt and the GIE bit is set, the PC is loaded with the interrupt vector (0004h).

TABLE 8-4 RESET CONDITIONS FOR ALL REGISTERS

Register	Address	Power-on Reset	MCLR Reset during: - normal operation - SLEEP WDT Reset during normal operation	Wake-up from SLEEP: – through interrupt – through WDT Time-out
W	_	xxxx xxxx	uuuu uuuu	uuuu uuuu
INDF	00h			
TMR0	01h	xxxx xxxx	uuuu uuuu	uuuu uuuu
PCL	02h	0000h	0000h	PC + 1 ⁽²⁾
STATUS	03h	0001 1xxx	000q quuu ⁽³⁾	uuuq quuu ⁽³⁾
FSR	04h	xxxx xxxx	uuuu uuuu	uuuu uuuu
PORTA	05h	x xxxx	u uuuu	u uuuu
PORTB	06h	xxxx xxxx	uuuu uuuu	uuuu uuuu
EEDATA	08h	xxxx xxxx	uuuu uuuu	uuuu uuuu
EEADR	09h	xxxx xxxx	uuuu uuuu	uuuu uuuu
PCLATH	0Ah	0 0000	0 0000	u uuuu
INTCON	0Bh	0000 000x	0000 000u	uuuu uuuu ⁽¹⁾
INDF	80h			
OPTION_REG	81h	1111 1111	1111 1111	uuuu uuuu
PCL	82h	0000h	0000h	PC + 1
STATUS	83h	0001 1xxx	000q quuu ⁽³⁾	uuuq quuu ⁽³⁾
FSR	84h	xxxx xxxx	uuuu uuuu	uuuu uuuu
TRISA	85h	1 1111	1 1111	u uuuu
TRISB	86h	1111 1111	1111 1111	uuuu uuuu
EECON1	88h	0 x000	0 q000	0 uuuu
EECON2	89h			
PCLATH	8Ah	0 0000	0 0000	u uuuu
INTCON	8Bh	0000 000x	0000 000u	uuuu uuuu ⁽¹⁾

Legend: u= unchanged, x= unknown, -= unimplemented bit read as '0', q= value depends on condition.

Note 1: One or more bits in INTCON will be affected (to cause wake-up).

^{2:} When the wake-up is due to an interrupt and the GIE bit is set, the PC is loaded with the interrupt vector (0004h).

^{3:} Table 8-3 lists the reset value for each specific condition.

8.4 Power-on Reset (POR)

A Power-on Reset pulse is generated on-chip when VDD rise is detected (in the range of 1.2V - 1.7V). To take advantage of the POR, just tie the $\overline{\text{MCLR}}$ pin directly (or through a resistor) to VDD. This will eliminate external RC components usually needed to create Power-on Reset. A minimum rise time for VDD must be met for this to operate properly. See Electrical Specifications for details.

When the device starts normal operation (exits the reset condition), device operating parameters (voltage, frequency, temperature, ...) must be meet to ensure operation. If these conditions are not met, the device must be held in reset until the operating conditions are met.

For additional information, refer to Application Note AN607, "Power-up Trouble Shooting."

The POR circuit does not produce an internal reset when VDD declines.

8.5 Power-up Timer (PWRT)

The Power-up Timer (PWRT) provides a fixed 72 ms nominal time-out (TPWRT) from POR (Figure 8-10, Figure 8-11, Figure 8-12 and Figure 8-13). The Power-up Timer operates on an internal RC oscillator. The chip is kept in reset as long as the PWRT is active. The PWRT delay allows the VDD to rise to an acceptable level (Possible exception shown in Figure 8-13).

A configuration bit, PWRTE, can enable/disable the PWRT. See either Figure 8-1 or Figure 8-2 for the operation of the PWRTE bit for a particular device.

The power-up time delay TPWRT will vary from chip to chip due to VDD, temperature, and process variation. See DC parameters for details.

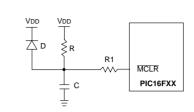
8.6 Oscillator Start-up Timer (OST)

The Oscillator Start-up Timer (OST) provides a 1024 oscillator cycle delay (from OSC1 input) after the PWRT delay ends (Figure 8-10, Figure 8-11, Figure 8-12 and Figure 8-13). This ensures the crystal oscillator or resonator has started and stabilized.

The OST time-out (Tost) is invoked only for XT, LP and HS modes and only on Power-on Reset or wake-up from SLEEP.

When VDD rises very slowly, it is possible that the TPWRT time-out and TOST time-out will expire before VDD has reached its final value. In this case (Figure 8-13), an external power-on reset circuit may be necessary (Figure 8-9).

FIGURE 8-9: EXTERNAL POWER-ON RESET CIRCUIT (FOR SLOW VDD POWER-UP)



- Note 1: External Power-on Reset circuit is required only if VDD power-up rate is too slow. The diode D helps discharge the capacitor quickly when VDD powers down.
 - 2: $R < 40 \text{ k}\Omega$ is recommended to make sure that voltage drop across R does not exceed 0.2V (max leakage current spec on \overline{MCLR} pin is 5 μ A). A larger voltage drop will degrade VIH level on the \overline{MCLR} pin.
 - 3: R1 = 100Ω to 1 k Ω will limit any current flowing into \overline{MCLR} from external capacitor C in the event of an \overline{MCLR} pin breakdown due to ESD or EOS.

FIGURE 8-10: TIME-OUT SEQUENCE ON POWER-UP (MCLR NOT TIED TO VDD): CASE 1

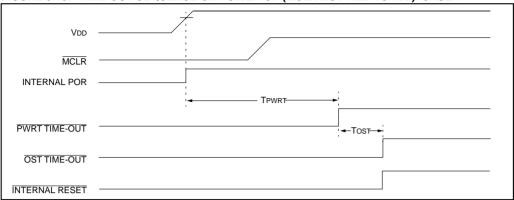
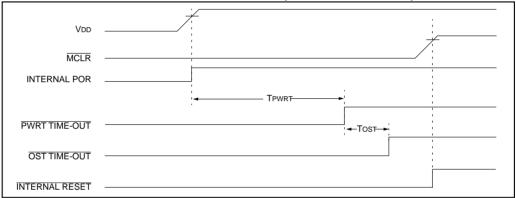


FIGURE 8-11: TIME-OUT SEQUENCE ON POWER-UP (MCLR NOT TIED TO VDD): CASE 2





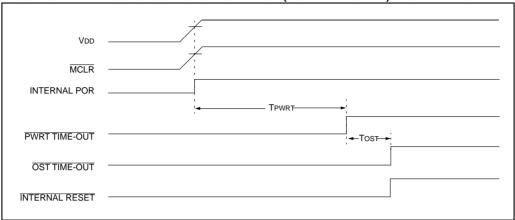
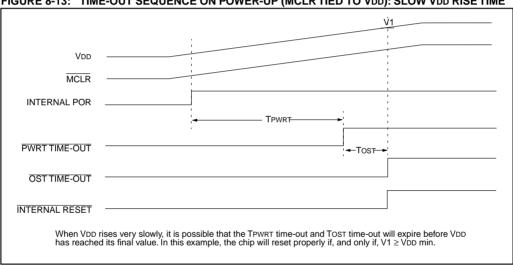


FIGURE 8-13: TIME-OUT SEQUENCE ON POWER-UP (MCLR TIED TO VDD): SLOW VDD RISETIME



8.7 <u>Time-out Sequence and Power-down</u> Status Bits (TO/PD)

On power-up (Figure 8-10, Figure 8-11, Figure 8-12 and Figure 8-13) the time-out sequence is as follows: First PWRT time-out is invoked after a POR has expired. Then the OST is activated. The total time-out will vary based on oscillator configuration and PWRTE configuration bit status. For example, in RC mode with the PWRT disabled, there will be no time-out at all.

TABLE 8-5 TIME-OUT IN VARIOUS SITUATIONS

Oscillator	Pow	Wake-up	
Configuration	PWRT Enabled	PWRT Disabled	from SLEEP
XT, HS, LP	72 ms + 1024Tosc	1024Tosc	1024Tosc
RC	72 ms	_	

Since the time-outs occur from the POR reset pulse, if $\overline{\text{MCLR}}$ is kept low long enough, the time-outs will expire. Then bringing $\overline{\text{MCLR}}$ high, execution will begin immediately (Figure 8-10). This is useful for testing purposes or to synchronize more than one PIC16F8X device when operating in parallel.

Table 8-6 shows the significance of the $\overline{\text{TO}}$ and $\overline{\text{PD}}$ bits. Table 8-3 lists the reset conditions for some special registers, while Table 8-4 lists the reset conditions for all the registers.

TABLE 8-6 STATUS BITS AND THEIR SIGNIFICANCE

то	PD	Condition
1	1	Power-on Reset
0	x	Illegal, TO is set on POR
x	0	Illegal, PD is set on POR
0	1	WDT Reset (during normal operation)
0	0	WDT Wake-up
1	1	MCLR Reset during normal operation
1	0	MCLR Reset during SLEEP or interrupt wake-up from SLEEP

8.8 Reset on Brown-Out

A brown-out is a condition where device power (VDD) dips below its minimum value, but not to zero, and then recovers. The device should be reset in the event of a brown-out

To reset a PIC16F8X device when a brown-out occurs, external brown-out protection circuits may be built, as shown in Figure 8-14 and Figure 8-15.

FIGURE 8-14: BROWN-OUT PROTECTION CIRCUIT 1

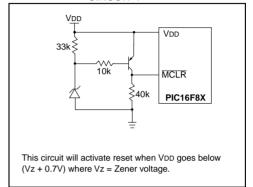
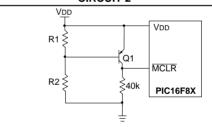


FIGURE 8-15: BROWN-OUT PROTECTION CIRCUIT 2



This brown-out circuit is less expensive, although less accurate. Transistor Q1 turns off when VDD is below a certain level such that:

$$V_{DD} \bullet \frac{R1}{R1 + R2} = 0.7V$$

8.9 Interrupts

The PIC16F8X has 4 sources of interrupt:

- · External interrupt RB0/INT pin
- · TMR0 overflow interrupt
- PORTB change interrupts (pins RB7:RB4)
- Data EEPROM write complete interrupt

The interrupt control register (INTCON) records individual interrupt requests in flag bits. It also contains the individual and global interrupt enable bits.

The global interrupt enable bit, GIE (INTCON<7>) enables (if set) all un-masked interrupts or disables (if cleared) all interrupts. Individual interrupts can be disabled through their corresponding enable bits in INTCON register. Bit GIE is cleared on reset.

The "return from interrupt" instruction, RETFIE, exits interrupt routine as well as sets the GIE bit, which re-enable interrupts.

The RB0/INT pin interrupt, the RB port change interrupt and the TMR0 overflow interrupt flags are contained in the INTCON register.

When an interrupt is responded to; the GIE bit is cleared to disable any further interrupt, the return address is pushed onto the stack and the PC is loaded with 0004h. For external interrupt events, such as the RB0/INT pin or PORTB change interrupt, the interrupt latency will be three to four instruction cycles. The exact latency depends when the interrupt event occurs (Figure 8-17). The latency is the same for both one and two cycle instructions. Once in the interrupt service routine the source(s) of the interrupt can be determined by polling the interrupt flag bits. The interrupt flag bit(s) must be cleared in software before re-enabling interrupts to avoid infinite interrupt requests.

Note 1: Individual interrupt flag bits are set regardless of the status of their corresponding mask bit or the GIE bit.

FIGURE 8-16: INTERRUPT LOGIC

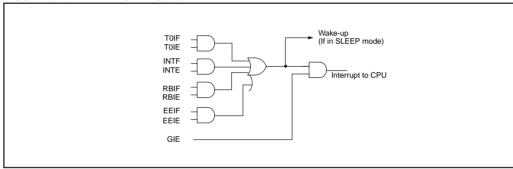
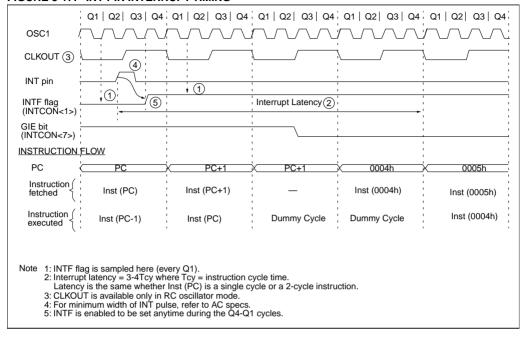


FIGURE 8-17: INT PIN INTERRUPT TIMING



8.9.1 INT INTERRUPT

External interrupt on RB0/INT pin is edge triggered: either rising if INTEDG bit (OPTION_REG<6>) is set, or falling, if INTEDG bit is clear. When a valid edge appears on the RB0/INT pin, the INTF bit (INTCON<1>) is set. This interrupt can be disabled by clearing control bit INTE (INTCON<4>). Flag bit INTF must be cleared in software via the interrupt service routine before re-enabling this interrupt. The INT interrupt can wake the processor from SLEEP (Section 8.12) only if the INTE bit was set prior to going into SLEEP. The status of the GIE bit decides whether the processor branches to the interrupt vector following wake-up.

8.9.2 TMR0 INTERRUPT

An overflow (FFh \rightarrow 00h) in TMR0 will set flag bit T0IF (INTCON<2>). The interrupt can be enabled/disabled by setting/clearing enable bit T0IE (INTCON<5>) (Section 6.0).

8.9.3 PORT RB INTERRUPT

An input change on PORTB<7:4> sets flag bit RBIF (INTCON<0>). The interrupt can be enabled/disabled by setting/clearing enable bit RBIE (INTCON<3>) (Section 5.2).

Note 1: For a change on the I/O pin to be recognized, the pulse width must be at least TCY wide.

8.10 Context Saving During Interrupts

During an interrupt, only the return PC value is saved on the stack. Typically, users wish to save key register values during an interrupt (e.g., W register and STATUS register). This is implemented in software.

Example 8-1 stores and restores the STATUS and W register's values. The User defined registers, W_TEMP and STATUS_TEMP are the temporary storage locations for the W and STATUS registers values.

Example 8-1 does the following:

- a) Stores the W register.
- b) Stores the STATUS register in STATUS TEMP.
- c) Executes the Interrupt Service Routine code.
- Restores the STATUS (and bank select bit) register.
- e) Restores the W register.

EXAMPLE 8-1: SAVING STATUS AND W REGISTERS IN RAM

```
PUSH
       MOVWF
                               ; Copy W to TEMP register,
              STATUS, W
                               ; Swap status to be saved into W
       SWAPF
       MOVWF
               STATUS TEMP
                               ; Save status to STATUS_TEMP register
ISR
       :
       .
                               ; Interrupt Service Routine
       :
                               ; should configure Bank as required
               STATUS TEMP, W ; Swap nibbles in STATUS TEMP register
POP
       SWAPF
                               ; and place result into W
       MOVWF
               STATUS
                               ; Move W into STATUS register
                               ; (sets bank to original state)
               W TEMP, F
                              ; Swap nibbles in W_TEMP and place result in W_TEMP
       SWAPF
       SWAPF
               W TEMP, W
                               ; Swap nibbles in W TEMP and place result into W
```

Watchdog Timer (WDT) 8.11

The Watchdog Timer is a free running on-chip RC oscillator which does not require any external components. This RC oscillator is separate from the RC oscillator of the OSC1/CLKIN pin. That means that the WDT will run even if the clock on the OSC1/CLKIN and OSC2/CLKOUT pins of the device has been stopped, for example, by execution of a SLEEP instruction. During normal operation a WDT time-out generates a device RESET. If the device is in SLEEP mode, a WDT Wake-up causes the device to wake-up and continue with normal operation. The WDT can be permanently disabled by programming configuration bit WDTE as a '0' (Section 8.1).

8.11.1 WDT PERIOD

The WDT has a nominal time-out period of 18 ms, (with no prescaler). The time-out periods vary with temperature, VDD and process variations from part to part (see DC specs). If longer time-out periods are desired, a prescaler with a division ratio of up to 1:128 can be assigned to the WDT under software control by writing to the OPTION_REG register. Thus, time-out periods up to 2.3 seconds can be realized.

The CLRWDT and SLEEP instructions clear the WDT and the postscaler (if assigned to the WDT) and prevent it from timing out and generating a device RESET condition.

The TO bit in the STATUS register will be cleared upon a WDT time-out.

8.11.2 WDT PROGRAMMING CONSIDERATIONS

It should also be taken into account that under worst case conditions (VDD = Min., Temperature = Max., max. WDT prescaler) it may take several seconds before a WDT time-out occurs.

FIGURE 8-18: WATCHDOG TIMER BLOCK DIAGRAM

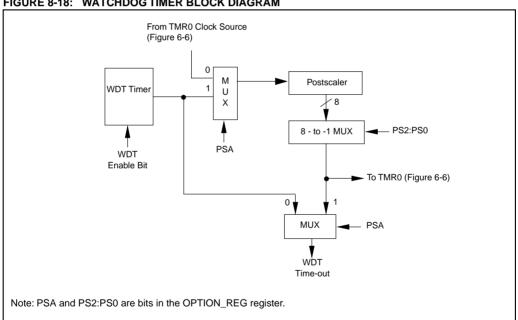


TABLE 8-7 SUMMARY OF REGISTERS ASSOCIATED WITH THE WATCHDOG TIMER

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on Power-on Reset	Value on all other resets
2007h	Config. bits	(2)	(2)	(2)	(2)	PWRTE ⁽¹⁾	WDTE	FOSC1	FOSC0	(2)	
81h	OPTION_ REG	RBPU	INTEDG	T0CS	T0SE	PSA	PS2	PS1	PS0	1111 1111	1111 1111

Legend: x = unknown. Shaded cells are not used by the WDT.

Note 1: See Figure 8-1 and Figure 8-2 for operation of the PWRTE bit.

2: See Figure 8-1, Figure 8-2 and Section 8.13 for operation of the Code and Data protection bits.

8.12 Power-down Mode (SLEEP)

A device may be powered down (SLEEP) and later powered up (Wake-up from SLEEP).

8.12.1 SLEEP

The Power-down mode is entered by executing the STREEP instruction.

If enabled, the Watchdog Timer is cleared (but keeps running), the PD bit (STATUS<3>) is cleared, the TO bit (STATUS<4>) is set, and the oscillator driver is turned off. The I/O ports maintain the status they had before the SLEEP instruction was executed (driving high, low, or hi-impedance).

For the lowest current consumption in SLEEP mode, place all I/O pins at either at VDD or Vss, with no external circuitry drawing current from the I/O pins, and disable external clocks. I/O pins that are hi-impedance inputs should be pulled high or low externally to avoid switching currents caused by floating inputs. The TOCKI input should also be at VDD or Vss. The contribution from on-chip pull-ups on PORTB should be considered.

The MCLR pin must be at a logic high level (VIHMC).

It should be noted that a RESET generated by a WDT time-out does not drive the \overline{MCLR} pin low.

8.12.2 WAKE-UP FROM SLEEP

The device can wake-up from SLEEP through one of the following events:

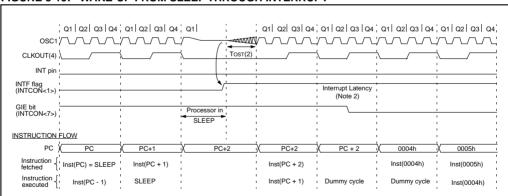
- 1. External reset input on MCLR pin.
- 2. WDT Wake-up (if WDT was enabled).
- Interrupt from RB0/INT pin, RB port change, or data EEPROM write complete.

Peripherals cannot generate interrupts during SLEEP, since no on-chip Q clocks are present.

The first event (MCLR reset) will cause a device reset. The two latter events are considered a continuation of program execution. The TO and PD bits can be used to determine the cause of a device reset. The PD bit, which is set on power-up, is cleared when SLEEP is invoked. The TO bit is cleared if a WDT time-out occurred (and caused wake-up).

While the SLEEP instruction is being executed, the next instruction (PC + 1) is pre-fetched. For the device to wake-up through an interrupt event, the corresponding interrupt enable bit must be set (enabled). Wake-up occurs regardless of the state of the GIE bit. If the GIE bit is clear (disabled), the device continues execution at the instruction after the SLEEP instruction. If the GIE bit is set (enabled), the device executes the instruction after the SLEEP instruction and then branches to the interrupt address (0004h). In cases where the execution of the instruction following SLEEP is not desirable, the user should have a NOP after the SLEEP instruction.





- Note 1: XT, HS or LP oscillator mode assumed.
 - 2: Tost = 1024Tosc (drawing not to scale) This delay will not be there for RC osc mode.
 - 3: GIE = '1' assumed. In this case after wake- up, the processor jumps to the interrupt routine. If GIE = '0', execution will continue in-line.
 - 4: CLKOUT is not available in these osc modes, but shown here for timing reference.

8.12.3 WAKE-UP USING INTERRUPTS

When global interrupts are disabled (GIE cleared) and any interrupt source has both its interrupt enable bit and interrupt flag bit set, one of the following will occur:

- If the interrupt occurs before the execution of a SLEEP instruction, the SLEEP instruction will complete as a NOP. Therefore, the WDT and WDT postscaler will not be cleared, the TO bit will not be set and PD bits will not be cleared.
- If the interrupt occurs during or after the execution of a SLEEP instruction, the device will immediately wake up from sleep. The SLEEP instruction will be completely executed before the wake-up. Therefore, the WDT and WDT postscaler will be cleared, the TO bit will be set and the PD bit will be cleared.

Even if the flag bits were checked before executing a SLEEP instruction, it may be possible for flag bits to become set before the SLEEP instruction completes. To determine whether a SLEEP instruction executed, test the PD bit. If the PD bit is set, the SLEEP instruction was executed as a NOP

To ensure that the WDT is cleared, a CLRWDT instruction should be executed before a SLEEP instruction.

8.13 Program Verification/Code Protection

If the code protection bit(s) have not been programmed, the on-chip program memory can be read out for verification purposes.

Note: Microchip does not recommend code protecting widowed devices.

8.14 ID Locations

Four memory locations (2000h - 2003h) are designated as ID locations to store checksum or other code identification numbers. These locations are not accessible during normal execution but are readable and writable only during program/verify. Only the 4 least significant bits of ID location are usable.

For ROM devices, these values are submitted along with the ROM code.

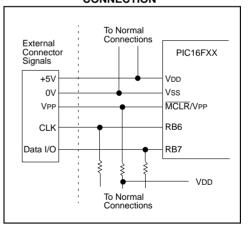
8.15 In-Circuit Serial Programming

PIC16F8X microcontrollers can be serially programmed while in the end application circuit. This is simply done with two lines for clock and data, and three other lines for power, ground, and the programming voltage. Customers can manufacture boards with unprogrammed devices, and then program the microcontroller just before shipping the product, allowing the most recent firmware or custom firmware to be programmed.

The device is placed into a program/verify mode by holding the RB6 and RB7 pins low, while raising the MCLR pin from VIL to VIHH (see programming specification). RB6 becomes the programming clock and RB7 becomes the programming data. Both RB6 and RB7 are Schmitt Trigger inputs in this mode.

After reset, to place the device into programming/verify mode, the program counter (PC) points to location 00h. A 6-bit command is then supplied to the device, 14-bits of program data is then supplied to or from the device, using load or read-type instructions. For complete details of serial programming, please refer to the PIC16CXX Programming Specifications (Literature #DS30189).

FIGURE 8-20: TYPICAL IN-SYSTEM SERIAL PROGRAMMING CONNECTION



For ROM devices, both the program memory and Data EEPROM memory may be read, but only the Data EEPROM memory may be programmed.

9.0 INSTRUCTION SET SUMMARY

Each PIC16CXX instruction is a 14-bit word divided into an OPCODE which specifies the instruction type and one or more operands which further specify the operation of the instruction. The PIC16CXX instruction set summary in Table 9-2 lists byte-oriented, bit-oriented, and literal and control operations. Table 9-1 shows the opcode field descriptions.

For **byte-oriented** instructions, 'f' represents a file register designator and 'd' represents a destination designator. The file register designator specifies which file register is to be used by the instruction.

The destination designator specifies where the result of the operation is to be placed. If 'd' is zero, the result is placed in the W register. If 'd' is one, the result is placed in the file register specified in the instruction.

For **bit-oriented** instructions, 'b' represents a bit field designator which selects the number of the bit affected by the operation, while 'f' represents the number of the file in which the bit is located.

For **literal and control** operations, 'k' represents an eight or eleven bit constant or literal value.

TABLE 9-1 OPCODE FIELD DESCRIPTIONS

Field	Description
f	Register file address (0x00 to 0x7F)
W	Working register (accumulator)
b	Bit address within an 8-bit file register
k	Literal field, constant data or label
x	Don't care location (= 0 or 1) The assembler will generate code with x = 0. It is the recommended form of use for compatibility with all Microchip software tools.
d	Destination select; d = 0: store result in W, d = 1: store result in file register f. Default is d = 1
label	Label name
TOS	Top of Stack
PC	Program Counter
PCLATH	Program Counter High Latch
GIE	Global Interrupt Enable bit
WDT	Watchdog Timer/Counter
TO	Time-out bit
PD	Power-down bit
dest	Destination either the W register or the specified register file location
[]	Options
()	Contents
\rightarrow	Assigned to
<>	Register bit field
€	In the set of
italics	User defined term (font is courier)

The instruction set is highly orthogonal and is grouped into three basic categories:

- · Byte-oriented operations
- · Bit-oriented operations
- · Literal and control operations

All instructions are executed within one single instruction cycle, unless a conditional test is true or the program counter is changed as a result of an instruction. In this case, the execution takes two instruction cycles with the second cycle executed as a NOP. One instruction cycle consists of four oscillator periods. Thus, for an oscillator frequency of 4 MHz, the normal instruction execution time is 1 μs . If a conditional test is true or the program counter is changed as a result of an instruction, the instruction execution time is 2 μs .

Table 9-2 lists the instructions recognized by the MPASM assembler.

Figure 9-1 shows the general formats that the instructions can have.

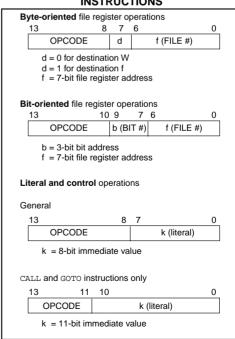
Note: To maintain upward compatibility with future PIC16CXX products, do not use the OPTION and TRIS instructions.

All examples use the following format to represent a hexadecimal number:

0xhh

where h signifies a hexadecimal digit.

FIGURE 9-1: GENERAL FORMAT FOR INSTRUCTIONS



PIC16F8X

TABLE 9-2 PIC16FXX INSTRUCTION SET

Mnemonic,		Description	Cycles		14-Bit	9	Status	Notes	
Operan	nds			MSb			LSb	Affected	
		BYTE-ORIENTED FILE REGIS	TER OPE	RATIO	NS				
ADDWF	f, d	Add W and f	1	00	0111	dfff	ffff	C,DC,Z	1,2
ANDWF	f, d	AND W with f	1	00	0101	dfff	ffff	Z	1,2
CLRF	f	Clear f	1	00	0001	lfff	ffff	Z	2
CLRW	-	Clear W	1	00	0001	0xxx	xxxx	Z	
COMF	f, d	Complement f	1	00	1001	dfff	ffff	Z	1,2
DECF	f, d	Decrement f	1	00	0011	dfff	ffff	Z	1,2
DECFSZ	f, d	Decrement f, Skip if 0	1(2)	00	1011	dfff	ffff		1,2,3
INCF	f, d	Increment f	1	00	1010	dfff	ffff	Z	1,2
INCFSZ	f, d	Increment f, Skip if 0	1(2)	00	1111	dfff	ffff		1,2,3
IORWF	f, d	Inclusive OR W with f	1	00	0100	dfff	ffff	Z	1,2
MOVF	f, d	Move f	1	00	1000	dfff	ffff	Z	1,2
MOVWF	f	Move W to f	1	00	0000	lfff	ffff		
NOP	-	No Operation	1	00	0000	0xx0	0000		
RLF	f, d	Rotate Left f through Carry	1	00	1101	dfff	ffff	С	1,2
RRF	f, d	Rotate Right f through Carry	1	00	1100	dfff	ffff	С	1,2
SUBWF	f, d	Subtract W from f	1	00	0010	dfff	ffff	C,DC,Z	1,2
SWAPF	f, d	Swap nibbles in f	1	00	1110	dfff	ffff		1,2
XORWF	f, d	Exclusive OR W with f	1	00	0110	dfff	ffff	Z	1,2
		BIT-ORIENTED FILE REGIST	ER OPER	RATIO	NS				
BCF	f, b	Bit Clear f	1	01	00bb	bfff	ffff		1,2
BSF	f, b	Bit Set f	1	01	01bb	bfff	ffff		1,2
BTFSC	f, b	Bit Test f, Skip if Clear	1 (2)	01	10bb	bfff	ffff		3
BTFSS	f, b	Bit Test f, Skip if Set	1 (2)	01	11bb	bfff	ffff		3
		LITERAL AND CONTROL	OPERAT	IONS				•	
ADDLW	k	Add literal and W	1	11	111x	kkkk	kkkk	C,DC,Z	
ANDLW	k	AND literal with W	1	11	1001	kkkk	kkkk	Z	
CALL	k	Call subroutine	2	10	0kkk	kkkk	kkkk		
CLRWDT	-	Clear Watchdog Timer	1	0.0	0000	0110	0100	TO,PD	
GOTO	k	Go to address	2	10	1kkk	kkkk	kkkk		
IORLW	k	Inclusive OR literal with W	1	11	1000	kkkk	kkkk	Z	
MOVLW	k	Move literal to W	1	11	00xx	kkkk	kkkk		
RETFIE	-	Return from interrupt	2	00	0000	0000	1001		
RETLW	k	Return with literal in W	2	11	01xx	kkkk	kkkk		
RETURN	-	Return from Subroutine	2	00	0000	0000	1000		
SLEEP	-	Go into standby mode	1	00	0000	0110	0011	TO,PD	
SUBLW	k	Subtract W from literal	1	11	110x	kkkk	kkkk	C,DC,Z	
XORLW	k	Exclusive OR literal with W	1	11	1010	kkkk	kkkk	Z	

Note 1: When an I/O register is modified as a function of itself (e.g., MOVF PORTB, 1), the value used will be that value present on the pins themselves. For example, if the data latch is '1' for a pin configured as input and is driven low by an external device, the data will be written back with a '0'.

^{2:} If this instruction is executed on the TMR0 register (and, where applicable, d = 1), the prescaler will be cleared if assigned to the Timer0 Module.

^{3:} If Program Counter (PC) is modified or a conditional test is true, the instruction requires two cycles. The second cycle is executed as a NOP.

9.1 <u>Instruction Descriptions</u>

ADDLW	Add Literal and W	ANDLW	AND Literal with W
Syntax:	[label] ADDLW k	Syntax:	[label] ANDLW k
Operands:	$0 \le k \le 255$	Operands:	$0 \leq k \leq 255$
Operation:	$(W) + k \to (W)$	Operation:	(W) .AND. (k) \rightarrow (W)
Status Affected:	C, DC, Z	Status Affected:	Z
Encoding:	11 111x kkkk kkkk	Encoding:	11 1001 kkkk kkkk
Description:	The contents of the W register are added to the eight bit literal 'k' and the result is placed in the W register.	Description:	The contents of W register are AND'ed with the eight bit literal 'k'. The result is placed in the W register.
Words:	1	Words:	1
Cycles:	1	Cycles:	1
Q Cycle Activity:	Q1 Q2 Q3 Q4	Q Cycle Activity:	Q1 Q2 Q3 Q4
	Decode Read Process Write to data W		Decode Read Process Write to data W
Example:	ADDLW 0x15	Example	ANDLW 0x5F
	Before Instruction W = 0x10 After Instruction W = 0x25		Before Instruction W = 0xA3 After Instruction W = 0x03

ADDWF	Add W and f	ANDWF	AND W with f
Syntax:	[label] ADDWF f,d	Syntax:	[label] ANDWF f,d
Operands:	$0 \le f \le 127$ $d \in [0,1]$	Operands:	$0 \le f \le 127$ $d \in [0,1]$
Operation:	(W) + (f) \rightarrow (destination)	Operation:	(W) .AND. (f) \rightarrow (destination)
Status Affected:	C, DC, Z	Status Affected:	Z
Encoding:	00 0111 dfff ffff	Encoding:	00 0101 dfff ffff
Description:	Add the contents of the W register with register 'f'. If 'd' is 0 the result is stored in the W register. If 'd' is 1 the result is stored back in register 'f'.	Description:	AND the W register with register 'f'. If 'd' is 0 the result is stored in the W register. If 'd' is 1 the result is stored back in register 'f'.
Words:	1	Words:	1
Cycles:	1	Cycles:	1
Q Cycle Activity:	Q1 Q2 Q3 Q4	Q Cycle Activity:	Q1 Q2 Q3 Q4
	Decode Read Process Write to destination		Decode Read register data Write to destination
Example	ADDWF FSR, 0	Example	ANDWF FSR, 1
	Before Instruction W = 0x17 FSR = 0xC2 After Instruction W = 0xD9 FSR = 0xC2		Before Instruction $W = 0x17$ $FSR = 0xC2$ After Instruction $W = 0x17$ $FSR = 0x02$

BCF	Bit Clear				BTFSC	Dit Toet	Skip if Cl	oor	
Syntax:	[label] B0				Syntax:		TFSC f,b	cai	
Operands:	0 ≤ f ≤ 12	,			Operands:	0 ≤ f ≤ 12			
Ореганаз.	0 ≤ 1 ≤ 12 0 ≤ b ≤ 7				Ореганаз.	0 ≤ 1 ≤ 12 0 ≤ b ≤ 7			
Operation:	$0 \rightarrow (f < b)$	>)			Operation:	skip if (f<	(b>) = 0		
Status Affected:	None	,			Status Affected:	None	•		
Encoding:	01	00bb	bfff	ffff	Encoding:	01	10bb	bfff	ffff
Description:	Bit 'b' in re	egister 'f' is	L s cleared.		Description:	If bit 'b' in	register 'f' is	i s '1' then th	ne next
Words:	1	J			•		is execute		the second
Cycles:	1						register 'f', is discarde		
Q Cycle Activity:	Q1	Q2	Q3	Q4		executed i	nstead, ma		
,	Decode	Read	Process	Write		instruction	١.		
		register 'f'	data	register 'f'	Words:	1			
					Cycles:	1(2)			
Example	BCF	FLAG_	REG, 7		Q Cycle Activity:	Q1	Q2	Q3	Q4
	Before In					Decode	Read register 'f'	Process data	No-Operat ion
	After Inst	_	EG = 0xC7	•	If Skip:	(2nd Cyc	:le)		
			EG = 0x47			Q1	Q2	Q3	Q4
							No-Operati		No-Operat
						No-Operat ion	on	tion	ion
					Example	HERE	BTFSC	FLAG,1	CODE
						FALSE TRUE	GOTO •	PROCESS_	_CODE
							•		
						Before In	struction		
								ddress H	ERE
BSF	Bit Set f					After Inst	ruction if FLAG<1>	· = 0	
Syntax:	[label] BS						PC =	address T	RUE
Operands:	$0 \le f \le 12$						if FLAG<1> PC = 8	·=1, address F∄	ALSE
oporariae.	$0 \le b \le 7$								
Operation:	$1 \rightarrow (f < b)$	>)							
Status Affected:	None								
Encoding:	01	01bb	bfff	ffff					
Description:	Bit 'b' in re	egister 'f' is	s set.						
Words:	1								
Cycles:	1								
Q Cycle Activity:	Q1	Q2	Q3	Q4					
	Decode	Read	Process	Write					
		register 'f'	data	register 'f'					
		•	1						
Example	BSF	FLAG_F	REG, 7						
	Before In								
	After Inst	_	EG = 0x0/	٦.					

FLAG_REG = 0x8A

BTFSS	Bit Test f, Skip if Set	CALL	Call Subroutine
Syntax:	[label] BTFSS f,b	Syntax:	[label] CALL k
Operands:	$0 \le f \le 127$	Operands:	$0 \le k \le 2047$
	0 ≤ b < 7	Operation:	(PC)+ $1 \rightarrow TOS$,
Operation:	skip if $(f < b >) = 1$		$k \rightarrow PC < 10:0>$,
Status Affected:	None		(PCLATH<4:3>) → PC<12:11>
Encoding:	01 11bb bfff ffff	Status Affected:	None
Description:	If bit 'b' in register 'f' is '0' then the next	Encoding:	10 0kkk kkkk kkkk
	instruction is executed. If bit 'b' is '1', then the next instruction is discarded and a NOP is executed instead, making this a 2Tcy instruction.	Description:	Call Subroutine. First, return address (PC+1) is pushed onto the stack. The eleven bit immediate address is loaded into PC bits <10:0>. The upper bits of
Words:	1		the PC are loaded from PCLATH. CALL is a two cycle instruction.
Cycles:	1(2)	Words:	1
Q Cycle Activity:	Q1 Q2 Q3 Q4	Cycles:	2
	Decode Read Process No-Operation on Section 1. Decode Read register 'f' data ion	Q Cycle Activity:	Q1 Q2 Q3 Q4
If Skip:	(2nd Cycle)	1st Cycle	Decode Read Process Write to literal 'k'. data PC
·	Q1 Q2 Q3 Q4	1	Push PC to Stack
	No-Operat on tion No-Operat ion	2nd Cycle	No-Opera tion No-Opera tion No-Opera tion No-Opera
Example	HERE BTFSC FLAG,1 FALSE GOTO PROCESS CODE	Example	HERE CALL THERE
	TRUE •		Before Instruction PC = Address HERE
	•		After Instruction
	Before Instruction PC = address HERE After Instruction if FLAG<1> = 0,		PC = Address THERE TOS = Address HERE+1

PC =

if FLAG<1> = 1, PC =

address FALSE

address TRUE

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CLRF	Clear f			
Syntax:	[label] C	LRF f		
Operands:	$0 \le f \le 12$	27		
Operation:	$\begin{array}{c} 00h \rightarrow (f) \\ 1 \rightarrow Z \end{array}$)		
Status Affected:	Z			
Encoding:	00	0001	1fff	ffff
Description:	The conte and the Z		ster 'f' are	cleared
Words:	1			
Cycles:	1			
Q Cycle Activity:	Q1	Q2	Q3	Q4
	Decode	Read register 'f'	Process data	Write register 'f'
Example	CLRF	FLAC	_REG	
	Before In	struction FLAG_RE		0x5A

After Instruction

FLAG_REG = Z =

0x00

CLRW	Clear W			
Syntax:	[label]	CLRW		
Operands:	None			
Operation:	$\begin{array}{c} 00h \rightarrow (V \\ 1 \rightarrow Z \end{array}$	V)		
Status Affected:	Z			
Encoding:	00	0001	0xxx	xxxx
Description:	W register set.	is cleared	I. Zero bit (Z) is
Words:	1			
Cycles:	1			
Q Cycle Activity:	Q1	Q2	Q3	Q4
	Decode	No-Opera tion	Process data	Write to W
Example	CLRW			
	Before In	struction		
		• •	0x5A	
	After Inst	ruction W =	0x00	
		Z =	1	

CLRWDT	Clear Wa	atchdog 1	imer		
Syntax:	[label]	CLRWD1	_		
Operands:	None				
Operation:					
Status Affected:	\overline{TO} , \overline{PD}				
Encoding:	00	0000	0110	0100	
Description:		nstruction r It also res T. Status b			
Words:	1				
Cycles:	1				
Q Cycle Activity:	Q1	Q2	Q3	Q4	
	Decode	No-Opera tion	Process data	Clear WDT Counter	
Example	CLRWDT				
	Before In	struction WDT cour	nter =	?	
	After Inst				
		WDT cour WDT pres		0x00 0	
		TO	=	1	
		PD	=	1	

COMF	Complement f	DECFSZ	Decrement f, Skip if 0
Syntax:	[label] COMF f,d	Syntax:	[label] DECFSZ f,d
Operands:	$0 \le f \le 127$ $d \in [0,1]$	Operands:	$0 \le f \le 127$ $d \in [0,1]$
Operation:	$(\bar{f}) o (destination)$	Operation:	(f) - 1 \rightarrow (destination);
Status Affected:	Z		skip if result = 0
Encoding:	00 1001 dfff ffff	Status Affected:	None
Description:	The contents of register 'f' are complemented. If 'd' is 0 the result is stored in	Encoding:	00 1011 dfff ffff
	W. If 'd' is 1 the result is stored back in register 'f'.	Description:	The contents of register 'f' are decremented. If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is placed
Words:	1		back in register 'f'. If the result is 1, the next instruction, is
Cycles: Q Cycle Activity:	1 Q1 Q2 Q3 Q4		executed. If the result is 0, then a NOP is executed instead making it a 2Tcy instruction.
	Decode Read Process Write to	Words:	1
	register data destination	Cycles:	1(2)
		Q Cycle Activity:	Q1 Q2 Q3 Q4
Example	COMF REG1, 0 Before Instruction		Decode Read Process Write to data destination
	REG1 = 0x13	If Skip:	(2nd Cycle)
	After Instruction REG1 = 0x13		Q1 Q2 Q3 Q4
	W = 0xEC		No-Operat tion ion No-Operati on
DECF	Decrement f		(9)
Syntax:	[label] DECF f,d	Example	HERE DECFSZ CNT, 1
Operands:	$0 \le f \le 127$ $d \in [0,1]$		GOTO LOOP CONTINUE • •
Operation:	(f) - 1 \rightarrow (destination)		•
Status Affected:	Z		Before Instruction PC = address HERE
Encoding:	00 0011 dfff ffff		After Instruction
Description:	Decrement register 'f'. If 'd' is 0 the result is stored in the W register. If 'd' is 1 the result is stored back in register 'f'.		CNT = CNT-1 if CNT = 0, PC = address CONTINUE
Words:	1		if CNT \neq 0,
Cycles:	1		PC = address HERE+1
Q Cycle Activity:	Q1 Q2 Q3 Q4		
	Decode Read Process Write to destination		
Example	DECF CNT, 1		
	Before Instruction CNT = 0x01 Z = 0		
	After Instruction		

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Uncondi	tional Br	anch		INCF	Increme	nt f		
[label]	GOTO	k		Syntax:	[label]	INCF 1	,d	
$0 \le k \le 20$	047			Operands:		27		
		PC<12:11	1>	Operation:		(destina	tion)	
None				Status Affected:	Z			
10	1kkk	kkkk	kkkk	Encoding:	0.0	1010	dfff	ffff
eleven bit into PC bit PC are loa	immediate is <10:0>. ided from I	value is lo The upper PCLATH<4	paded bits of 4:3>.	Description:	mented. If the W reg	d' is 0 th	e result is is 1 the re	placed in
1	,			Words:	1			
2				Cycles:	1			
Q1	Q2	Q3	Q4	Q Cycle Activity:	Q1	Q2	Q3	Q4
Decode	Read literal 'k'	Process data	Write to PC		Decode	Read register 'f'	Process data	Write to destination
No-Operat ion	No-Operat ion	No-Opera tion	No-Operat ion	Example	INCF	CNT,	1	
					Before In	struction	1	
GOTO TI	HERE							F
		A -1-1			After Inst	_	= 0	
	PC = 1	Aaaress '	THERE			CNT)
	$ [\ label] \\ 0 \leq k \leq 20 \\ k \rightarrow PC < PCLATH- \\ None \\ \hline $		$\begin{array}{c ccccccccccccccccccccccccccccccccccc$					

INCFSZ	Increment f, Skip if 0	IORLW	Inclusive OR Literal with W
Syntax:	[label] INCFSZ f,d	Syntax:	[label] IORLW k
Operands:	$0 \le f \le 127$	Operands:	$0 \le k \le 255$
	d ∈ [0,1]	Operation:	(W) .OR. $k \rightarrow$ (W)
Operation:	(f) + 1 \rightarrow (destination), skip if result = 0	Status Affected:	Z
Status Affected:	None	Encoding:	11 1000 kkkk kkkk
Encoding:	00 1111 dfff ffff	Description:	The contents of the W register is OR'ed with the eight bit literal 'k'. The
Description:	The contents of register 'f' are incre-		result is placed in the W register.
·	mented. If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is	Words:	1
	placed back in register 'f'. If the result is 1, the next instruction is	Cycles:	1
	executed. If the result is 0, a NOP is e cuted instead making it a 2Tcy instruction	e- Q Cycle Activity:	Q1 Q2 Q3 Q4
Words:	tion. 1		Decode Read Process Write to literal 'k' data W
Cycles:	1(2)		
Q Cycle Activity:	Q1 Q2 Q3 Q4	Example	IORLW 0x35
,	Decode Read Process Write register 'f' data destina		Before Instruction W = 0x9A
If Skip:	(2nd Cycle)		After Instruction W = 0xBF
п экір.	Q1 Q2 Q3 Q4		Z = 1
	No-Operat tion No-Opera tion No-Opera tion		
Example	HERE INCFSZ CNT, 1 GOTO LOOP CONTINUE •		
	$\begin{array}{lll} \text{Before Instruction} & & \text{PC} & = & \text{address HERE} \\ \text{After Instruction} & & \text{CNT} & = & \text{CNT} + 1 \\ & & & & \text{if CNT=} & 0, \\ & & & \text{PC} & = & \text{address Continue} \\ & & & & \text{if CNT} \neq & 0, \\ & & & \text{PC} & = & \text{address HERE} & + 1 \\ \end{array}$		

IORWF Inclusive OR W with f
Syntax: [label] IORWF f,d

Operands: $0 \leq f \leq 127 \\ d \in [0,1]$

Operation: (W) .OR. (f) \rightarrow (destination)

Status Affected: Z

Encoding: 00 0100 dfff ffff

Description: Inclusive OR the W register with register 'f'. If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is placed

back in register 'f'.

Words: 1 Cycles: 1

Q Cycle Activity: Q1 Q2 Q3 Q4

Decode Read register data Write to destination

Example IORWF RESULT, 0

Before Instruction

RESULT = 0x13 W = 0x91

After Instruction

RESULT = 0x13 W = 0x93 Z = 1 MOVLW Move Literal to W

Syntax: [label] MOVLW k Operands: $0 \le k \le 255$

Operation: $k \rightarrow (W)$ Status Affected: None

Encoding: 11 00xx kkkk kkkk

Description: The eight bit literal 'k' is loaded into W register. The don't cares will assemble

as 0's.

Words: 1 Cycles: 1

Q Cycle Activity: Q1 Q2 Q3 Q4

Decode Read Process Write to data W

Example MOVLW 0x5A

After Instruction
W = 0x5A

MOVF Move f
Syntax: [label] MOVF f,d

Operands: $0 \le f \le 127$ $d \in [0,1]$

Operation: $(f) \rightarrow (destination)$

Status Affected: Z

Encoding: 00 1000 dfff ffff

Description: The contents of register f is moved to a

destination dependant upon the status of d. If d = 0, destination is W register. If d = 1, the destination is file register f itself. d = 1 is useful to test a file register since status flag Z is affected.

Words: 1
Cycles: 1

Q Cycle Activity: Q1 Q2 Q3 Q4

Decode Read Process Write to destination destination

Example MOVF FSR, 0

After Instruction

W = value in FSR registerZ = 1

Z = 1

MOVWF Move W to f

Syntax: [label] MOVWF

Operands: $0 \le f \le 127$ Operation: $(W) \to (f)$

Status Affected: None

Encoding: 00 0000 1fff ffff

Description: Move data from W register to register

'f'. Words: 1

Cycles: 1

Q Cycle Activity:

Cycle Activity: Q1 Q2 Q3 Q4

Decode Read Process Write register 'f

Example MOVWF OPTION_REG

Before Instruction

OPTION = 0xFF W = 0x4F

After Instruction

 $\begin{array}{rcl} \mathsf{OPTION} &=& \mathsf{0x4F} \\ \mathsf{W} &=& \mathsf{0x4F} \end{array}$

NOP	No Oper	ation		
Syntax:	[label]	NOP		
Operands:	None			
Operation:	No opera	ation		
Status Affected:	None			
Encoding:	0.0	0000	0xx0	0000
Description:	No operat	ion.		
Words:	1			
Cycles:	1			
Q Cycle Activity:	Q1	Q2	Q3	Q4
	Decode	No-Opera tion	No-Opera tion	No-Operat ion
Example	NOP			

OPTION	Load Op	tion Reg	gister	
Syntax:	[label]	OPTIO	1	
Operands:	None			
Operation:	$(W) \rightarrow O$	PTION		
Status Affected:	None			
Encoding:	0.0	0000	0110	0010
Description:	The contents of the W register are loaded in the OPTION register. This instruction is supported for code compatibility with PIC16C5X products. Since OPTION is a readable/writable register, the user can directly address it.			
Words:	1			
Cycles:	1			
Example				
			ard comp	

RETFIE	Return from Interrupt							
Syntax:	[label]	RETFIE						
Operands:	None	None						
Operation:	$\begin{array}{l} TOS \rightarrow PC, \\ 1 \rightarrow GIE \end{array}$							
Status Affected:	None							
Encoding:	00	0000	0000	1001				
Description:	Return from Interrupt. Stack is POPed and Top of Stack (TOS) is loaded in the PC. Interrupts are enabled by setting Global Interrupt Enable bit, GIE (INTCON<7>). This is a two cycle instruction.							
Words:	1							
Cycles:	2							
Q Cycle Activity:	Q1	Q2	Q3	Q4				
1st Cycle	Decode	No-Opera tion	Set the GIE bit	Pop from the Stack				
2nd Cycle	No-Operat ion	No-Opera tion	No-Opera tion	No-Operat ion				

Example RETFIE

After Interrupt

PC = TOS

GIE = 1

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RETLW	Return with Literal in W						
Syntax:	[label]	RETLW	k				
Operands:	0 ≤ k ≤ 25	55					
Operation:	$\begin{array}{l} k \rightarrow (W); \\ TOS \rightarrow PC \end{array}$						
Status Affected:	None						
Encoding:	11	01xx	kkkk	kkkk			
Description:	The W register is loaded with the eight bit literal 'k'. The program counter is loaded from the top of the stack (the return address). This is a two cycle instruction.						
Words:	1						
Cycles:	2						
Q Cycle Activity:	Q1	Q2	Q3	Q4			
1st Cycle	Decode	Read literal 'k'	No-Opera tion	Write to W, Pop from the Stack			
2nd Cycle	No-Operat ion	No-Opera tion	No-Opera tion	No-Operat ion			
Example	CALL TABLE ;W contains table ;offset value ;W now has table value						
TABLE	ADDWF PC ;W = offset RETLW k1 ;Begin table RETLW k2 ;						
	RETLW kn	; End of	table				
	Before In		0x07				
	After Inst		OAU1				
	,	W =	value of k8	3			

RETURN	Return fi	Return from Subroutine						
Syntax:	[label]	RETURI	V					
Operands:	None							
Operation:	$TOS \to F$	$TOS \to PC$						
Status Affected:	None							
Encoding:	00	0000	0000	1000				
Description:	Return from subroutine. The stack is POPed and the top of the stack (TOS) is loaded into the program counter. This is a two cycle instruction.							
Words:	1							
Cycles:	2							
Q Cycle Activity:	Q1	Q2	Q3	Q4				
1st Cycle	Decode	No-Opera tion	No-Opera tion	Pop from the Stack				
2nd Cycle	No-Operat ion	No-Opera tion	No-Opera tion	No-Opera tion				
Example	RETURN After Inte	rrupt						
		PC = TOS						

RLF	Rotate L	eft f thre	ough Ca	rry	RRF	Rotate F	Rotate Right f through Carry				
Syntax:	[label]		RLF f	,d	Syntax:	[label]	RRF f	,d			
Operands:	$0 \le f \le 12$ $d \in [0,1]$				Operands:	$0 \le f \le 12$ $d \in [0,1]$					
Operation:	See desc	cription b	elow		Operation:	See des	See description below				
Status Affected:	С				Status Affected:	С					
Encoding:	0.0	1101	dfff	ffff	Encoding:	00	1100	dfff	ffff		
Description:	The contents of register 'f' are rotated one bit to the left through the Carry Flag. If 'd' is 0 the result is placed in the W register. If 'd' is 1 the result is stored back in register 'f'. Register f			Description:	The contents of register 'f' are rotated one bit to the right through the Carry Flag. If 'd' is 0 the result is placed in t W register. If 'd' is 1 the result is place back in register 'f'. Register f			e Carry ced in the is placed			
Words:	1				Words:	1					
Cycles:	1				Cycles:	1					
Q Cycle Activity:	Q1	Q2	Q3	Q4	Q Cycle Activity:	Q1	Q2	Q3	Q4		
, ,	Decode	Read register 'f'	Process data	Write to destination		Decode	Read register 'f'	Process data	Write to destination		
Example	RLF	REG	G1,0		Example	RRF		REG1,0			
	Before In	struction	1			Before Instruction					
		REG1 C	= 111 = 0	.0 0110			REG1		.0 0110		
	After Inst	-	= 0			After Ins	C truction	= 0			
		REG1		.0 0110			REG1	= 111	.0 0110		
		W C	= 110 = 1	0 1100			W C	= 011 = 0	.1 0011		
		-	_				C	- 0			

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SLEEP

Syntax: [label] SLEEP

Operands: None

Operation: $00h \rightarrow WDT$,

 $0 \rightarrow WDT$ prescaler,

 $\begin{array}{c} 1 \rightarrow \overline{TO}, \\ 0 \rightarrow \overline{PD} \end{array}$

Status Affected: TO, PD

Encoding: 00 0000 0110 0011

Description: The power-down status bit, PD is cleared. Time-out status bit, TO is

set. Watchdog Timer and its prescaler

are cleared.

The processor is put into SLEEP mode with the oscillator stopped. See

Section 14.8 for more details.

Words: 1 Cycles: 1

Q Cycle Activity: Q1 Q2 Q3 Q4

Decode No-Opera tion No-Opera Sleep

Example: SLEEP

SUBLW	Subtract W from Literal							
Syntax:	[label]	SUBLW	k					
Operands:	$0 \le k \le 25$	55						
Operation:	k - (W) \rightarrow	· (W)						
Status Affected:	C, DC, Z							
Encoding:	11	110x	kkkk	kkkk				
Description:	ment meth	ister is sub od) from th is placed ir	e eight bit	literal 'k'.				
Words:	1							
Cycles:	1							
Q Cycle Activity:	Q1	Q2	Q3	Q4				
	Decode	Read literal 'k'	Process data	Write to W				
Example 1:	SUBLW Before Ins	struction	0x02					
	Dololo III	W =	1					
		C = Z =	?					
	After Insti	ruction						
		W = C = Z =	1 1; result is 0	positive				
Example 2:	Before Ins	struction						
		W = C = Z =	2 ? ?					
	After Insti	ruction						
		W = C = Z =	0 1; result is	s zero				
Example 3:	Before In:	struction						
		W = C = Z =	3 ? ?					

After Instruction
W =

С

tive Z 0xFF

0

0; result is nega-

SUBWF	Subtract	W from f		
Syntax:	[label]	SUBWF	f,d	
Operands:	$0 \le f \le 12^{n}$ $d \in [0,1]$	7		
Operation:	(f) - (W) -	→ (destina	ition)	
Status Affected:	C, DC, Z			
Encoding:	00	0010	dfff	ffff
Description:	ister from r stored in th	egister 'f'. I ne W regist		result is the
Words:	1			
Cycles:	1			
Q Cycle Activity:	Q1	Q2	Q3	Q4
	Decode	Read register 'f'	Process data	Write to destination
Example 1:	SUBWF		REG1,1	
	Before Ins	struction		
	REG1 W C Z	= = =	3 2 ?	
	After Instr	uction		
	REG1 W C Z	= = =	1 2 1; result is	positive
Example 2:	Before Ins	struction	ŭ	
	REG1 W C Z	= = = =	2 2 ? ?	
	After Instr	uction		
	REG1 W C Z	= = = =	0 2 1; result is 1	zero
Example 3:	Before Ins	struction		
	REG1 W C Z	= = = =	1 2 ?	
	After Instr	uction		
	REG1 W C Z	= = =	0xFF 2 0; result is 0	negative

SWAPF	Swap Ni	bbles in	f					
Syntax:	[label]	[label] SWAPF f,d						
Operands:	$0 \le f \le 12$ $d \in [0,1]$							
Operation:		ightarrow (destin						
Status Affected:	None							
Encoding:	00	1110	df	ff	ffff			
Description:	The upper and lower nibbles of register 'f' are exchanged. If 'd' is 0 the result is placed in W register. If 'd' is 1 the result is placed in register 'f'.							
Words:	1							
Cycles:	1							
Q Cycle Activity:	Q1	Q2	Q	13	Q4			
	Decode	Read register 'f'		cess	Write to destination			
Example	SWAPF	REG,	0					
	Before In	struction						
		REG1	=	0x/	4 5			
	After Inst	truction						
		REG1	=	0x/				
		W	=	0x8	5A			

TRIS	Load TRIS Register					
Syntax:	[label] T	RIS	f			
Operands:	$5 \le f \le 7$					
Operation:	(W) \rightarrow TRIS register f;					
Status Affected:	None					
Encoding:	00	0000	0110	Offf		
	compatibility with the PIC16C5X prod- ucts. Since TRIS registers are read- able and writable, the user can directly address them.					
Words:	1					
Cycles:	1					
Example						
	To maintain upward compatibility with future PIC16CXX products, do not use this instruction.					

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XORLW	Exclusive OR Literal with W	XORWF	Exclusive OR W with f
Syntax:	[<i>label</i>] XORLW k	Syntax:	[label] XORWF f,d
Operands:	0 ≤ k ≤ 255	Operands:	$0 \le f \le 127$ $d \in [0,1]$
Operation:	(W) .XOR. $k \rightarrow (W)$	Operation:	(W) .XOR. (f) → (destination)
Status Affected:	Z	Status Affected:	Z
Encoding:	11 1010 kkkk kkkk	Encoding:	00 0110 dfff ffff
Description:	The contents of the W register are XOR'ed with the eight bit literal 'k'. The result is placed in the W register.	Description:	Exclusive OR the contents of the W register with register 'f'. If 'd' is 0 the result is stored in the W register. If 'd' is
Words:	1	147	1 the result is stored back in register 'f'.
Cycles:	1	Words:	1
Q Cycle Activity:	Q1 Q2 Q3 Q4	Cycles:	1
,	Decode Read Process Write to	Q Cycle Activity:	Q1 Q2 Q3 Q4
	literal 'k' data W		Decode Read Process Write to register data destination
Example:	XORLW 0xAF		
	Before Instruction	Example	XORWF REG 1
	W = 0xB5		Before Instruction
	After Instruction W = 0x1A		$ \begin{array}{rcl} REG & = & 0xAF \\ W & = & 0xB5 \end{array} $
			After Instruction
			REG = 0x1A W = 0xB5

10.0 DEVELOPMENT SUPPORT

10.1 Development Tools

The PICmicro™ microcontrollers are supported with a full range of hardware and software development tools:

- PICMASTER®/PICMASTER CE Real-Time In-Circuit Emulator
- ICEPIC™ Low-Cost PIC16C5X and PIC16CXXX In-Circuit Emulator
- PRO MATE® II Universal Programmer
- PICSTART® Plus Entry-Level Prototype Programmer
- PICDEM-1 Low-Cost Demonstration Board
- PICDEM-2 Low-Cost Demonstration Board
- PICDEM-3 Low-Cost Demonstration Board
- MPASM Assembler
- MPLAB™ SIM Software Simulator
- MPLAB-C17 (C Compiler)
- Fuzzy Logic Development System (fuzzyTECH®-MP)

10.2 PICMASTER: High Performance Universal In-Circuit Emulator with MPLAB IDE

The PICMASTER Universal In-Circuit Emulator is intended to provide the product development engineer with a complete microcontroller design tool set for all microcontrollers in the PIC14C000, PIC12CXXX, PIC16C5X, PIC16CXXX and PIC17CXX families. PICMASTER is supplied with the MPLAB™ Integrated Development Environment (IDE), which allows editing, "make" and download, and source debugging from a single environment.

Interchangeable target probes allow the system to be easily reconfigured for emulation of different processors. The universal architecture of the PICMASTER allows expansion to support all new Microchip microcontrollers.

The PICMASTER Emulator System has been designed as a real-time emulation system with advanced features that are generally found on more expensive development tools. The PC compatible 386 (and higher) machine platform and Microsoft Windows® 3.x environment were chosen to best make these features available to you, the end user.

A CE compliant version of PICMASTER is available for European Union (EU) countries.

10.3 <u>ICEPIC: Low-Cost PICmicro™</u> In-Circuit Emulator

ICEPIC is a low-cost in-circuit emulator solution for the Microchip PIC12CXXX, PIC16C5X and PIC16CXXX families of 8-bit OTP microcontrollers.

ICEPIC is designed to operate on PC-compatible machines ranging from 286-AT $^{\odot}$ through Pentium $^{\top M}$ based machines under Windows 3.x environment. ICEPIC features real time, non-intrusive emulation.

10.4 PRO MATE II: Universal Programmer

The PRO MATE II Universal Programmer is a full-featured programmer capable of operating in stand-alone mode as well as PC-hosted mode. PRO MATE II is CE compliant.

The PRO MATE II has programmable VDD and VPP supplies which allows it to verify programmed memory at VDD min and VDD max for maximum reliability. It has an LCD display for displaying error messages, keys to enter commands and a modular detachable socket assembly to support various package types. In standalone mode the PRO MATE II can read, verify or program PIC12CXXX, PIC14C000, PIC16C5X, PIC16CXXX and PIC17CXX devices. It can also set configuration and code-protect bits in this mode.

10.5 <u>PICSTART Plus Entry Level</u> Development System

The PICSTART programmer is an easy-to-use, low-cost prototype programmer. It connects to the PC via one of the COM (RS-232) ports. MPLAB Integrated Development Environment software makes using the programmer simple and efficient. PICSTART Plus is not recommended for production programming.

PICSTART Plus supports all PIC12CXXX, PIC14C000, PIC16C5X, PIC16CXXX and PIC17CXX devices with up to 40 pins. Larger pin count devices such as the PIC16C923, PIC16C924 and PIC17C756 may be supported with an adapter socket. PICSTART Plus is CE compliant.

10.6 PICDEM-1 Low-Cost PICmicro Demonstration Board

The PICDEM-1 is a simple board which demonstrates the capabilities of several of Microchip's microcontrollers. The microcontrollers supported are: PIC16C5X (PIC16C54 to PIC16C58A), PIC16C61, PIC16C62X, PIC16C71, PIC16C8X, PIC17C42, PIC17C43 and PIC17C44. All necessary hardware and software is included to run basic demo programs. The users can program the sample microcontrollers provided with the PICDEM-1 board, on a PRO MATE II or PICSTART-Plus programmer, and easily test firmware. The user can also connect the PICDEM-1 board to the PICMASTER emulator and download the firmware to the emulator for testing. Additional prototype area is available for the user to build some additional hardware and connect it to the microcontroller socket(s). Some of the features include an RS-232 interface, a potentiometer for simulated analog input, push-button switches and eight LEDs connected to PORTB.

10.7 PICDEM-2 Low-Cost PIC16CXX Demonstration Board

The PICDEM-2 is a simple demonstration board that supports the PIC16C62, PIC16C64, PIC16C65, PIC16C73 and PIC16C74 microcontrollers. All the necessary hardware and software is included to run the basic demonstration programs. The user can program the sample microcontrollers provided with the PICDEM-2 board, on a PRO MATE II programmer or PICSTART-Plus, and easily test firmware. The PICMASTER emulator may also be used with the PICDEM-2 board to test firmware. Additional prototype area has been provided to the user for adding additional hardware and connecting it to the microcontroller socket(s). Some of the features include a RS-232 interface, push-button switches, a potentiometer for simulated analog input, a Serial EEPROM to demonstrate usage of the I²C bus and separate headers for connection to an LCD module and a keypad.

10.8 PICDEM-3 Low-Cost PIC16CXXX Demonstration Board

The PICDEM-3 is a simple demonstration board that supports the PIC16C923 and PIC16C924 in the PLCC package. It will also support future 44-pin PLCC microcontrollers with a LCD Module. All the necessary hardware and software is included to run the basic demonstration programs. The user can program the sample microcontrollers provided with the PICDEM-3 board, on a PRO MATE II programmer or PICSTART Plus with an adapter socket, and easily test firmware. The PICMASTER emulator may also be used with the PICDEM-3 board to test firmware. Additional prototype area has been provided to the user for adding hardware and connecting it to the microcontroller socket(s). Some of the features include

an RS-232 interface, push-button switches, a potentiometer for simulated analog input, a thermistor and separate headers for connection to an external LCD module and a keypad. Also provided on the PICDEM-3 board is an LCD panel, with 4 commons and 12 segments, that is capable of displaying time, temperature and day of the week. The PICDEM-3 provides an additional RS-232 interface and Windows 3.1 software for showing the demultiplexed LCD signals on a PC. A simple serial interface allows the user to construct a hardware demultiplexer for the LCD signals.

10.9 MPLAB™ Integrated Development Environment Software

The MPLAB IDE Software brings an ease of software development previously unseen in the 8-bit microcontroller market. MPLAB is a windows based application which contains:

- A full featured editor
- · Three operating modes
 - editor
 - emulator
- simulator
- · A project manager
- Customizable tool bar and key mapping
- · A status bar with project information
- · Extensive on-line help

MPLAB allows you to:

- Edit your source files (either assembly or 'C')
- One touch assemble (or compile) and download to PICmicro tools (automatically updates all project information)
- · Debug using:
 - source files
- absolute listing file
- Transfer data dynamically via DDE (soon to be replaced by OLE)
- · Run up to four emulators on the same PC

The ability to use MPLAB with Microchip's simulator allows a consistent platform and the ability to easily switch from the low cost simulator to the full featured emulator with minimal retraining due to development tools.

10.10 Assembler (MPASM)

The MPASM Universal Macro Assembler is a PC-hosted symbolic assembler. It supports all micro-controller series including the PIC12C5XX, PIC14000, PIC16C5X, PIC16CXXX, and PIC17CXX families.

MPASM offers full featured Macro capabilities, conditional assembly, and several source and listing formats. It generates various object code formats to support Microchip's development tools as well as third party programmers.

MPASM allows full symbolic debugging from PICMASTER, Microchip's Universal Emulator System.

MPASM has the following features to assist in developing software for specific use applications.

- Provides translation of Assembler source code to object code for all Microchip microcontrollers.
- · Macro assembly capability.
- Produces all the files (Object, Listing, Symbol, and special) required for symbolic debug with Microchip's emulator systems.
- Supports Hex (default), Decimal and Octal source and listing formats.

MPASM provides a rich directive language to support programming of the PICmicro. Directives are helpful in making the development of your assemble source code shorter and more maintainable.

10.11 Software Simulator (MPLAB-SIM)

The MPLAB-SIM Software Simulator allows code development in a PC host environment. It allows the user to simulate the PICmicro series microcontrollers on an instruction level. On any given instruction, the user may examine or modify any of the data areas or provide external stimulus to any of the pins. The input/output radix can be set by the user and the execution can be performed in; single step, execute until break, or in a trace mode.

MPLAB-SIM fully supports symbolic debugging using MPLAB-C and MPASM. The Software Simulator offers the low cost flexibility to develop and debug code outside of the laboratory environment making it an excellent multi-project software development tool.

10.12 C Compiler (MPLAB-C17)

The MPLAB-C Code Development System is a complete 'C' compiler and integrated development environment for Microchip's PIC17CXXX family of microcontrollers. The compiler provides powerful integration capabilities and ease of use not found with other compilers.

For easier source level debugging, the compiler provides symbol information that is compatible with the MPLAB IDE memory display.

10.13 <u>Fuzzy Logic Development System</u> (fuzzyTECH-MP)

fuzzyTECH-MP fuzzy logic development tool is available in two versions - a low cost introductory version, MP Explorer, for designers to gain a comprehensive working knowledge of fuzzy logic system design; and a full-featured version, fuzzyTECH-MP, Edition for implementing more complex systems.

Both versions include Microchip's *fuzzy*LAB™ demonstration board for hands-on experience with fuzzy logic systems implementation.

10.14 <u>MP-DriveWay™ – Application Code</u> Generator

MP-DriveWay is an easy-to-use Windows-based Application Code Generator. With MP-DriveWay you can visually configure all the peripherals in a PICmicro device and, with a click of the mouse, generate all the initialization and many functional code modules in C language. The output is fully compatible with Microchip's MPLAB-C C compiler. The code produced is highly modular and allows easy integration of your own code. MP-DriveWay is intelligent enough to maintain your code through subsequent code generation.

10.15 <u>SEEVAL® Evaluation and</u> <u>Programming System</u>

The SEEVAL SEEPROM Designer's Kit supports all Microchip 2-wire and 3-wire Serial EEPROMs. The kit includes everything necessary to read, write, erase or program special features of any Microchip SEEPROM product including Smart Serials. M and secure serials. The Total Endurance Disk is included to aid in trade-off analysis and reliability calculations. The total kit can significantly reduce time-to-market and result in an optimized system.

10.16 <u>KEELoq® Evaluation and</u> Programming Tools

KEELOQ evaluation and programming tools support Microchips HCS Secure Data Products. The HCS evaluation kit includes an LCD display to show changing codes, a decoder to decode transmissions, and a programming interface to program test transmitters.

TABLE 10-1: DEVELOPMENT TOOLS FROM MICROCHIP

	PIC12C5XX	PIC14000	PIC16C5X	PIC16CXXX	PIC16C6X	PIC16C7XX	PIC16C8X	PIC16C9XX	PIC17C4X	PIC17C75X		HCS200 HCS300 HCS301
PICMASTER®/ PICMASTER-CE In-Circuit Emulator	✓	✓	✓	✓	✓	✓	✓	✓	√	✓		
ICEPIC™ Low-Cost In-Circuit Emulator	✓		✓	✓	✓	✓	✓	✓				
MPLAB™ Integrated Development Environment	✓	✓	✓	✓	✓	✓ ·	✓	✓	✓	✓		
MPLAB™ C17 Compiler									✓	✓		
Compiler fuzzyTECH®-MP Explorer/Edition Fuzzy Logic Dev. Tool	✓	✓	✓	✓	✓	✓	✓	✓	✓			
MP-DriveWay™ Applications Code Generator			✓	✓	✓	✓	✓	✓	√			
Total Endurance™ Software Model											✓	
PICSTART®Plus Low-Cost Universal Dev. Kit	✓	✓	1	✓	✓	✓	✓	✓	✓	✓		
Universal Dev. Kit PRO MATE® II Universal Programmer	✓	✓	1	✓	✓	✓	✓	1	✓	✓	✓	✓
KEELOQ [®] Programmer												✓
SEEVAL® Designers Kit											✓	
PICDEM-1			✓	✓			✓		✓			
PICDEM-2					✓	✓						
PICDEM-3								✓				
KEELOQ [®] Evaluation Kit												✓

10.0 ELECTRICAL CHARACTERISTICS FOR PIC16F83 AND PIC16F84

Absolute Maximum Ratings †

Ambient temperature under bias	55°C to +125°C
Storage temperature	
Voltage on VDD with respect to Vss	-0.3 to +7.5V
Voltage on MCLR with respect to Vss ⁽²⁾	0.3 to +14V
Voltage on any pin with respect to Vss (except VDD and MCLR)	-0.6V to (VDD + 0.6V)
Total power dissipation ⁽¹⁾	800 mW
Maximum current out of Vss pin	150 mA
Maximum current into VDD pin	\100 mA
Input clamp current, Iικ (VI < 0 or VI > VDD)	± 20 mA
Output clamp current, lok (Vo < 0 or Vo > VDD)	
Maximum output current sunk by any I/O pin	25 mA
Maximum output current sourced by any I/O pin	20 mA
Maximum current sunk by PORTA	80 mA
Maximum current sunk by PORTA	50 mA
Maximum current sunk by PORTB	150 mA
Maximum current sourced by PORTB	100 mA
Note A. Deven dissination is calculated as follows Ddis 1/22 ///25	Thurst Till Till Till Till Till Till Till Til

Note 1: Power dissipation is calculated as follows: Pdis = $VDD \times \{\overline{DD} - \Sigma - Dx\} + \Sigma (VDD - VOH) \times IOH\} + \Sigma (VOI \times IOL)$

Note 2: Voltage spikes below Vss at the MCLR pin, inducing surrents greater than 80 mA, may cause latch-up. Thus, a series resistor of 50-100Ω should be used when applying a "low" level to the MCLR pin rather than pulling this pin directly to Vss.

† NOTICE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

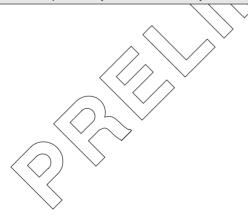
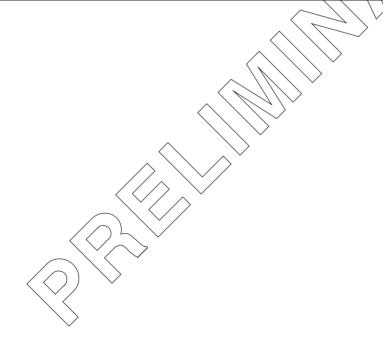


TABLE 10-1 CROSS REFERENCE OF DEVICE SPECS FOR OSCILLATOR CONFIGURATIONS AND FREQUENCIES OF OPERATION (COMMERCIAL DEVICES)

osc	PIC16F84-04	PIC16F84-10	PIC16LF84-04
	PIC16F83-04	PIC16F83-10	PIC16LF83-04
RC	VDD: 4.0V to 6.0V	VDD: 4.5V to 5.5V	VDD: 2.0V to 6.0V
	IDD: 4.5 mA max. at 5.5V	IDD: 1.8 mA typ. at 5.5V	IDD: 4.5 mA max. at 5.5V
	IPD: 14 μA max. at 4V WDT dis	IPD: 1.0 μA typ. at 5.5V WDT dis	IPD: 7.0 μA max. at 2V WDT dis
	Freq: 4.0 MHz max.	Freq: 40 MHz max.	Freq: 2.0 MHz max.
XT	VDD: 4.0V to 6.0V	VDD: 4.5V to 5.5V	VDD: 2.0V to 6.0V
	IDD: 4.5 mA max. at 5.5V	IDD: 1.8 mA typ. at 5.5V	IDD: 4.5 mA max. at 5.6V
	IPD: 14 μA max. at 4V WDT dis	IPD: 1.0 μA typ. at 5.5V WDT dis	IPD: 7.0 µA max. at 2V WDT dis
	Freq: 4.0 MHz max.	Freq: 4.0 MHz max.	Freq: 2.0 MHz max.
HS	VDD: 4.5V to 5.5V IDD: 4.5 mA typ. at 5.5V IPD: 1.0 µA typ. at 4.5V WDT dis	VDD: 4.5V to 5.5V IDD: 10 mA max. at 5.5V typ. IPD: 1.0 μA typ. at 4.5V WDT dis	Do not use in HS mode
LP	Freq: 4.0 MHz max. VDD: 4.0V to 6.0V IDD: 48 μA typ. at 32 kHz, 2.0V IPD: 0.6 μA typ. at 3.0V WDT dis Freq: 200 kHz max.	Freq: 10 MHz max. Do not use in LP mode	VDD: 2.0V10,6.0V IDD: 45 μA/max. at 32 kHz, 2.0V HD: 7 μA/max, at 2.0V WDT dis Freq: 200 kHz/max.

The shaded sections indicate oscillator selections which are tested for functionality, but not for MIN/MAX specifications. It is recommended that the user select the device type that ensures the specifications required.



10.1 DC CHARACTERISTICS: PIC16F84, PIC16F83 (Commercial, Industrial)

DC Characteristics Power Supply Pins				Standard Operating Conditions (unless otherwise stated) Operating temperature $0^{\circ}C \le TA \le +70^{\circ}C$ (commercial) $-40^{\circ}C \le TA \le +85^{\circ}C$ (industrial)					
Parameter No.	Sym	Characteristic	Min	Тур†	Max	Units	Conditions		
D001 D001A	VDD	Supply Voltage	4.0 4.5	_	6.0 5.5	V V	XT, RC and LP osc configuration HS osc configuration		
D002	VDR	RAM Data Retention Voltage ⁽¹⁾	1.5*	_	_	V	Device in SLEEP mode		
D003	VPOR	VDD start voltage to ensure internal Power-on Reset signal	_	Vss	_	V	See section on Power-on Reset for details		
D004	SVDD	VDD rise rate to ensure internal Power-on Reset signal	0.05*	_	_	V/ms	See section on Power-on Reset for details		
D010 D010A	IDD	Supply Current ⁽²⁾	_	1.8 7.3	4.5 10	mA mA	RC and XT osc configuration (4) Fosc = 4.0 MHz, VDD = 5.5V Fosc = 4.0 MHz, VDg = 5.5V (Dyring Flash programming)		
D013			_	5	10	mA<	HS oso configuration (PIC16F84-10) Foso = 10 MHz, VDD = 5.5V		
D020 D021 D021A	IPD	Power-down Current ⁽³⁾		7.0 1.0 1.0	28 14 16	μΑ μΑ μΑ	VDD = 4.0V, WDT enabled, industrial VDD = 4.0V, WDT disabled, commercial VDD = 4.0V, WDT disabled, industrial		

- These parameters are characterized but not tested.
- † Data in "Typ" column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

- 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as I/O pin loading and switching rate, oscillator type, internal code execution pattern, and temperature also have an impact on the current consumption.
 - The test conditions for all IDD measurements in active operation mode are:
 - OSC1=external square wave, from rail to tail, all I/O pins tristated, pulled to VDD, TOCKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
- 3: The power down current in SLEEP mode does not depend on the oscillator type. Power-down current is measured with the part in SLEEP mode, with all I/O pins in hi-impedance state and tied to VDD and Vss.
- 4: For RC osc configuration, current through Rext is not included. The current through the resistor can be estimated by the formula 15 = Vp0/2Rext (mA) with Rext in kOhm.



10.2 DC CHARACTERISTICS: PIC16LF84, PIC16LF83 (Commercial, Industrial)

DC Characteristics Power Supply Pins				Standard Operating Conditions (unless otherwise stated) Operating temperature $0^{\circ}C \le TA \le +70^{\circ}C$ (commercial) $-40^{\circ}C \le TA \le +85^{\circ}C$ (industrial)					
Parameter No.	Sym	Characteristic	Min	Тур†	Max	Units	Conditions		
D001	VDD	Supply Voltage	2.0	_	6.0	V	XT, RC, and LP osc configuration		
D002	VDR	RAM Data Retention Voltage ⁽¹⁾	1.5*	_	_	V	Device in SLEEP mode		
D003	VPOR	VDD start voltage to ensure internal Power-on Reset signal	_	Vss	_	V	See section on Power-on Reset/or details		
D004	SVDD	VDD rise rate to ensure internal Power-on Reset signal	0.05*	_	_	V/ms	See section on Power-on-Reset for details		
	IDD	Supply Current ⁽²⁾					RC and XT osc configuration (4)		
D010			—	1	4	mA	Fosc = 2.0 MHz, VDD = 5.5V		
D010A			_	7.3	10	mA	Fosc = 2.0 MHz, VDD = 5.5V (During Elash programming) LP osc configuration		
D014			_	15	45	μΑ <	Fosc ± 32 kHz, VDD = 2.0V, WDT disabled		
D020	IPD	Power-down Current ⁽³⁾	_	3.0	16	pΑ	Vbp = 2.0\ WDT enabled, industrial		
D021			—	0.4	7.0	√Aμ∕	VDD = 2.0V, WDT disabled, commercial		
D021A			_	0.4	9.0	μA `	VDD ≥ 2.0V, WDT disabled, industrial		

- * These parameters are characterized but not tested.
- † Data in "Typ" column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.
- Note 1: This is the limit to which VDD can be lowered in SAEER mode without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as I/O pin loading and switching rate, oscillator type, internal code execution pattern, and temperature also have an impact on the current consumption.
 - The test conditions for all IDD measurements in active operation mode are:
 - OSC1=external square wave, from rail to rail; all I/O pins tristated, pulled to VDD, TOCKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
 - 3: The power down current in SLEEP mode does not depend on the oscillator type. Power-down current is measured with the part in SLEEP mode, with all I/O pins in hi-impedance state and tied to VDD and Vss.
 - 4: For RC osc configuration, current through Rext is not included. The current through the resistor can be estimated by the formula R ≠√00/2Rext (mA) with Rext in kOhm.



10.3 DC CHARACTERISTICS:

PIC16F84, PIC16F83 (Commercial, Industrial) PIC16LF84, PIC16LF83 (Commercial, Industrial)

DC Characteristics All Pins Except Power Supply Pins Standard Operating Conditions (unless otherwise stated)

Operating temperature $0^{\circ}C \leq TA \leq +70^{\circ}C$ (commercial) $-40^{\circ}C \leq TA \leq +85^{\circ}C$ (industrial)

Operating voltage VDD range as described in DC spec

Section 10.1 and Section 10.2.

Parame- ter							
No.	Sym	Characteristic	Min	Typ†	Max	Units	Conditions
		Input Low Voltage					
	VIL	I/O ports					
D030		with TTL buffer	Vss	–	0.8	V	$4.5 \text{ V} \le \text{VDD} \le 5.5 \text{ V}^{(4)}$
D030A			Vss	–	0.16VDD	V	entire range(4)
D031		with Schmitt Trigger buffer	Vss	–	0.2VDD	V	entire range
D032		MCLR, RA4/T0CKI	Vss	_	0.2VDD	\	
D033		OSC1 (XT, HS and LP modes)(1)	Vss	—	0.3VDD	\ \	
D034		OSC1 (RC mode)	Vss	_	0.1VDD	V	
		Input High Voltage				, \	
	VIH	I/O ports		_	\		
D040		with TTL buffer	2.4	—	/VDD	\	$4.5 \text{ V} \le \text{VDD} \le 5.5 \text{ V}^{(4)}$
D040A			0.48VDD	_	/VDD	\V\	entire range ⁽⁴⁾
D041		with Schmitt Trigger buffer	0.45VDD		NDB /		entire range
D042		MCLR, RA4/T0CKI, OSC1	0.85	\ \tau'.	ADD	> v	
		(RC mode)	VDD<	\ '	\ .\	\ , <i>,</i>	
D043) (OSC1 (XT, HS and LP modes)(1)	0.7 VDD	$\sqrt{-}$	Vpb	V	
D050	VHYS	Hysteresis of Schmitt Trigger inputs	TRD		> -	V	
D070	IPURB	PORTB weak pull-up current	50	250*	400*	μA	VDD = 5.0V, VPIN = VSS
D070	IFURB	Input Leakage Current(2,3)	1301	\ \ \\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	400	μΛ	VDD = 3.0 V, VFIN = V33
D060	lil.	I/O ports	$//\sim$	_	±1	μA	Vss ≤ VPIN ≤ VDD,
D000	"-	WO ports				μΛ	Pin at hi-impedance
D061		MCLR, RA4/TOCKI	> –	_	±5	μА	Vss ≤ Vpin ≤ Vdd
D063		OSC1	_	_	±5	μA	Vss ≤ VPIN ≤ VDD, XT, HS
						·	and LP osc configuration
		Output Low Voltage					
D080	VOL	I/O ports	_	–	0.6	V	IOL = 8.5 mA, VDD = 4.5V
D083		OSC2/CLKQUT/	_	_	0.6	V	IOL = 1.6 mA, VDD = 4.5V
	/,	Output High Voltage					
D090	VOH	WØ ports(3)	VDD-0.7	-	_	V	IOH = -3.0 mA, VDD = 4.5V
D092	\Box	OŚC2/CLKOUT	VDD-0.7	_	_	V	IOH = -1.3 mA, VDD = 4.5V

These parameters are characterized but not tested.

[†] Data in "Typ" column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: In RC oscillator configuration, the OSC1 pin is a Schmitt Trigger input. Do not drive the PIC16F8X with an external clock while the device is in RC mode, or chip damage may result.

^{2:} The leakage current on the MCLR pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltages.

^{3:} Negative current is defined as coming out of the pin.

^{4:} The user may choose the better of the two specs.

10.4 DC CHARACTERISTICS: PIC16F84, PIC16F83 (Commercial, Industrial) PIC16LF84, PIC16F83 (Commercial, Industrial)

Parameter No.	Sym	Characteristic	Min	Тур†	Max	Units	Conditions
		Capacitive Loading Specs on Output Pins					\wedge
D100	Cosc ₂	OSC2 pin	_	_	15	pF	In XT, HS and LP modes when external clock is used to drive OSC1.
D101	Сю	All I/O pins and OSC2 (RC mode)	_	_	50	pF	
		Data EEPROM Memory					
D120	ED	Endurance	1M	10M	_	EAV	25°C at 5V
D121	VDRW	VDD for read/write	VMIN	_	6.0	\v/	VMIN = Minimum operating voltage
D122	TDEW	Erase/Write cycle time	_	10	2 0*	m's \	
		Program Flash Memory		_			
D130	EР	Endurance	100	1000		Ewy \	
D131	VPR	VDD for read	VMIN		6.0	V	VMIN = Minimum operating voltage
D132	VPEW	VDD for erase/write	4.5	/ - /	5.5	V	
D133	TPEW	Erase/Write cycle time	/`	/ 94 /	$\downarrow >$	ms	

^{*} These parameters are characterized but not tested.

[†] Data in "Typ" column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

TABLE 10-2 TIMING PARAMETER SYMBOLOGY

The timing parameter symbols have been created following one of the following formats:

1. TppS2ppS

2. TppS

2. TPPO			
Т			
F	Frequency	Т	Time
Lowerd	case symbols (pp) and their meanings:		
pp			4
2	to	os,osc	OSC1
ck	CLKOUT	ost	oscillator start-up timer _ \ \
су	cycle time	pwrt	power-up timer
io	I/O port	rbt	RBx pins
inp	INT pin	t0	TOCKI
mc	MCLR	wdt	watchdog timer
Upper	case symbols and their meanings:		*/ \
S			
F	Fall	P	Period
Н	High	R	Rise
I	Invalid (Hi-impedance)	V	Valid
1	Low	7 ~	High Impedance

FIGURE 10-1: PARAMETER MEASUREMENT INFORMATION

All timings are measure between high and low measurement points as indicated in the figures below.

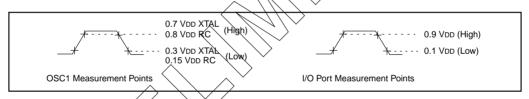
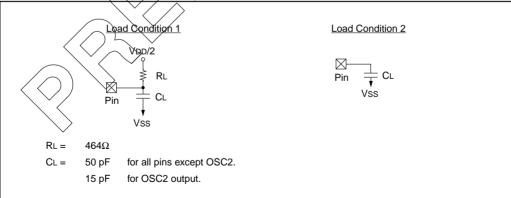


FIGURE 10-2: LOAD CONDITIONS



10.5 Timing Diagrams and Specifications

FIGURE 10-3: EXTERNAL CLOCK TIMING

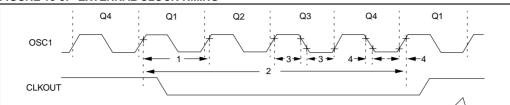


TABLE 10-3 EXTERNAL CLOCK TIMING REQUIREMENTS

Parameter No.	Sym	Characteristic	Min	Тур†	Max	Units	Co	onditions
	Fosc	External CLKIN Frequency ⁽¹⁾	DC		2	MHz	XT, RC osc	PIC16LF8X-04
			DC	_	4	MHz	XT, RC ose	RIC)76F8X-04
			DC	_	10	MHz	HS osc	PIC16F8X-10
			DC	_	200	kHz~	LP osc	PIC16LF8X-04
		Oscillator Frequency ⁽¹⁾	DC		2	MHz	RC ose	PIC16LF8X-04
			DC	_	/4	MiH ∑ ∕	RC osc	PIC16F8X-04
			0.1	_	/2 /	MHz ⁽	(XT osc	PIC16LF8X-04
			0.1	-/~	4	MHX	XT osc	PIC16F8X-04
			1.0	_	10	MHz	HS osc	PIC16F8X-10
			DC		200	√kHz	LP osc	PIC16LF8X-04
1	Tosc	External CLKIN Period ⁽¹⁾	500	/-/	$\left \begin{array}{c} \leftarrow \end{array} \right $	ns	XT, RC osc	PIC16LF8X-04
			(250 €	/ –/	\ <u>~</u> `	ns	XT, RC osc	PIC16F8X-04
			1\Q0\\	$' \neq '$	√ − ∣	ns	HS osc	PIC16F8X-10
			5.0	//-/	_	μs	LP osc	PIC16LF8X-04
		Oscillator Period ⁽¹⁾	\$60	/ /	_	ns	RC osc	PIC16LF8X-04
			250	\vee -	_	ns	RC osc	PIC16F8X-04
			500	_	10,000	ns	XT osc	PIC16LF8X-04
			250	_	10,000	ns	XT osc	PIC16F8X-04
			/100	_	1,000	ns	HS osc	PIC16F8X-10
			5.0	_	_	μs	LP osc	PIC16LF8X-04
2	TCY	Instruction Cycle Time(1)	0.4	4/Fosc	DC	μs		
3	TosL,	Clock in (OSC1) High or Low	60 *	_	_	ns	XT osc	PIC16LF8X-04
	TosH	Time	50 *	_	_	ns	XT osc	PIC16F8X-04
		<u>-</u> \ \ \ / /	2.0 *	_	_	μs	LP osc	PIC16LF8X-04
			35 *	_	_	ns	HS osc	PIC16F8X-10
4	TosR,	Clock in (QSC1) Rise or Fall Time	25 *	_	_	ns	XT osc	PIC16F8X-04
	TosF		50 *	_	_	ns	LP osc	PIC16LF8X-04
			15 *	_	_	ns	HS osc	PIC16F8X-10

^{*} These parameters are characterized but no tested.

Note 1: Instruction cycle period (TcY) equals four times the input oscillator time-base period. All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. All devices are tested to operate at "min." values with an external clock applied to the OSC1 pin.

When an external clock input is used, the "Max." cycle time limit is "DC" (no clock) for all devices.

[†] Data in "Typ" column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

FIGURE 10-4: CLKOUT AND I/O TIMING

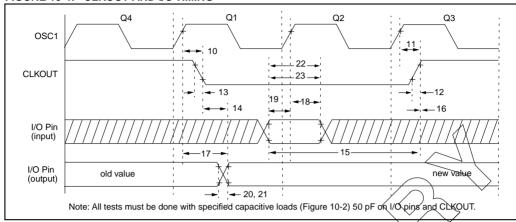


TABLE 10-4 CLKOUT AND I/O TIMING REQUIREMENTS

Parameter No.	Sym	Characteri	etic	Min	Typ†	Max	Units	Conditions
-	_				$\overline{}$	/		
10	TosH2ckL	OSC1↑ to CLKOUT↓	PIC16F8X		1/5	30 *	ns	Note 1
10A			PIC16LF8X		\15\	120 *	ns	Note 1
11	TosH2ckH	OSC1↑ to CLKOUT↑	PIC16F8X	17	_/15	30 *	ns	Note 1
11A			PIC16LF8X	/ //	15	120 *	ns	Note 1
12	TckR	CLKOUT rise time	PIC1øF8X	\	15	30 *	ns	Note 1
12A			PIC16LF8X	\rightarrow	15	100 *	ns	Note 1
13	TckF	CLKOUT fall time	PIC16F8X	\	15	30 *	ns	Note 1
13A		\	RICYBLE8X	_	15	100 *	ns	Note 1
14	TckL2ioV	CLKOUT ↓ to Port out	valid	_	_	0.5Tcy +20 *	ns	Note 1
15	TioV2ckH	Port in valid before	PIC16F8X	0.30Tcy + 30 *	_	_	ns	Note 1
		CLKOUT^(RIC16LF8X	0.30Tcy + 80 *	_	_	ns	Note 1
16	TckH2ioI	Port in hold after CLKO	IJŢ Ŷ	0 *	_	_	ns	Note 1
17	TosH2ioV	ØSC11 (Q1 cycle) to	PIC16F8X	_	_	125 *	ns	
		Port øut valid	PIC16LF8X	_	_	250 *	ns	
18	TosH2iol	OSC1 (Q2 cycle) to	PIC16F8X	10 *	_	_	ns	
		Rort input invalid (I/O in hold time)	PIC16LF8X	10 *		_	ns	
19	TioV2osH	Rort input valid to	PIC16F8X	-75 *	_	_	ns	
	$\backslash \backslash \backslash$	OSC1↑ (I/O in setup time)	PIC16LF8X	-175 *		_	ns	
20/	TioR	Port output rise time	PIC16F8X	_	10	35 *	ns	
20A	ĺ		PIC16LF8X	_	10	70 *	ns	
21	TioF	Port output fall time	PIC16F8X	_	10	35 *	ns	
21A			PIC16LF8X	_	10	70 *	ns	
22	Tinp	INT pin high	PIC16F8X	20 *	_	_	ns	
22A		or low time	PIC16LF8X	55 *	_	_	ns	
23	Trbp	RB7:RB4 change INT	PIC16F8X	Tosc §	_	_	ns	
23A		high or low time	PIC16LF8X	Tosc §	_	_	ns	

^{*} These parameters are characterized but not tested.

Note 1: Measurements are taken in RC Mode where CLKOUT output is 4 x Tosc.

[†] Data in "Typ" column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

[§] By design

FIGURE 10-5: RESET, WATCHDOG TIMER, OSCILLATOR START-UP TIMER AND POWER-UP TIMER TIMING

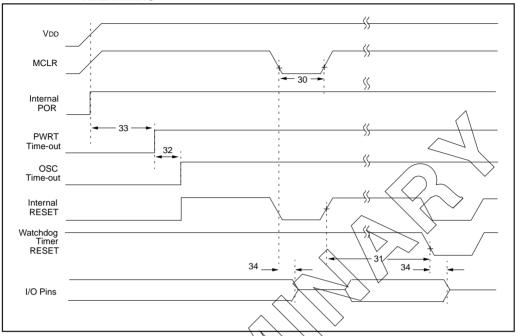


TABLE 10-5 RESET, WATCHDOG TIMER, OSCILLATOR START-UP TIMER AND POWER-UP TIMER REQUIREMENTS

Parameter No.	Sym	Characteristic	Min		Max	Units	Conditions
30	TmcL	MCLR Pulse Width (low)	1000 *	_	_	ns	2.0V ≤ VDD ≤ 6.0V
31	Twdt	Watchdog Timer Time-out Period (No Prescaler)	7 *	18	33 *	ms	VDD = 5.0V
32	Tost	Oscillation Start-up Timer Period		1024Tosc		ms	Tosc = OSC1 period
33	Tpwrt	Power-up Timer Period	28 *	72	132 *	ms	VDD = 5.0V
34	Tioz	I/O Hi-impedance from MCLR Low or reset	_	_	100 *	ns	

^{*} These parameters are characterized but not tested.

[†] Data in "Typ" column is at 50,25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

FIGURE 10-6: TIMERO CLOCK TIMINGS

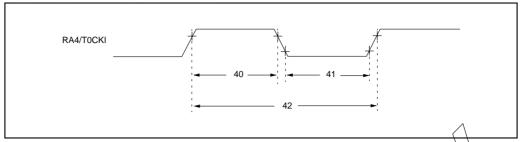


TABLE 10-6 TIMERO CLOCK REQUIREMENTS

Parameter No.	Sym	Characteristic		Min	Тур†	Max	Units	Conditions
40	Tt0H	T0CKI High Pulse Width	No Prescaler	0.5Tcy + 20 *	_	/-/	ns	
			With Prescaler	50 * 30 *	/	7	ns ns	$2.0V \le VDD \le 3.0V$ $3.0V \le VDD \le 6.0V$
41	Tt0L	T0CKI Low Pulse Width	No Prescaler	0.5Tcy + 20 (1	/	ns	
			With Prescaler	50 * 20*	+		ns ns	$2.0V \le VDD \le 3.0V$ $3.0V \le VDD \le 6.0V$
42	Tt0P	T0CKI Period		Tcy + 40	F	> -	ns	N = prescale value (2, 4,, 256)

* These parameters are characterized but not tested.

† Data in "Typ" column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

NOTES:



11.0 ELECTRICAL CHARACTERISTICS FOR PIC16CR83 AND PIC16CR84

Absolute Maximum Ratings †

Ambient temperature under bias	55°C to +125°C
Storage temperature	65°C to +150°C
Voltage on VDD with respect to Vss	-0.3 to +7.5V
Voltage on MCLR with respect to Vss ⁽²⁾	0.3 to +14V
Voltage on any pin with respect to Vss (except VDD and $\overline{\text{MCLR}})$	0.6V to (VDD + 0.6V)
Total power dissipation ⁽¹⁾	800 mW
Maximum current out of Vss pin	á .
Maximum current into VDD pin	
Input clamp current, lik (Vi < 0 or Vi > VDD)	± 20 mA
Output clamp current, lok (Vo < 0 or Vo > VDD)	±20 mA
Maximum output current sunk by any I/O pin	25 mA
Maximum output current sourced by any I/O pin	20 mA
Maximum current sunk by PORTA	80 mA
Maximum current sourced by PORTA	50 mA
Maximum current sunk by PORTB	150 mA
Maximum current sunk by PORTB	100 mA

Note 1: Power dissipation is calculated as follows: Pdis = $VDD \times \{DD - \Sigma DH\} + \sum (VDD - VOH) \times DOH\} + \sum (VOI \times DOL)$

Note 2: Voltage spikes below Vss at the MCLR pin, inducing surrents greater than 80 mA, may cause latch-up. Thus, a series resistor of 50-100Ω should be used when applying a "low" level to the MCLR pin rather than pulling this pin directly to Vss.

† NOTICE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

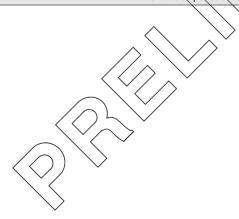


TABLE 11-1 CROSS REFERENCE OF DEVICE SPECS FOR OSCILLATOR CONFIGURATIONS AND FREQUENCIES OF OPERATION (COMMERCIAL DEVICES)

osc	PIC16CR84-04	PIC16CR84-10	PIC16LCR84-04
	PIC16CR83-04	PIC16CR83-10	PIC16LCR83-04
RC	VDD: 4.0V to 6.0V	VDD: 4.5V to 5.5V	VDD: 2.0V to 6.0V
	IDD: 4.5 mA max. at 5.5V	IDD: 1.8 mA typ. at 5.5V	IDD: 4.5 mA max. at 5.5V
	IPD: 14 μA max. at 4V WDT dis	IPD: 1.0 μA typ. at 5.5V WDT dis	IPD: 5 µA max. at 2V WDT dis
	Freq: 4.0 MHz max.	Freq: 40 MHz max.	Freq: 2.0 MHz max.
XT	VDD: 4.0V to 6.0V	VDD: 4.5V to 5.5V	VDD: 2.0V to 6.0V
	IDD: 4.5 mA max. at 5.5V	IDD: 1.8 mA typ. at 5.5V	IDD: 4.5 mA max. at 5.5V
	IPD: 14 μA max. at 4V WDT dis	IPD: 1.0 μA typ. at 5.5V WDT dis	IPD: 5 µA max. at 2V WDT dis
	Freq: 4.0 MHz max.	Freq: 4.0 MHz max.	Freq: 2.0 MHz max.
HS	VDD: 4.5V to 5.5V IDD: 4.5 mA typ. at 5.5V IPD: 1.0 μA typ. at 4.5V WDT dis Freq: 4.0 MHz max.	VDD: 4.5V to 5.5V IDD: 10 mA max. at 5.5V typ. IPD: 1.0 μA typ. at 4.5V WDT dis Freq: 10 MHz max.	Do not use in HS mode
LP	VDD: $4.0V$ to $6.0V$ IDD: $48~\mu\text{A}$ typ. at $32~\text{kHz}$, $2.0V$ IPD: $0.6~\mu\text{A}$ typ. at $3.0V$ WDT dis Freq: $200~\text{kHz}$ max.	Do not use in LP mode	VDD: 2,0V46 6,0V IDD: 45 µA max. at 32 kHz, 2.0V IPD: 5 µA max. at 2V WDT dis Freq: 200 kH2 max.

The shaded sections indicate oscillator selections which are tested for functionality, but not for MIN/MAX specifications. It is recommended that the user select the device type that ensures the specifications required.



11.1 DC CHARACTERISTICS: PIC16CR84, PIC16CR83 (Commercial, Industrial)

DC Characteristics Power Supply Pins				Standard Operating Conditions (unless otherwise stated) Operating temperature $0^{\circ}C \le TA \le +70^{\circ}C$ (commercial) $-40^{\circ}C \le TA \le +85^{\circ}C$ (industrial)							
Parameter No.	Sym	Characteristic	Min	Тур†	Max	Units	Conditions				
D001 D001A	VDD	Supply Voltage	4.0 4.5	_	6.0 5.5	V	XT, RC and LP osc configuration HS osc configuration				
D002	VDR	RAM Data Retention Voltage ⁽¹⁾	1.5*	_	_	V	Device in SLEEP mode				
D003	VPOR	VDD start voltage to ensure internal Power-on Reset signal	_	Vss	_	V	See section on Power-on Reset for details				
D004	SVDD	VDD rise rate to ensure internal Power-on Reset signal	0.05*	_	_	V/ms	See section on Power-on Reset-for details				
D010 D010A	IDD	Supply Current ⁽²⁾	_	1.8 7.3	4.5 10	mA mA	RC and XT osc configuration Fosc = 4.0 MHz, VDD = 5.5V FOSC = 4.0 MHz, VDD = 5.5V (During EERROM programming) HS osc configuration (PIC16CR84-10)				
D013			_	5	10	mA<	Fosc = 10 MHz, VDD = 5.5V				
D020 D021 D021A	IPD	Power-down Current ⁽³⁾		7.0 1.0 1.0	28 14 16	μA μA	VDD = 4.0V, WDT enabled, industrial VDD = 4.0V, WDT disabled, commercial VDD = 4.0V, WDT disabled, industrial				

- These parameters are characterized but not tested.
- † Data in "Typ" column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

- 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as I/O pin loading and switching rate, oscillator type, internal code execution pattern, and temperature also have an impact on the current consumption.
 - The test conditions for all IDD measurements in active operation mode are:
 - OSC1=external square wave, from rail to tail, all I/O pins tristated, pulled to VDD, TOCKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
- 3: The power down current in SLEEP mode does not depend on the oscillator type. Power-down current is measured with the part in SLEEP mode, with all I/O pins in hi-impedance state and tied to VDD and Vss.
- 4: For RC osc configuration, current through Rext is not included. The current through the resistor can be estimated by the formula 15 = Vp0/2Rext (mA) with Rext in kOhm.



11.2 DC CHARACTERISTICS: PIC16LCR84, PIC16LCR83 (Commercial, Industrial)

DC Charac Power Sup			Standard Operating Conditions (unless otherwise stated) Operating temperature $0^{\circ}C \le TA \le +70^{\circ}C$ (commercial) $-40^{\circ}C \le TA \le +85^{\circ}C$ (industrial)					
Parameter No.	Sym	Characteristic	Min	Тур†	Max	Units	Conditions	
D001	VDD	Supply Voltage	2.0	_	6.0	V	XT, RC, and LP osc configuration	
D002	VDR	RAM Data Retention Voltage ⁽¹⁾	1.5*	_	_	V	Device in SLEEP mode	
D003	VPOR	VDD start voltage to ensure internal Power-on Reset signal	_	Vss	_	V	See section on Power-on Reservor details	
D004	SVDD	VDD rise rate to ensure internal Power-on Reset signal	0.05*	_	_	V/ms	See section on Power-on-Reset for details	
D010 D010A	IDD	Supply Current ⁽²⁾	_	1 7.3	4 10	mA mA	RC and XT osc configuration (4) Fosc = 2.0 MHz, VDD = 5.5V Fosc = 2.0 MHz, VDD = 5.5V (During EEPROM programming) LP osc configuration	
D014			_	15	45	μA <	Fosc = 32 kHz, VDD = 2.0V, WDT disabled	
D020 D021 D021A	IPD	Power-down Current ⁽³⁾		3.0 0.4 0.4	16 5.0 6.0	μΑ	VBD ≥2.0 WDT enabled, industrial VDD = 2.0 V, WDT disabled, commercial VDD = 2.0 V, WDT disabled, industrial	

- * These parameters are characterized but not tested.
- † Data in "Typ" column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEER made without losing RAM data.
 - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as I/O pin loading and switching rate, oscillator type, internal code execution pattern, and temperature also have an impact on the current consumption.
 - The test conditions for all IDD measurements in active operation mode are:
 - OSC1=external square wave, from rail to rail; all I/O pins tristated, pulled to VDD, T0CKI = VDD, MCLR = VDD: WDT enabled/disabled as specified.
 - 3: The power down current in SLEEP mode does not depend on the oscillator type. Power-down current is measured with the part in SLEEP mode, with all I/O pins in hi-impedance state and tied to VDD and Vss.
 - 4: For RC osc configuration, current through Rext is not included. The current through the resistor can be estimated by the formula R = √00/2Rext (mA) with Rext in kOhm.



11.3 DC CHARACTERISTICS:

PIC16CR84, PIC16CR83 (Commercial, Industrial) PIC16LCR84, PIC16LCR83 (Commercial, Industrial)

Section 11.1 and Section 11.2.

DC Characteristics All Pins Except Power Supply Pins Standard Operating Conditions (unless otherwise stated)

Operating temperature $0^{\circ}C \le TA \le +70^{\circ}C$ (commercial) $-40^{\circ}C \le TA \le +85^{\circ}C$ (industrial)

Operating voltage VDD range as described in DC spec

D					00000011		
Parame- ter							
No.	Sym	Characteristic	Min	Typ†	Max	Units	Conditions
		Input Low Voltage					\wedge
	VIL	I/O ports					\
D030		with TTL buffer	Vss	_	0.8	V	$4.5 \text{ V} \leq \text{V} \text{dd} \leq 5 \sqrt{5} \sqrt{4}$
D030A			Vss	_	0.16VDD	V	entire range(4)
D031		with Schmitt Trigger buffer	Vss	_	0.2VDD	V	entire range
D032		MCLR, RA4/T0CKI	Vss	_	0.2VDD	V <	
D033		OSC1 (XT, HS and LP modes) ⁽¹⁾	Vss	_	0.3VDD	\ \ \ \	$\backslash \backslash \backslash \backslash \rangle$
D034		OSC1 (RC mode)	Vss	_	0.1VDD/	V	
		Input High Voltage				1	
	VIH	I/O ports		_	\ \ \ \ \ \	$\setminus \vee$	
D040		with TTL buffer	2.4	_	VDD	\v($4.5 \text{ V} \le \text{VDD} \le 5.5 \text{V}^{(4)}$
D040A			0.48VDD		Nøb	V/	entire range ⁽⁴⁾
D041		with Schmitt Trigger buffer	0.45VDD	/ / ,	ADD		entire range
D042		MCLR, RA4/T0CKI, OSC1 (RC mode)	0.85 VDQ	//	ADD	V	
D043		OSC1 (XT, HS and LP modes) ⁽¹⁾	0.7 KDD	(\neq)	> VDD	V	
D050	VHYS	Hysteresis of Schmitt Trigger inputs	TBD	\sum	_	V	
D070	IPURB	PORTB weak pull-up current	50*	250*	400*	μΑ	VDD = 5.0V, VPIN = VSS
		Input Leakage Current ^(2,3)					
D060	lı∟	I/O ports	> -	_	±1	μА	Vss ≤ VPIN ≤ VDD, Pin at hi-impedance
D061		MCLR, RA4/TOCKI	_	_	±5	μΑ	Vss ≤ VPIN ≤ VDD
D063		OSC1	_	_	±5	μΑ	Vss ≤ VPIN ≤ VDD, XT, HS and LP osc configuration
		Output Low Voltage					
D080	Vol/	1/O ports	-	—	0.6	V	IOL = 8.5 mA, VDD = 4.5V
D083		OSC2/CLKOUT	_	–	0.6	V	IOL = 1.6 mA, VDD = 4.5V
		Qutput High Voltage					
D090 <	V) н)	I/O ports(3)	VDD-0.7	–	_	V	IOH = -3.0 mA, VDD = 4.5V
D092	\mathbb{Z}	OSC2/CLKOUT	VDD-0.7			V	IOH = -1.3 mA, VDD = 4.5V

- These parameters are characterized but not tested.
- † Data ln. Typ" column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.
- Note 1: In RC oscillator configuration, the OSC1 pin is a Schmitt Trigger input. Do not drive the PIC16CR8X with an external clock while the device is in RC mode, or chip damage may result.
 - 2: The leakage current on the MCLR pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltages.
 - 3: Negative current is defined as coming out of the pin.
 - 4: The user may choose the better of the two specs.

11.4 DC CHARACTERISTICS: PIC16CR84, PIC16CR83 (Commercial, Industrial) PIC16LCR84, PIC16LCR83 (Commercial, Industrial)

 Standard Operating Conditions (unless otherwise stated)

 DC Characteristics
 Operating temperature 0° C $\leq TA \leq +70^{\circ}$ C (commercial)

 All Pins Except
 -40° C $\leq TA \leq +85^{\circ}$ C (industrial)

 Power Supply Pins
 Operating voltage VDD range as described in DC spec

 Section 11.1 and Section 11.2.

			Cootion	i i i i ana c	20000011 1		
Parameter No.	Sym	Characteristic	Min	Тур†	Max	Units	Conditions
		Capacitive Loading Specs on Output Pins					\wedge
D100	Cosc ₂	OSC2 pin	_	_	15	pF	In XT, HS and LP modes when external clock is used to drive OSC1.
D101	Сю	All I/O pins and OSC2 (RC mode)	_	_	50	pF	
		Data EEPROM Memory					
D120	ED	Endurance	1M	10M	_	E/W	25°C at 5V
D121	VDRW	VDD for read/write	VMIN	_	6.0	(N)	Vми = Miximum operating voltage
D122	TDEW	Erase/Write cycle time	—	10	20 *	m's `	/ ~

* These parameters are characterized but not tested.

† Data in "Typ" column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

TABLE 11-2 TIMING PARAMETER SYMBOLOGY

The timing parameter symbols have been created following one of the following formats:

1. TppS2ppS

Z. IPPO

Т			
F	Frequency	Т	Time
Lower	case symbols (pp) and their meanings:		
pp			4
2	to	os,osc	OSC1
ck	CLKOUT	ost	oscillator start-up timer _ \
су	cycle time	pwrt	power-up timer
io	I/O port	rbt	RBx pins
inp	INT pin	t0	TOCKI
mc	MCLR	wdt	watchdog timer
Upper	case symbols and their meanings:		
S			
F	Fall	P	Period
Н	High	R	Rise
I	Invalid (Hi-impedance)	V	Valid \
1	Low	7 ~	High Impedance

FIGURE 11-1: PARAMETER MEASUREMENT INFORMATION

All timings are measure between high and low measurement points as indicated in the figures below.

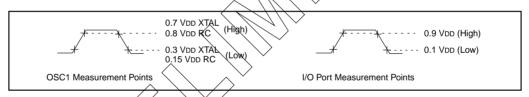
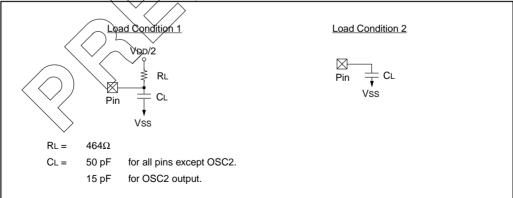


FIGURE 11-2: LOAD CONDITIONS



11.5 Timing Diagrams and Specifications

FIGURE 11-3: EXTERNAL CLOCK TIMING

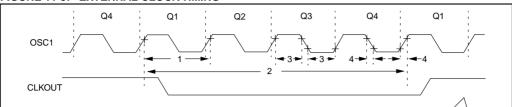


TABLE 11-3 EXTERNAL CLOCK TIMING REQUIREMENTS

Parameter No.	Sym	Characteristic	Min	Тур†	Max	Units	C	onditions
	Fosc	External CLKIN Frequency ⁽¹⁾	DC	_	2	MHz	XT, RC osc	PIÇ16LCR8X-04
			DC	_	4	MHz	XT, RC 05C	RIC16CR8X-04
			DC	_	10	MHz	HS osc	PIC16CR8X-10
			DC	_	200	kḤz	¹⊾P osc \	PIC16LCR8X-04
		Oscillator Frequency ⁽¹⁾	DC	_	,2	МНХ	RC osc	PIC16LCR8X-04
			DC	_	4	MHz,	RC osc	PIC16CR8X-04
			0.1		2 \	MHz	XT osc	PIC16LCR8X-04
			0.1	\prec	4	MHz	XT osc	PIC16CR8X-04
			1.0	\wedge	10	M Hz	HS osc	PIC16CR8X-10
			DČ	/-/	200	kHz	LP osc	PIC16LCR8X-04
1	Tosc	External CLKIN Period ⁽¹⁾	€0Q	$\langle - \rangle$	$\backslash \simeq$	ns	XT, RC osc	PIC16LCR8X-04
			250	(+)	√ −	ns	XT, RC osc	PIC16CR8X-04
			100/	$//-\rangle$	_	ns	HS osc	PIC16CR8X-10
			5.0	1 \\	_	μs	LP osc	PIC16LCR8X-04
		Oscillator Period ⁽¹⁾	500		_	ns	RC osc	PIC16LCR8X-04
			250	_	_	ns	RC osc	PIC16CR8X-04
			500	_	10,000	ns	XT osc	PIC16LCR8X-04
			250	_	10,000	ns	XT osc	PIC16CR8X-04
			100	_	1,000	ns	HS osc	PIC16CR8X-10
			5.0		_	μs	LP osc	PIC16LCR8X-04
2	TCY	Instruction Cycle Time ⁽¹⁾	0.4	4/Fosc	DC	μs		
3	TosL,	Clock in (QSC1) High or Low	60 *	_	_	ns	XT osc	PIC16LCR8X-04
	TosH	Time	50 *	_	_	ns	XT osc	PIC16CR8X-04
		$\langle \rangle$	2.0 *	_	_	μs	LP osc	PIC16LCR8X-04
			35 *			ns	HS osc	PIC16CR8X-10
4//	JosiR,	Clock in (OSC1) Rise or Fall Time	25 *	_	_	ns	XT osc	PIC16CR8X-04
$ $ \langle \langle	Tos⊭	\ \ \	50 *	_	_	ns	LP osc	PIC16LCR8X-04
L ,	<u> </u>		15 *			ns	HS osc	PIC16CR8X-10

^{*} These parameters are characterized but not tested.

When an external clock input is used, the "Max." cycle time limit is "DC" (no clock) for all devices.

[†] Data in "Typ" column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: Instruction cycle period (TcY) equals four times the input oscillator time base period. All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. All devices are tested to operate at "min." values with an external clock applied to the OSC1 pin.

FIGURE 11-4: CLKOUT AND I/O TIMING

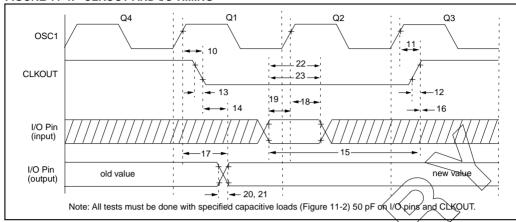


TABLE 11-4 CLKOUT AND I/O TIMING REQUIREMENTS

No. Sym Characteristic Min Typt Max Units Conditions	Parameter					1	\sim		
10A		Sym	Characteristic		Min	Typt	Max	Units	Conditions
11 TosH2ckH OSC1↑ to CLKOUT↑ PIC16CR8X	10	TosH2ckL	OSC1↑ to CLKOUT↓	PIC16CR8X	7/	15	30 *	ns	Note 1
11A	10A			PIC16LCR8X		15	120 *	ns	Note 1
12	11	TosH2ckH	OSC1↑ to CLKOUT↑	PIC16CR8X	17	<u>_</u> /15	30 *	ns	Note 1
12A	11A			PIC16LCR8X	/ //	15	120 *	ns	Note 1
13	12	TckR	CLKOUT rise time	1 \ \ \	\ <u>-</u> \	15	30 *	ns	Note 1
13A	12A			PIC16LCR8X	\rightarrow	15	100 *	ns	Note 1
14 TckL2ioV CLKOUT ↓ to Po'n out valid — — 0.5Tcy +20 * ns Note 1 15 TioV2ckH Port in valid before CLKOUT ↑ PtC16CR8X 0.30Tcy + 30 * — — ns Note 1 16 TckH2ioI Port in hold after CLKOUT ↑ 0 * — — ns Note 1 17 TosH2ioV ØSC1↑ (Q↑ cycle) to PC16CR8X — — 125 * ns 18 TosH2ioI OSC1↑ (Q2 cycle) to PC16LCR8X — — 250 * ns 18 TosH2ioI OSC1↑ (Q2 cycle) to PC16LCR8X PlC16CR8X 10 * — — ns PlC16LCR8X 10 * — — ns ns ns ns 19 TioV2osH Rort input valid to OSC1↑ (I/O in setup filme) PlC16CR8X -75 * — — ns 20 TioR Port output rise time PlC16CR8X — 10 35 * ns 20 TioF Port output fall time PlC16CR8X — 10 70 * ns 21 Tiop INT pin high	13	TckF	CLKOUT fall time	PIC16CR8X	\	15	30 *	ns	Note 1
TioV2ckH	13A		_ `	PICTOLCR8X	_	15	100 *	ns	Note 1
CLKOUT	14	TckL2ioV	CLKOUT ↓ to Port out	valid	_	_	0.5Tcy +20 *	ns	Note 1
16	15	TioV2ckH	Port in valid before	PIC16CR8X	0.30Tcy + 30 *	_	_	ns	Note 1
17			CLKOUT (RIC16LCR8X	0.30Tcy + 80 *	_	_	ns	Note 1
Port out yalid PIC16LCR8X 250 * ns	16	TckH2ioI	Port in hold after CLKØ	UJT Ť	0 *	_	_	ns	Note 1
TosH2iol	17	TosH2ioV	ØSC11 (Q1 cycle) to	PIC16CR8X	_	_	125 *	ns	
Rort invalid invalid (I/O in hold time)			Port out valid	PIC16LCR8X	_	_	250 *	ns	
19	18	TosH2iol		PIC16CR8X	10 *	_	_	ns	
OSC11 (I/O in setup time)				PIC16LCR8X	10 *		_	ns	
Tior Port output rise time PIC16CR8X — 10 35 * ns	19	TioV2osH	X 1 1 1 1 1 1 1 1	PIC16CR8X	-75 *		_	ns	
PIC16LCR8X		\	[X ' '	PIC16LCR8X	-175 *		_	ns	
TioF Port output fall time PIC16CR8X — 10 35 * ns	/20/	TioR	Port output rise time	PIC16CR8X	_	10	35 *	ns	
21A PIC16LCR8X — 10 70 * ns 22 Tinp INT pin high PIC16CR8X 20 * — — ns 22A or low time PIC16LCR8X 55 * — — ns	20A /	ĺ		PIC16LCR8X	_	10	70 *	ns	
22 Tinp INT pin high or low time PIC16CR8X 20 * ns - ns 22A PIC16LCR8X 55 * ns - ns	21	TioF	Port output fall time	PIC16CR8X	_	10	35 *	ns	
22A or low time PIC16LCR8X 55 * — ns	21A	}		PIC16LCR8X	_	10	70 *	ns	
	22	Tinp	INT pin high	PIC16CR8X	20 *	_	_	ns	
23 Trbp RB7:RB4 change INT PIC16CR8X Tosc § — ns	22A		or low time	PIC16LCR8X	55 *	_	_	ns	
	23	Trbp	RB7:RB4 change INT	PIC16CR8X	Tosc §	_	_	ns	
23A high or low time PIC16LCR8X Tosc §	23A		high or low time	PIC16LCR8X	Tosc §	_	_	ns	

^{*} These parameters are characterized but not tested.

Note 1: Measurements are taken in RC Mode where CLKOUT output is 4 x Tosc.

[†] Data in "Typ" column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

[§] By design

FIGURE 11-5: RESET, WATCHDOG TIMER, OSCILLATOR START-UP TIMER AND POWER-UP TIMER TIMING

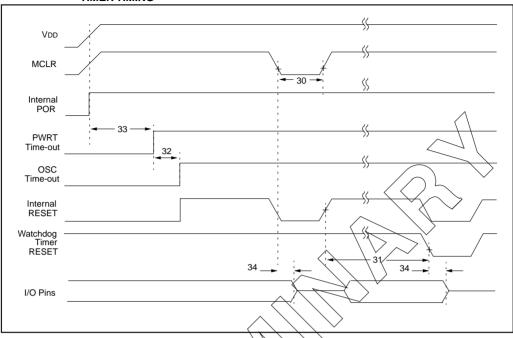


TABLE 11-5 RESET, WATCHDOG TIMER, OSCILLATOR START-UP TIMER AND POWER-UP TIMER REQUIREMENTS

Parameter No.	Sym	Characteristic	Min	Typ†	Max	Units	Conditions
30	TmcL	MCLR Pulse Width (low)	1000*	_	_	ns	2.0V ≤ VDD ≤ 6.0V
31	Twdt	Watchdog Timer Time-out Period (No Prescaler)	7 *	18	33 *	ms	VDD = 5.0V
32	Tost	Oscillation Start-up Timer Period		1024Tosc		ms	Tosc = OSC1 period
33	Tpwrt	Power-up Timer Period	28 *	72	132 *	ms	VDD = 5.0V
34	Tioz	I/O Hi-impedance from MCLR Low or reset	_	_	100 *	ns	

^{*} These parameters are characterized but not tested.

[†] Data in "Typ" column is at 50,25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

FIGURE 11-6: TIMERO CLOCK TIMINGS

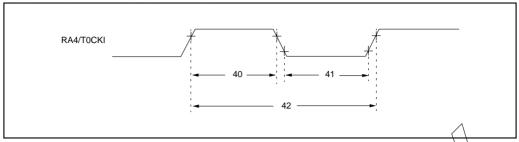


TABLE 11-6 TIMERO CLOCK REQUIREMENTS

Parameter No.	Sym	Characteristic		Min	Тур†	Max	Units	Conditions
40	Tt0H	T0CKI High Pulse Width	No Prescaler	0.5Tcy + 20 *	_	/<	ns	_
			With Prescaler	50 * 30 *	\ -	_		2.0V ≥ VDD ≤ 3.0V 3.0V ≤ VDD ≤ 6.0V
41	Tt0L	T0CKI Low Pulse Width	No Prescaler	0.5Tcy + 20 *	()	V	ns	
			With Prescaler	50 * 20 *	\downarrow		ns ns	$2.0V \le VDD \le 3.0V$ $3.0V \le VDD \le 6.0V$
42	Tt0P	T0CKI Period		Tcy + 40 *	1	>-	ns	N = prescale value (2, 4,, 256)

* These parameters are characterized but not tested.

† Data in "Typ" column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

NOTES:



12.0 DC & AC CHARACTERISTICS GRAPHS/TABLES

The graphs and tables provided in this section are for design quidance and are not tested or quaranteed.

In some graphs or tables, the data presented are **outside specified operating range** (i.e., outside specified VDD range). This is for **information only** and devices are guaranteed to operate properly only within the specified range.

The data presented in this section is a **statistical summary** of data collected on units from different lots over a period of time and matrix samples. 'Typical' represents the mean of the distribution at 25° C, while 'max' or 'min' represents (mean + 3σ) and (mean - 3σ) respectively, where σ is standard deviation.

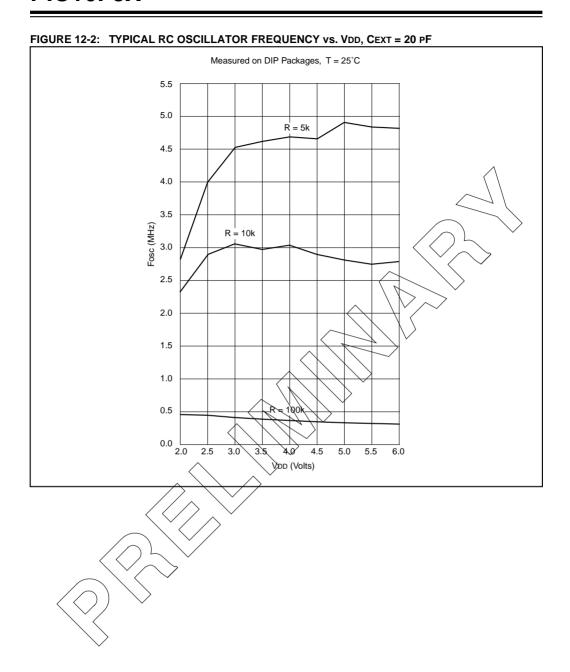
Frequency normalized to +25°C Fosc (25°C) 1.20 Rext = $10 \text{ k}\Omega$ 1.16 Cext = 100 pF1.12 1.08 1.04 1.00 VDD = 5.5 V 0.96 0.92 $\sqrt{VDD} = 3.5 \text{ V}$ 0.88 0.84 -40 -20 40 60 70 80 85 100

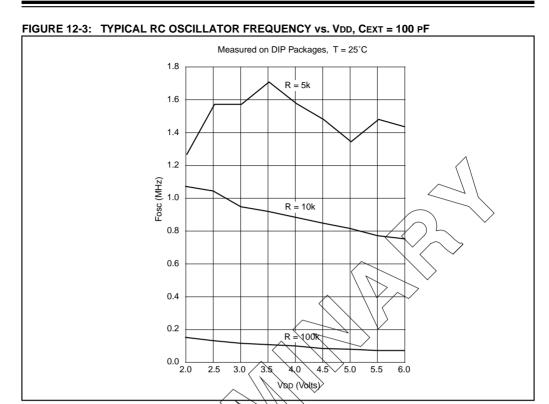
FIGURE 12-1: TYPICAL RC OSCILLATOR FREQUENCY vs. TEMPERATURE

TABLE 12-1 RC OSCILLATOR FREQUENCIES*

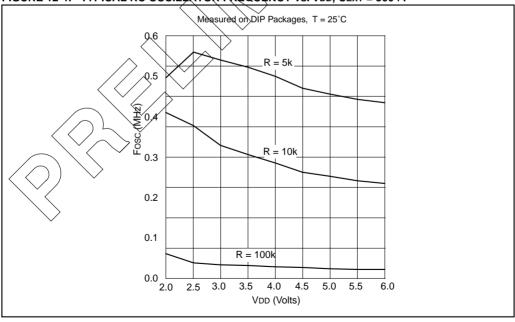
Cext	Rext		rage 5V, 25°C
			Part to Part Variation
20 pF	5 k	4.61 MHz	± 25%
	→ 10 k	2.66 MHz	± 24%
L \'\	100 k	311 kHz	± 39%
100 pF	5 k	1.34 MHz	± 21%
	10 k	756 kHz	± 18%
	100 k	82.8 kHz	± 28%
300 pF	5 k	428 kHz	± 13%
	10 k	243 kHz	± 13%
	100 k	26.2 kHz	± 23%

^{*} Measured on DIP packages. The percentage variation indicated here is part-to-part variation due to normal process distribution. The variation indicated is ± 3 standard deviation from average value for full VDD range.









PIC16F8X

FIGURE 12-5: TYPICAL IPD vs. VDD, WATCHDOG DISABLED

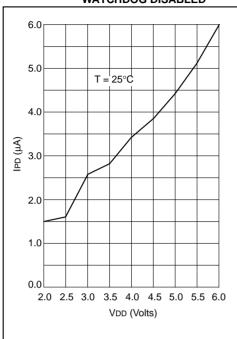


FIGURE 12-6: TYPICAL IPD vs. VDD, WATCHDOG ENABLED

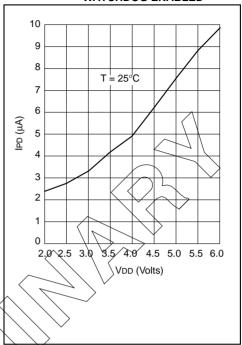


FIGURE 12-7: VTH (INPUT THRESHOLD VOLTAGE) OF 1/0 PINS vs. VDD

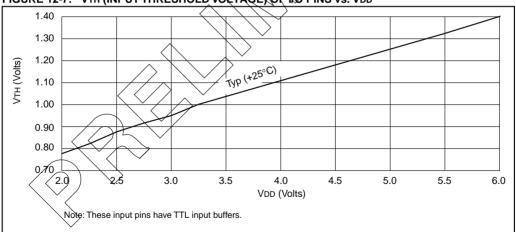


FIGURE 12-8: VTH (INPUT THRESHOLD VOLTAGE) OF OSC1 INPUT (IN XT, HS, AND LP MODES) vs. VDD

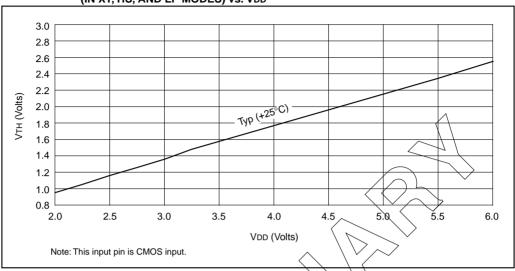
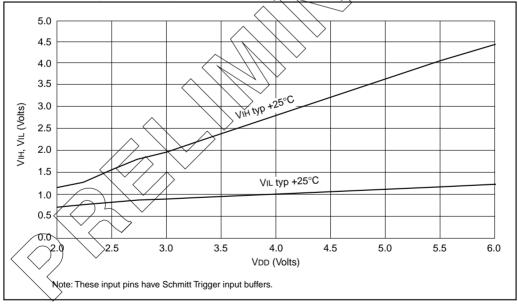
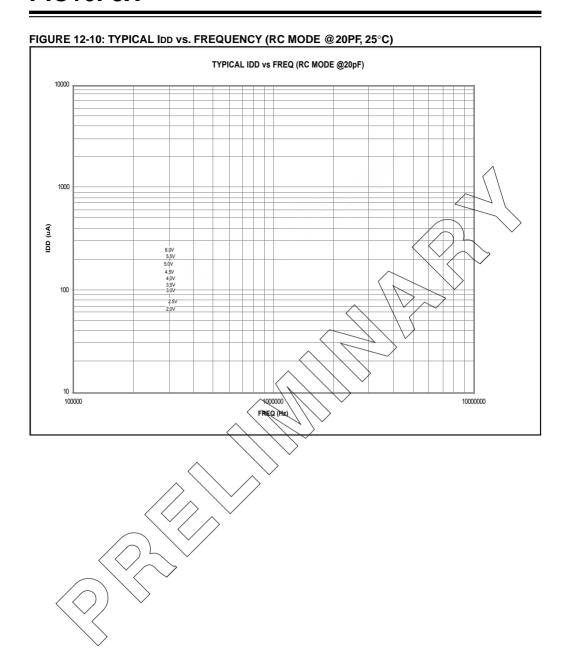
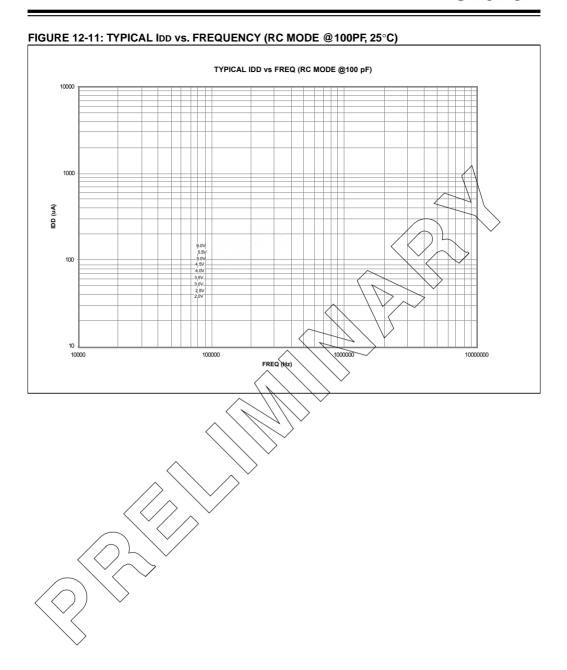


FIGURE 12-9: VIH, VIL OF MCLR, TOCKI AND OSC1 (IN RC MODE) vs. VDD







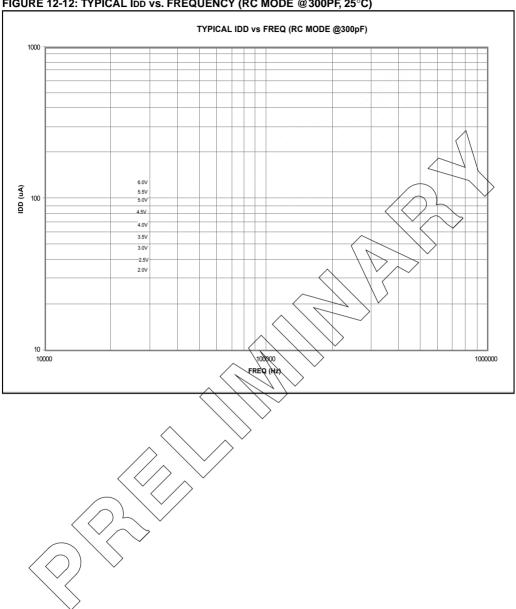


FIGURE 12-13: WDT TIMER TIME-OUT PERIOD vs. VDD

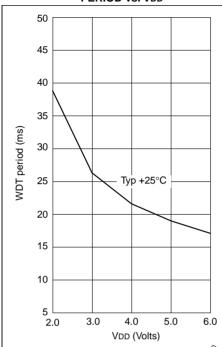


FIGURE 12-14: TRANSCONDUCTANCE (gm)
OF HS OSCILLATOR vs. VDD

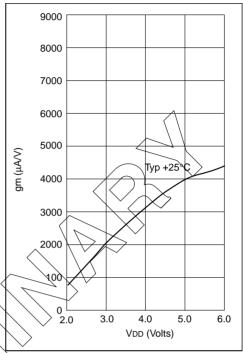


FIGURE 12-15: TRANSCONDUCTANCE (gm)
OF LP OSCILLATOR vs. VDD

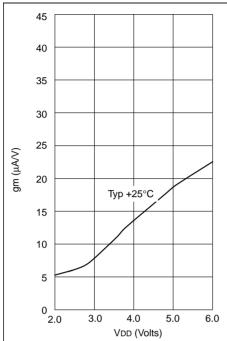


FIGURE 12-16: TRANSCONDUCTANCE (gm)
OF XT OSCILLATOR vs. VDD

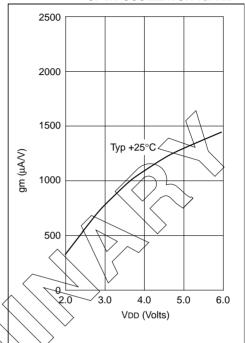


FIGURE 12-17: IOH vs. VOH, VDD = 3 V

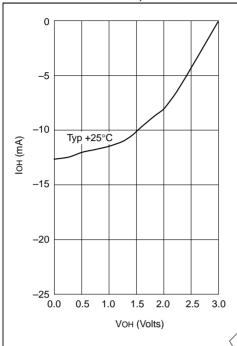


FIGURE 12-19: IOL vs. VOL, VDD = 3 V

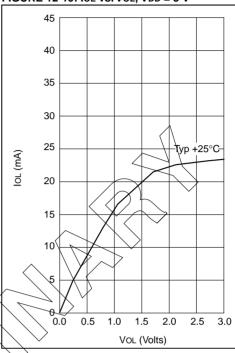


FIGURE 12-18: IOH vs. VOH, VDD = 5 V

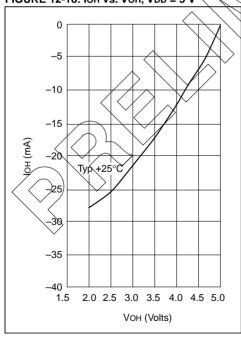


FIGURE 12-20: IOL vs. VOL, <u>VDD = 5 V</u>

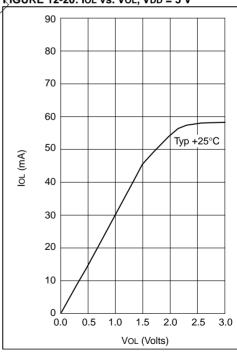


FIGURE 12-21: TYPICAL DATA MEMORY ERASE/WRITE CYCLE TIME VS. VDD

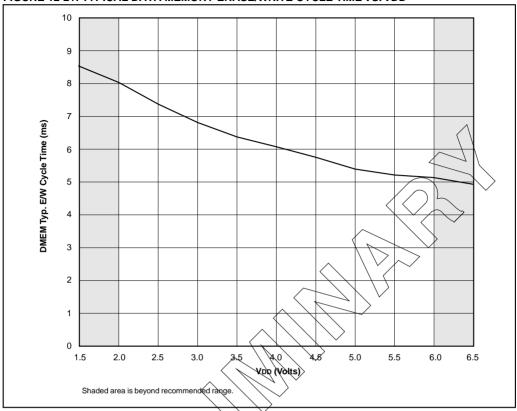


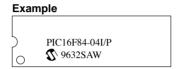
TABLE 12-2 INPUT CAPACITANCE*

Pin Name	Typical Capa	Typical Capacitance (pF)				
Fill Name	18L PDIP	18L SOIC				
PORTA	5.0	4.3				
PORTB	5.0	4.3				
MCLR	17.0	17.0				
OSCYCLKIM	4.0	3.5				
OSCZYCLKOUT	4.3	3.5				
ТОСКІ	3.2	2.8				

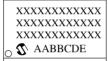
^{*} All capacitance values are typical at 25°C. A part to part variation of ±25% (three standard deviations) should be taken into account.

13.0 PACKAGING INFORMATION

13.1 Package Marking Information



18L SOIC



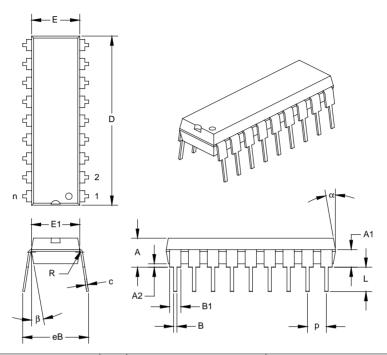




Legend:	XXX AA	Microchip part number & customer specific information* Year code (last two digits of calendar year)			
	BB	Week code (week of January 1 is week '01')			
	С	Facility code of the plant at which wafer is manufactured			
		C = Chandler, Arizona, U.S.A.,			
		S = Tempe, Arizona, U.S.A.			
	D	Mask revision number			
	E	Assembly code of the plant or country of origin in which part was assembled			
Note:	In the ever	nt the full Microchip part number cannot be marked on one line,			
	it will be carried over to the next line, thus limiting the number of availa				

^{*} Standard OTP marking consists of Microchip part number, year code, week code, facility code, mask rev# and assembly code. For OTP marking beyond this, certain price adders apply. Please check with your Microchip Sales Office. For QTP devices, any special marking adders are included in QTP price.

Package Type: K04-007 18-Lead Plastic Dual In-line (P) - 300 mil



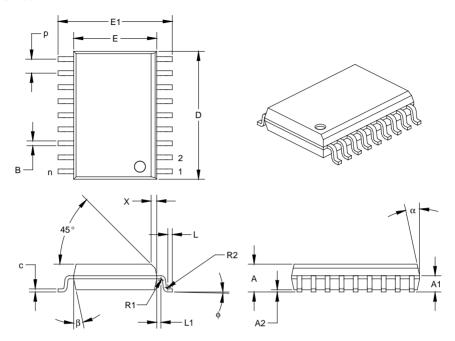
Units		INCHES*		MILLIMETERS			
Dimension Limits		MIN	NOM	MAX	MIN	NOM	MAX
PCB Row Spacing			0.300			7.62	
Number of Pins	n		18			18	
Pitch	р		0.100			2.54	
Lower Lead Width	В	0.013	0.018	0.023	0.33	0.46	0.58
Upper Lead Width	B1 [†]	0.055	0.060	0.065	1.40	1.52	1.65
Shoulder Radius	R	0.000	0.005	0.010	0.00	0.13	0.25
Lead Thickness	С	0.005	0.010	0.015	0.13	0.25	0.38
Top to Seating Plane	Α	0.110	0.155	0.155	2.79	3.94	3.94
Top of Lead to Seating Plane	A1	0.075	0.095	0.115	1.91	2.41	2.92
Base to Seating Plane	A2	0.000	0.020	0.020	0.00	0.51	0.51
Tip to Seating Plane	L	0.125	0.130	0.135	3.18	3.30	3.43
Package Length	D‡	0.890	0.895	0.900	22.61	22.73	22.86
Molded Package Width	E‡	0.245	0.255	0.265	6.22	6.48	6.73
Radius to Radius Width	E1	0.230	0.250	0.270	5.84	6.35	6.86
Overall Row Spacing	eВ	0.310	0.349	0.387	7.87	8.85	9.83
Mold Draft Angle Top	α	5	10	15	5	10	15
Mold Draft Angle Bottom	β	5	10	15	5	10	15

^{*} Controlling Parameter.

[†] Dimension "B1" does not include dam-bar protrusions. Dam-bar protrusions shall not exceed 0.003" (0.076 mm) per side or 0.006" (0.152 mm) more than dimension "B1."

[‡] Dimensions "D" and "E" do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.010" (0.254 mm) per side or 0.020" (0.508 mm) more than dimensions "D" or "E."

Package Type: K04-051 18-Lead Plastic Small Outline (SO) - Wide, 300 mil



Units		INCHES*			MILLIMETERS		
Dimension Limits		MIN	NOM	MAX	MIN	NOM	MAX
Pitch	р		0.050			1.27	
Number of Pins	n		18			18	
Overall Pack. Height	Α	0.093	0.099	0.104	2.36	2.50	2.64
Shoulder Height	A1	0.048	0.058	0.068	1.22	1.47	1.73
Standoff	A2	0.004	0.008	0.011	0.10	0.19	0.28
Molded Package Length	D [‡]	0.450	0.456	0.462	11.43	11.58	11.73
Molded Package Width	E [‡]	0.292	0.296	0.299	7.42	7.51	7.59
Outside Dimension	E1	0.394	0.407	0.419	10.01	10.33	10.64
Chamfer Distance	X	0.010	0.020	0.029	0.25	0.50	0.74
Shoulder Radius	R1	0.005	0.005	0.010	0.13	0.13	0.25
Gull Wing Radius	R2	0.005	0.005	0.010	0.13	0.13	0.25
Foot Length	L	0.011	0.016	0.021	0.28	0.41	0.53
Foot Angle	φ	0	4	8	0	4	8
Radius Centerline	L1	0.010	0.015	0.020	0.25	0.38	0.51
Lead Thickness	С	0.009	0.011	0.012	0.23	0.27	0.30
Lower Lead Width	Β [†]	0.014	0.017	0.019	0.36	0.42	0.48
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15

^{*} Controlling Parameter.

[†] Dimension "B" does not include dam-bar protrusions. Dam-bar protrusions shall not exceed 0.003" (0.076 mm) per side or 0.006" (0.152 mm) more than dimension "B."

[‡] Dimensions "D" and "E" do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.010" (0.254 mm) per side or 0.020" (0.508 mm) more than dimensions "D" or "E."